

K61P143M120SF3

K61 Sub-Family

Supports the following:
MK61FN1M0CAA12

Key features

- Operating Characteristics
 - Voltage range: 1.71 to 3.6 V
 - Flash write voltage range: 1.71 to 3.6 V
 - Temperature range (ambient): -40 to 85°C
- Performance
 - Up to 120 MHz Arm® Cortex®-M4 core with DSP instructions delivering 1.25 Dhrystone MIPS per MHz
- Memories and memory interfaces
 - Up to 1024 KB program flash memory on non-FlexMemory devices
 - Up to 128 KB RAM
 - Serial programming interface (EzPort)
 - FlexBus external bus interface
 - NAND flash controller interface
- Clocks
 - 3 to 32 MHz crystal oscillator
 - 32 kHz crystal oscillator
 - Multi-purpose clock generator
- System peripherals
 - Multiple low-power modes to provide power optimization based on application requirements
 - Memory protection unit with multi-master protection
 - 32-channel DMA controller, supporting up to 128 request sources
 - External watchdog monitor
 - Software watchdog
 - Low-leakage wakeup unit
- Security and integrity modules
 - Hardware CRC module to support fast cyclic redundancy checks
 - Tamper detect and secure storage
 - Hardware random-number generator
 - Hardware encryption supporting DES, 3DES, AES, MD5, SHA-1, and SHA-256 algorithms
 - 128-bit unique identification (ID) number per chip
- Human-machine interface
 - Low-power hardware touch sensor interface (TSI)
 - General-purpose input/output
- Analog modules
 - Four 16-bit SAR ADCs
 - Programmable gain amplifier (PGA) (up to x64) integrated into each ADC
 - Two 12-bit DACs
 - Four analog comparators (CMP) containing a 6-bit DAC and programmable reference input
 - Voltage reference
- Timers
 - Programmable delay block
 - Two 8-channel motor control/general purpose/PWM timers
 - Two 2-channel quadrature decoder/general purpose timers
 - IEEE 1588 timers
 - Periodic interrupt timers
 - 16-bit low-power timer
 - Carrier modulator transmitter
 - Real-time clock
- Communication interfaces
 - Ethernet controller with MII and RMI interface to external PHY and hardware IEEE 1588 capability
 - USB high-/full-/low-speed On-the-Go controller with ULPI interface
 - USB full-/low-speed On-the-Go controller with on-chip transceiver
 - USB Device Charger detect (USBDCD)
 - Two Controller Area Network (CAN) modules
 - Three SPI modules
 - Two I2C modules
 - Six UART modules
 - Secure Digital Host Controller (SDHC)
 - Two I2S modules

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1 Ordering parts

1.1 Determining valid orderable parts

Valid orderable part numbers are provided on the web. To determine the orderable part numbers for this device, go to nxp.com and perform a part number search for the following device numbers: PK61 and MK61

2 Part identification

2.1 Description

Part numbers for the chip have fields that identify the specific part. You can use the values of these fields to determine the specific part you have received.

2.2 Format

Part numbers for this device have the following format:

Q K## A M FFF T PP CC N

2.3 Fields

This table lists the possible values for each field in the part number (not all combinations are valid):

Field	Description	Values
Q	Qualification status	<ul style="list-style-type: none"> M = Fully qualified, general market flow P = Prequalification
K##	Kinetis family	<ul style="list-style-type: none"> K61
A	Key attribute	<ul style="list-style-type: none"> F = Cortex-M4 w/ DSP and FPU
M	Flash memory type	<ul style="list-style-type: none"> N = Program flash only X = Program flash and FlexMemory
FFF	Program flash memory size	<ul style="list-style-type: none"> 512 = 512 KB 1M0 = 1 MB

Table continues on the next page...

Terminology and guidelines

Field	Description	Values
T	Temperature range (°C)	<ul style="list-style-type: none">• V = -40 to 105• C = -40 to 85
PP	Package identifier	<ul style="list-style-type: none">• AA = 143 WLCSP
CC	Maximum CPU frequency (MHz)	<ul style="list-style-type: none">• 12 = 120 MHz
N	Packaging type	<ul style="list-style-type: none">• R = Tape and reel

2.4 Example

This is an example part number:

MK61FN1M0CAA12

3 Terminology and guidelines

3.1 Definitions

Key terms are defined in the following table:

Term	Definition
Rating	<p>A minimum or maximum value of a technical characteristic that, if exceeded, may cause permanent chip failure:</p> <ul style="list-style-type: none">• <i>Operating ratings</i> apply during operation of the chip.• <i>Handling ratings</i> apply when the chip is not powered. <p>NOTE: The likelihood of permanent chip failure increases rapidly as soon as a characteristic begins to exceed one of its operating ratings.</p>
Operating requirement	<p>A specified value or range of values for a technical characteristic that you must guarantee during operation to avoid incorrect operation and possibly decreasing the useful life of the chip</p>
Operating behavior	<p>A specified value or range of values for a technical characteristic that are guaranteed during operation if you meet the operating requirements and any other specified conditions</p>
Typical value	<p>A specified value for a technical characteristic that:</p> <ul style="list-style-type: none">• Lies within the range of values specified by the operating behavior• Is representative of that characteristic during operation when you meet the typical-value conditions or other specified conditions <p>NOTE: Typical values are provided as design guidelines and are neither tested nor guaranteed.</p>

3.2 Examples

Operating rating:

Symbol	Description	Min.	Max.	Unit
V _{DD}	1.0 V core supply voltage	-0.3	1.2	V

Operating requirement:

Symbol	Description	Min.	Max.	Unit
V _{DD}	1.0 V core supply voltage	0.9	1.1	V

Operating behavior that includes a typical value:

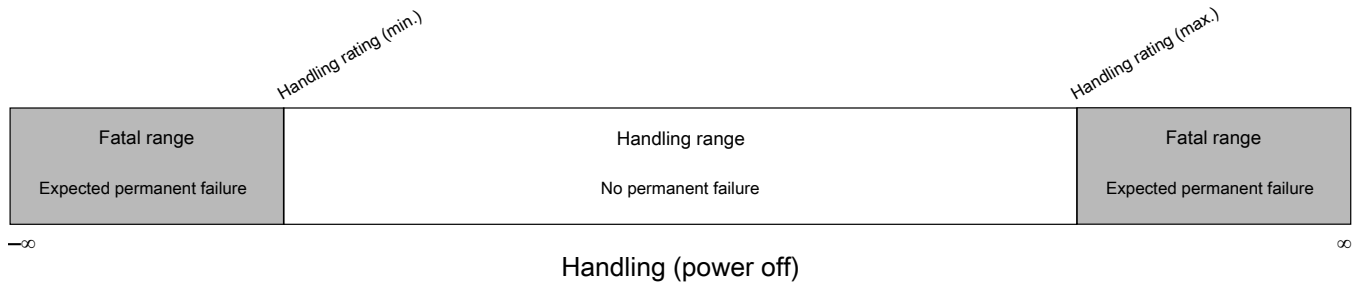
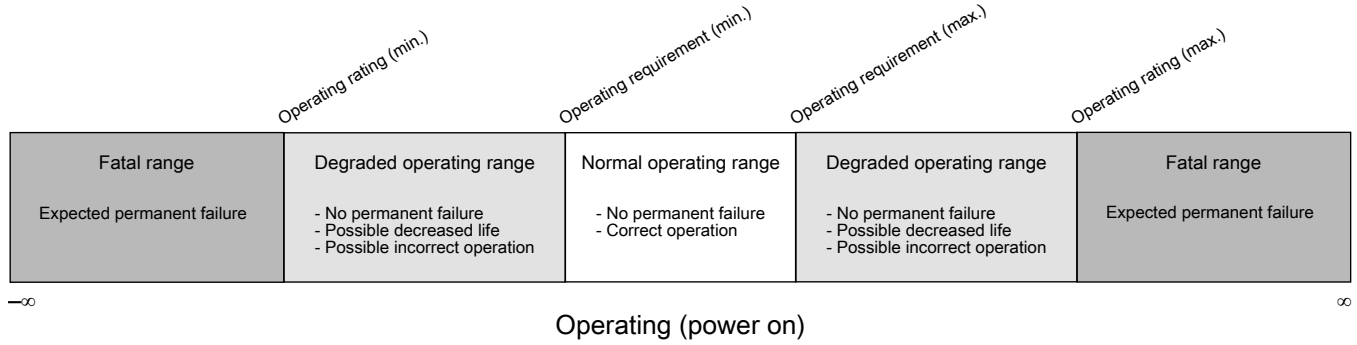
Symbol	Description	Min.	Typ.	Max.	Unit
I _{WP}	Digital I/O weak pullup/pulldown current	10	70	130	μA

3.3 Typical-value conditions

Typical values assume you meet the following conditions (or other conditions as specified):

Symbol	Description	Value	Unit
T _A	Ambient temperature	25	°C
V _{DD}	Supply voltage	3.3	V

3.4 Relationship between ratings and operating requirements



3.5 Guidelines for ratings and operating requirements

Follow these guidelines for ratings and operating requirements:

- Never exceed any of the chip’s ratings.
- During normal operation, don’t exceed any of the chip’s operating requirements.
- If you must exceed an operating requirement at times other than during normal operation (for example, during power sequencing), limit the duration as much as possible.

4 Ratings

4.1 Thermal handling ratings

Symbol	Description	Min.	Max.	Unit	Notes
T _{STG}	Storage temperature	-55	150	°C	1
T _{SDR}	Solder temperature, lead-free	—	260	°C	2

1. Determined according to JEDEC Standard JESD22-A103, *High Temperature Storage Life*.
 2. Determined according to IPC/JEDEC Standard J-STD-020, *Moisture/Reflow Sensitivity Classification for Nonhermetic Solid State Surface Mount Devices*.

4.2 Moisture handling ratings

Symbol	Description	Min.	Max.	Unit	Notes
MSL	Moisture sensitivity level	—	3	—	1

1. Determined according to IPC/JEDEC Standard J-STD-020, *Moisture/Reflow Sensitivity Classification for Nonhermetic Solid State Surface Mount Devices*.

4.3 ESD handling ratings

Symbol	Description	Min.	Max.	Unit	Notes
V _{HBM}	Electrostatic discharge voltage, human body model	-2000	+2000	V	1
V _{CDM}	Electrostatic discharge voltage, charged-device model	-500	+500	V	2
I _{LAT}	Latch-up current at ambient temperature of 105°C	-100	+100	mA	3

1. Determined according to JEDEC Standard JESD22-A114, *Electrostatic Discharge (ESD) Sensitivity Testing Human Body Model (HBM)*.
2. Determined according to JEDEC Standard JESD22-C101, *Field-Induced Charged-Device Model Test Method for Electrostatic-Discharge-Withstand Thresholds of Microelectronic Components*.
3. Determined according to JEDEC Standard JESD78, *IC Latch-Up Test*.

4.4 Voltage and current operating ratings

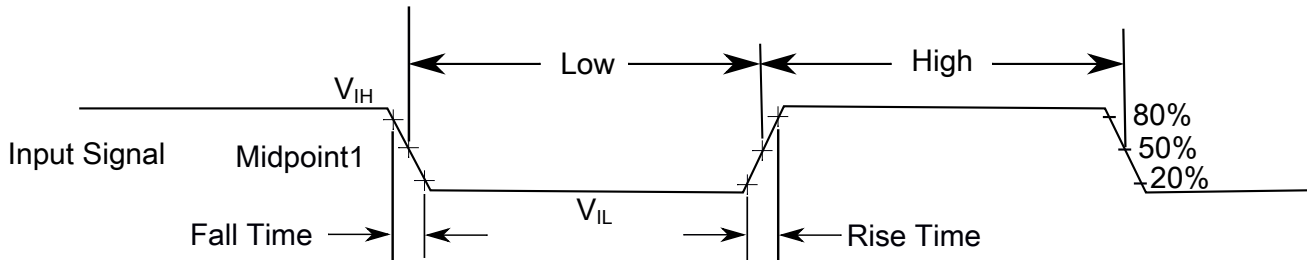
Symbol	Description	Min.	Max.	Unit
V _{DD}	Digital supply voltage ¹	-0.3	3.8	V
I _{DD}	Digital supply current	—	300	mA
V _{DIO}	Digital input voltage (except $\overline{\text{RESET}}$, EXTAL0/XTAL0, and EXTAL1/XTAL1) ²	-0.3	5.5	V
V _{AIO}	Analog ³ , $\overline{\text{RESET}}$, EXTAL0/XTAL0, and EXTAL1/XTAL1 input voltage	-0.3	V _{DD} + 0.3	V
I _D	Maximum current single pin limit (applies to all digital pins)	-25	25	mA
V _{DDA}	Analog supply voltage	V _{DD} - 0.3	V _{DD} + 0.3	V
V _{USB0_DP}	USB0_DP input voltage	-0.3	3.63	V
V _{USB0_DM}	USB0_DM input voltage	-0.3	3.63	V
V _{REGIN}	USB regulator input	-0.3	6.0	V
V _{BAT}	RTC battery supply voltage	-0.3	3.8	V

1. It applies for all port pins except Tamper pins.
2. It covers digital pins except Tamper pins.
3. Analog pins are defined as pins that do not have an associated general purpose I/O port function.

5 General

5.1 AC electrical characteristics

Unless otherwise specified, propagation delays are measured from the 50% to the 50% point, and rise and fall times are measured at the 20% and 80% points, as shown in the following figure.



The midpoint is $V_{IL} + (V_{IH} - V_{IL}) / 2$

Figure 1. Input signal measurement reference

All digital I/O switching characteristics assume:

1. output pins
 - have $C_L=30pF$ loads,
 - are configured for fast slew rate ($PORTx_PCRn[SRE]=0$), and
 - are configured for high drive strength ($PORTx_PCRn[DSE]=1$)
2. input pins
 - have their passive filter disabled ($PORTx_PCRn[PFE]=0$)

5.2 Nonswitching electrical specifications

5.2.1 Voltage and current operating requirements

Table 1. Voltage and current operating requirements

Symbol	Description	Min.	Max.	Unit	Notes
V_{DD}	Supply voltage	1.71	3.6	V	
V_{DDA}	Analog supply voltage	1.71	3.6	V	
$V_{DD} - V_{DDA}$	V_{DD} -to- V_{DDA} differential voltage	-0.1	0.1	V	
$V_{SS} - V_{SSA}$	V_{SS} -to- V_{SSA} differential voltage	-0.1	0.1	V	

Table continues on the next page...

Table 1. Voltage and current operating requirements (continued)

Symbol	Description	Min.	Max.	Unit	Notes
V _{BAT}	RTC battery supply voltage	1.71	3.6	V	
V _{IH}	Input high voltage (digital pins except Tamper pins) <ul style="list-style-type: none"> • 2.7 V ≤ V_{DD} ≤ 3.6 V • 1.7 V ≤ V_{DD} ≤ 2.7 V 	0.7 × V _{DD} 0.75 × V _{DD}	— —	V V	
V _{IL}	Input low voltage (digital pins except Tamper pins) <ul style="list-style-type: none"> • 2.7 V ≤ V_{DD} ≤ 3.6 V • 1.7 V ≤ V_{DD} ≤ 2.7 V 	— —	0.35 × V _{DD} 0.3 × V _{DD}	V V	
V _{HYS}	Input hysteresis (digital pins except Tamper pins)	0.06 × V _{DD}	—	V	
I _{CDIO}	Digital pin (except Tamper pins) negative DC injection current — single pin <ul style="list-style-type: none"> • V_{IN} < V_{SS}-0.3V 	-5	—	mA	1
I _{CAIO}	Analog ² , EXTAL0/XTAL0, and EXTAL1/XTAL1 pin DC injection current — single pin <ul style="list-style-type: none"> • V_{IN} < V_{SS}-0.3V (Negative current injection) • V_{IN} > V_{DD}+0.3V (Positive current injection) 	-5 —	— +5	mA	3
I _{Ccont}	Contiguous pin DC injection current — regional limit, includes sum of negative injection currents or sum of positive injection currents of 16 contiguous pins <ul style="list-style-type: none"> • Negative current injection • Positive current injection 	-25 —	— +25	mA	
V _{ODPU}	Open drain pullup voltage level	V _{DD}	V _{DD}	V	4
V _{RAM}	V _{DD} voltage required to retain RAM	1.2	—	V	
V _{RFVBAT}	V _{BAT} voltage required to retain the VBAT register file	V _{POR_VBAT}	—	V	

1. All 5 V tolerant digital I/O pins are internally clamped to V_{SS} through an ESD protection diode. There is no diode connection to V_{DD}. If V_{IN} is less than V_{DIO_MIN}, a current limiting resistor is required. If V_{IN} greater than V_{DIO_MIN} (=V_{SS}-0.3V) is observed, then there is no need to provide current limiting resistors at the pads. The negative DC injection current limiting resistor is calculated as $R=(V_{DIO_MIN}-V_{IN})/|I_{CDIO}|$.
2. Analog pins are defined as pins that do not have an associated general purpose I/O port function. Additionally, EXTAL and XTAL are analog pins.
3. All analog pins are internally clamped to V_{SS} and V_{DD} through ESD protection diodes. If V_{IN} is less than V_{AIO_MIN} or greater than V_{AIO_MAX}, a current limiting resistor is required. The negative DC injection current limiting resistor is calculated as $R=(V_{AIO_MIN}-V_{IN})/|I_{CAIO}|$. The positive injection current limiting resistor is calculated as $R=(V_{IN}-V_{AIO_MAX})/|I_{CAIO}|$. Select the larger of these two calculated resistances if the pin is exposed to positive and negative injection currents.
4. Open drain outputs must be pulled to V_{DD}.

5.2.2 LVD and POR operating requirements

Table 2. LVD and POR operating requirements

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
V _{POR}	Falling VDD POR detect voltage	0.8	1.1	1.5	V	
V _{LVDH}	Falling low-voltage detect threshold — high range (LVDV=01)	2.48	2.56	2.64	V	
V _{LW1H}	Low-voltage warning thresholds — high range <ul style="list-style-type: none"> • Level 1 falling (LVWV=00) • Level 2 falling (LVWV=01) • Level 3 falling (LVWV=10) • Level 4 falling (LVWV=11) 	2.62	2.70	2.78	V	1
V _{LW2H}		2.72	2.80	2.88	V	
V _{LW3H}		2.82	2.90	2.98	V	
V _{LW4H}		2.92	3.00	3.08	V	
V _{HYSH}		Low-voltage inhibit reset/recover hysteresis — high range	—	±80	—	mV
V _{LVDL}	Falling low-voltage detect threshold — low range (LVDV=00)	1.54	1.60	1.66	V	
V _{LW1L}	Low-voltage warning thresholds — low range <ul style="list-style-type: none"> • Level 1 falling (LVWV=00) • Level 2 falling (LVWV=01) • Level 3 falling (LVWV=10) • Level 4 falling (LVWV=11) 	1.74	1.80	1.86	V	1
V _{LW2L}		1.84	1.90	1.96	V	
V _{LW3L}		1.94	2.00	2.06	V	
V _{LW4L}		2.04	2.10	2.16	V	
V _{HYSL}		Low-voltage inhibit reset/recover hysteresis — low range	—	±60	—	mV
V _{BG}	Bandgap voltage reference	0.97	1.00	1.03	V	
t _{LPO}	Internal low power oscillator period factory trimmed	900	1000	1100	µs	

1. Rising thresholds are falling threshold + hysteresis voltage

Table 3. VBAT power operating requirements

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
V _{POR_VBAT}	Falling VBAT supply POR detect voltage	0.8	1.1	1.5	V	

5.2.3 Voltage and current operating behaviors

Table 4. Voltage and current operating behaviors

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
V _{OH}	Output high voltage — high drive strength <ul style="list-style-type: none"> • 2.7 V ≤ V_{DD} ≤ 3.6 V, I_{OH} = -9mA • 1.71 V ≤ V_{DD} ≤ 2.7 V, I_{OH} = -3mA 	V _{DD} - 0.5	—	—	V	
		V _{DD} - 0.5	—	—	V	

Table continues on the next page...

Table 4. Voltage and current operating behaviors (continued)

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
	Output high voltage — low drive strength <ul style="list-style-type: none"> • $2.7\text{ V} \leq V_{DD} \leq 3.6\text{ V}$, $I_{OH} = -2\text{ mA}$ • $1.71\text{ V} \leq V_{DD} \leq 2.7\text{ V}$, $I_{OH} = -0.6\text{ mA}$ 	$V_{DD} - 0.5$ $V_{DD} - 0.5$	— —	— —	V V	
I_{OHT}	Output high current total for all ports	—	—	100	mA	
I_{OHT_io60}	Output high current total for fast digital ports	—	—	100	mA	
V_{OH_Tamper}	Output high voltage — high drive strength <ul style="list-style-type: none"> • $2.7\text{ V} \leq V_{BAT} \leq 3.6\text{ V}$, $I_{OH} = -10\text{ mA}$ • $1.71\text{ V} \leq V_{BAT} \leq 2.7\text{ V}$, $I_{OH} = -3\text{ mA}$ 	$V_{BAT} - 0.5$ $V_{BAT} - 0.5$	— —	— —	V V	
	Output high voltage — low drive strength <ul style="list-style-type: none"> • $2.7\text{ V} \leq V_{BAT} \leq 3.6\text{ V}$, $I_{OH} = -2\text{ mA}$ • $1.71\text{ V} \leq V_{BAT} \leq 2.7\text{ V}$, $I_{OH} = -0.6\text{ mA}$ 	$V_{BAT} - 0.5$ $V_{BAT} - 0.5$	— —	— —	V V	
I_{OH_Tamper}	Output high current total for Tamper pins	—	—	100	mA	
V_{OL}	Output low voltage — high drive strength <ul style="list-style-type: none"> • $2.7\text{ V} \leq V_{DD} \leq 3.6\text{ V}$, $I_{OL} = 10\text{ mA}$ • $1.71\text{ V} \leq V_{DD} \leq 2.7\text{ V}$, $I_{OL} = 5\text{ mA}$ 	— —	— —	0.5 0.5	V V	
	Output low voltage — low drive strength <ul style="list-style-type: none"> • $2.7\text{ V} \leq V_{DD} \leq 3.6\text{ V}$, $I_{OL} = 2\text{ mA}$ • $1.71\text{ V} \leq V_{DD} \leq 2.7\text{ V}$, $I_{OL} = 1\text{ mA}$ 	— —	— —	0.5 0.5	V V	
I_{OLT}	Output low current total for all ports	—	—	100	mA	
I_{OLT_io60}	Output low current total for fast digital ports	—	—	100	mA	
V_{OL_Tamper}	Output low voltage — high drive strength <ul style="list-style-type: none"> • $2.7\text{ V} \leq V_{BAT} \leq 3.6\text{ V}$, $I_{OL} = 10\text{ mA}$ • $1.71\text{ V} \leq V_{BAT} \leq 2.7\text{ V}$, $I_{OL} = 3\text{ mA}$ 	— —	— —	0.5 0.5	V V	
	Output low voltage — low drive strength <ul style="list-style-type: none"> • $2.7\text{ V} \leq V_{BAT} \leq 3.6\text{ V}$, $I_{OL} = 2\text{ mA}$ • $1.71\text{ V} \leq V_{BAT} \leq 2.7\text{ V}$, $I_{OL} = 0.6\text{ mA}$ 	— —	— —	0.5 0.5	V V	
I_{OL_Tamper}	Output low current total for Tamper pins	—	—	100	mA	
I_{INA}	Input leakage current, analog pins and digital pins configured as analog inputs <ul style="list-style-type: none"> • $V_{SS} \leq V_{IN} \leq V_{DD}$ <ul style="list-style-type: none"> • All pins except EXTAL32, XTAL32, EXTAL, XTAL • EXTAL (PTA18) and XTAL (PTA19) • EXTAL32, XTAL32 	—	0.002	0.5	μA	1, 2
		—	0.004	1.5	μA	
		—	0.075	10	μA	
I_{IND}	Input leakage current, digital pins <ul style="list-style-type: none"> • $V_{SS} \leq V_{IN} \leq V_{IL}$ 					2, 3

Table continues on the next page...

Table 4. Voltage and current operating behaviors (continued)

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
	<ul style="list-style-type: none"> All digital pins 	—	0.002	0.5	μA	
	<ul style="list-style-type: none"> $V_{IN} = V_{DD}$ All digital pins except PTD7 PTD7 	—	0.002	0.5	μA	
		—	0.004	1	μA	
I_{IND}	Input leakage current, digital pins <ul style="list-style-type: none"> $V_{IL} < V_{IN} < V_{DD}$ $V_{DD} = 3.6\text{ V}$ $V_{DD} = 3.0\text{ V}$ $V_{DD} = 2.5\text{ V}$ $V_{DD} = 1.7\text{ V}$ 	—	18	26	μA	2, 3, 4
		—	12	19	μA	
		—	8	13	μA	
		—	3	6	μA	
I_{IND}	Input leakage current, digital pins <ul style="list-style-type: none"> $V_{DD} < V_{IN} < 5.5\text{ V}$ 	—	1	50	μA	2, 3
Z_{IND}	Input impedance examples, digital pins <ul style="list-style-type: none"> $V_{DD} = 3.6\text{ V}$ $V_{DD} = 3.0\text{ V}$ $V_{DD} = 2.5\text{ V}$ $V_{DD} = 1.7\text{ V}$ 	—	—	48	kΩ	2, 5
		—	—	55	kΩ	
		—	—	57	kΩ	
		—	—	85	kΩ	
I_{IN_Tamper}	Input leakage current (per Tamper pin) for full temperature range	—	—	1	μA	
I_{IN_Tamper}	Input leakage current (per Tamper pin) at 25°C	—	—	0.025	μA	
R_{PU}	Internal pullup resistors (except Tamper pins)	20	—	50	kΩ	6
R_{PD}	Internal pulldown resistors (except Tamper pins)	20	—	50	kΩ	7

1. Analog pins are defined as pins that do not have an associated general purpose I/O port function.
2. Digital pins have an associated GPIO port function and have 5V tolerant inputs, except EXTAL and XTAL.
3. Internal pull-up/pull-down resistors disabled.
4. Characterized, not tested in production.
5. Examples calculated using V_{IL} relation, V_{DD} , and max I_{IND} : $Z_{IND} = V_{IL} / I_{IND}$. This is the impedance needed to pull a high signal to a level below V_{IL} due to leakage when $V_{IL} < V_{IN} < V_{DD}$. These examples assume signal source low = 0 V. See [Figure 2](#).
6. Measured at V_{DD} supply voltage = V_{DD} min and $V_{input} = V_{SS}$
7. Measured at V_{DD} supply voltage = V_{DD} min and $V_{input} = V_{DD}$

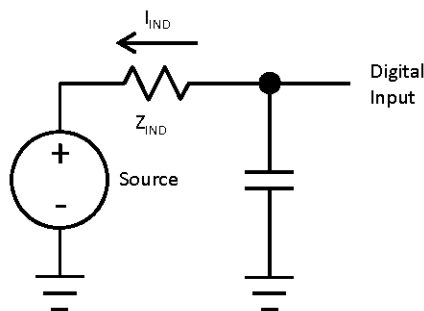


Figure 2. 5 V Tolerant Input IIND Parameter

5.2.4 Power mode transition operating behaviors

All specifications except t_{POR} , and $VLLSx \rightarrow RUN$ recovery times in the following table assume this clock configuration:

- CPU and system clocks = 100 MHz
- Bus clock = 50 MHz
- FlexBus clock = 50 MHz
- Flash clock = 25 MHz
- MCG mode: FEI

Table 5. Power mode transition operating behaviors

Symbol	Description	Min.	Max.	Unit	Notes
t_{POR}	After a POR event, amount of time from the point V_{DD} reaches 1.71 V to execution of the first instruction across the operating temperature range of the chip. <ul style="list-style-type: none"> • V_{DD} slew rate ≥ 5.7 kV/s • V_{DD} slew rate < 5.7 kV/s 	—	300	μs	1
	• $VLLS1 \rightarrow RUN$	—	160	μs	
	• $VLLS2 \rightarrow RUN$	—	114	μs	
	• $VLLS3 \rightarrow RUN$	—	114	μs	
	• $LLS \rightarrow RUN$	—	5.0	μs	
	• $VLPS \rightarrow RUN$	—	5	μs	
	• $STOP \rightarrow RUN$	—	4.8	μs	

1. Normal boot (FTFE_FOFT[LPBOOT]=1)

5.2.5 Power consumption operating behaviors

Table 6. Power consumption operating behaviors

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
I _{DDA}	Analog supply current	—	—	See note	mA	1
I _{DD_RUN}	Run mode current — all peripheral clocks disabled, code executing from flash	—	49.28	73.85	mA	2
		—	49.08	73.93	mA	
I _{DD_RUN}	Run mode current — all peripheral clocks enabled, code executing from flash	—	74.43	99.97	mA	3
		—	74.28	100.41	mA	
I _{DD_WAIT}	Wait mode high frequency current at 3.0 V — all peripheral clocks disabled	—	34.67	58.5	mA	2
I _{DD_WAIT}	Wait mode reduced frequency current at 3.0 V — all peripheral clocks disabled	—	18.03	41.91	mA	4
I _{DD_STOP}	Stop mode current at 3.0 V	—	1.25	1.62	mA	
		—	2.93	4.39	mA	
		—	7.08	10.74	mA	
I _{DD_VLPR}	Very-low-power run mode current at 3.0 V — all peripheral clocks disabled	—	1.03	4.48	mA	5
I _{DD_VLPR}	Very-low-power run mode current at 3.0 V — all peripheral clocks enabled	—	1.58	4.96	mA	5
I _{DD_VLPW}	Very-low-power wait mode current at 3.0 V	—	0.64	4.29	mA	5
I _{DD_VLPS}	Very-low-power stop mode current at 3.0 V	—	0.22	0.38	mA	
		—	0.78	1.33	mA	
		—	2.18	3.56	mA	
I _{DD_LLS}	Low leakage stop mode current at 3.0 V	—	0.22	0.37	mA	
		—	0.78	1.33	mA	
		—	2.16	3.52	mA	
I _{DD_VLLS3}	Very low-leakage stop mode 3 current at 3.0 V	—	4.09	5.58	μA	
		—	20.98	28.93	μA	
		—	84.95	111.15	μA	
I _{DD_VLLS2}	Very low-leakage stop mode 2 current at 3.0 V					

Table continues on the next page...

Table 6. Power consumption operating behaviors (continued)

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
	<ul style="list-style-type: none"> @ -40 to 25°C @ 70°C @ 85°C 	—	2.68	4.22	μA	
I _{DD_VLLS1}	Very low-leakage stop mode 1 current at 3.0 V <ul style="list-style-type: none"> @ -40 to 25°C @ 70°C @ 85°C 	—	2.46	4.02	μA	
		—	7.04	8.99	μA	
		—	30.68	37.04	μA	
I _{DD_VBAT}	Average current when CPU is not accessing RTC registers at 3.0 V <ul style="list-style-type: none"> @ -40 to 25°C @ 70°C @ 85°C 	—	0.89	1.10	μA	6
		—	1.28	1.85	μA	
		—	3.10	4.3	μA	

1. The analog supply current is the sum of the active or disabled current for each of the analog modules on the device. See each module's specification for its supply current.
2. 120 MHz core and system clock, 60 MHz bus, 30 MHz FlexBus clock, and 20 MHz flash clock. MCG configured for PEE mode. All peripheral clocks disabled.
3. 120 MHz core and system clock, 60 MHz bus, 30 MHz FlexBus clock, and 20 MHz flash clock. MCG configured for PEE mode. All peripheral clocks enabled, but peripherals are not in active operation.
4. 25 MHz core and system clock, 25 MHz bus clock, and 12.5 MHz FlexBus and flash clock. MCG configured for FEI mode.
5. 4 MHz core, system, 2 MHz FlexBus, and 2 MHz bus clock and 0.5 MHz flash clock. MCG configured for BLPE mode. All peripheral clocks disabled.
6. Includes 32kHz oscillator current and RTC operation.

5.2.5.1 Diagram: Typical I_{DD_RUN} operating behavior

The following data was measured under these conditions:

- MCG in FBE mode for 50 MHz and lower frequencies. MCG in FEE mode at greater than 50 MHz frequencies. MCG in PEE mode at greater than 100 MHz frequencies.
- USB regulator disabled
- No GPIOs toggled
- Code execution from flash with cache enabled
- For the ALLOFF curve, all peripheral clocks are disabled except FTFE

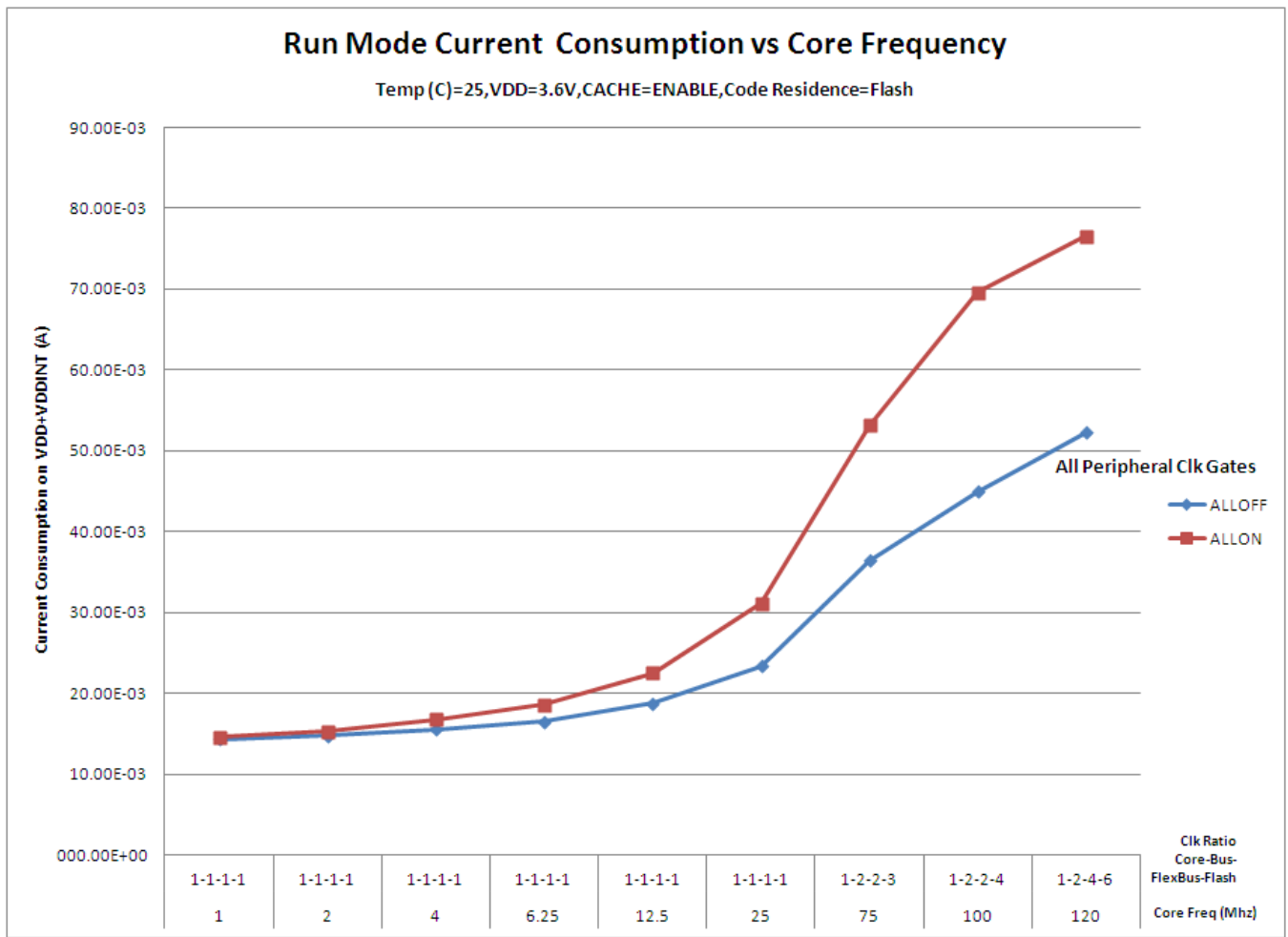


Figure 3. Run mode supply current vs. core frequency

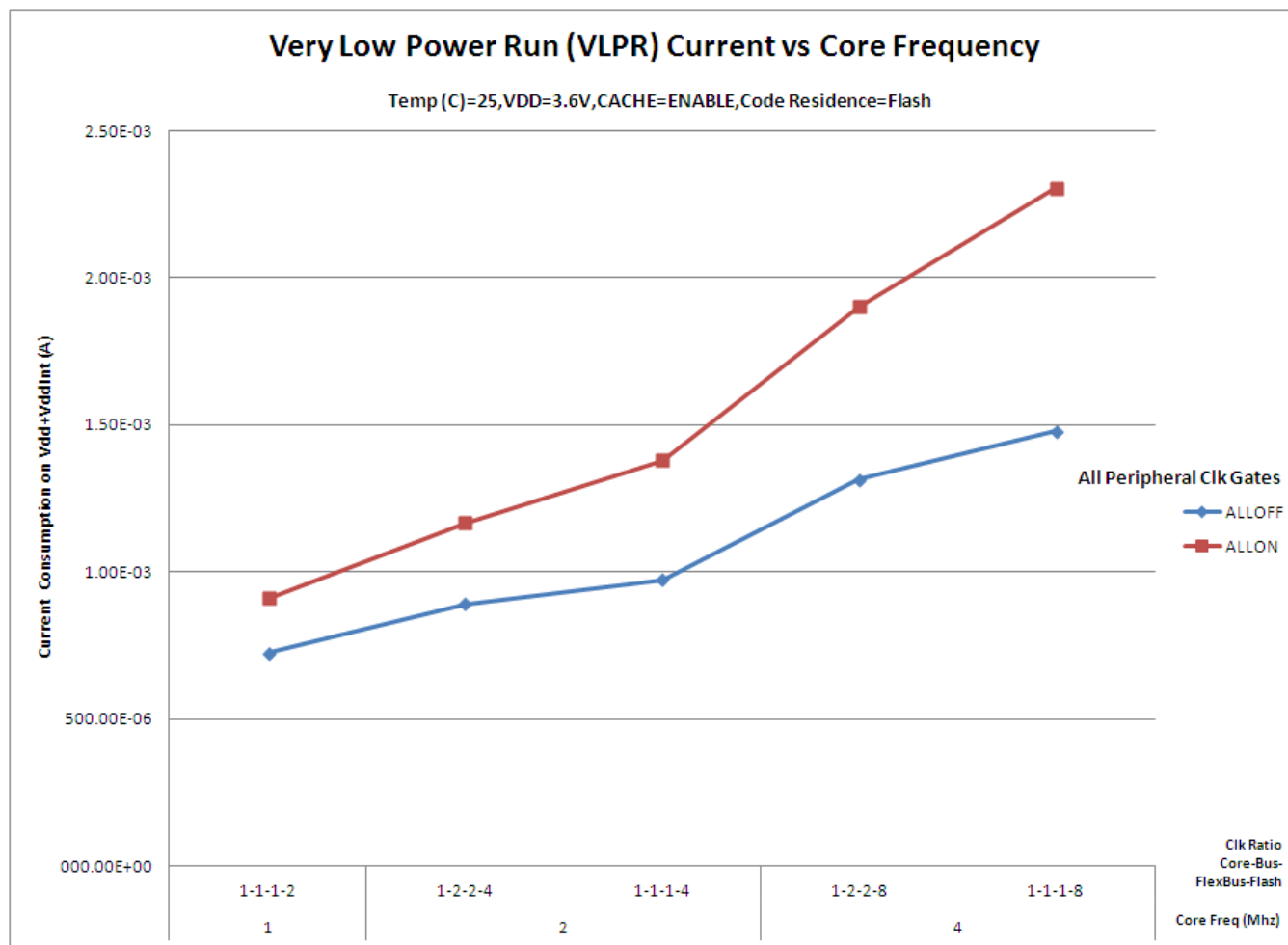


Figure 4. VLPR mode supply current vs. core frequency

5.2.6 EMC radiated emissions operating behaviors

Table 7. EMC radiated emissions operating behaviors for 256MAPBGA

Symbol	Description	Frequency band (MHz)	Typ.	Unit	Notes
V _{RE1}	Radiated emissions voltage, band 1	0.15–50	21	dBμV	1, 2, 3
V _{RE2}	Radiated emissions voltage, band 2	50–150	24	dBμV	
V _{RE3}	Radiated emissions voltage, band 3	150–500	29	dBμV	
V _{RE4}	Radiated emissions voltage, band 4	500–1000	28	dBμV	

1. Determined according to IEC Standard 61967-1, *Integrated Circuits - Measurement of Electromagnetic Emissions, 150 kHz to 1 GHz Part 1: General Conditions and Definitions* and IEC Standard 61967-2, *Integrated Circuits - Measurement of Electromagnetic Emissions, 150 kHz to 1 GHz Part 2: Measurement of Radiated Emissions—TEM Cell and Wideband TEM Cell Method*. Measurements were made while the microcontroller was running basic application code. The reported emission level is the value of the maximum measured emission, rounded up to the next whole number, from among the measured orientations in each frequency range.
2. V_{DD} = 3.3 V, T_A = 25 °C, f_{OSC} = 12 MHz (crystal), f_{SYS} = 72 MHz, f_{BUS} = 72 MHz
3. Determined according to IEC Standard JESD78, *IC Latch-Up Test*

5.2.7 Designing with radiated emissions in mind

To find application notes that provide guidance on designing your system to minimize interference from radiated emissions:

1. Go to www.nxp.com.
2. Perform a keyword search for “EMC design.”

5.2.8 Capacitance attributes

Table 8. Capacitance attributes

Symbol	Description	Min.	Max.	Unit
C_{IN_A}	Input capacitance: analog pins	—	7	pF
C_{IN_D}	Input capacitance: digital pins	—	7	pF
$C_{IN_D_io60}$	Input capacitance: fast digital pins	—	9	pF

5.3 Switching specifications

5.3.1 Device clock specifications

Table 9. Device clock specifications

Symbol	Description	Min.	Max.	Unit	Notes
Normal run mode					
f_{SYS}	System and core clock	—	120	MHz	
f_{SYS_USBFS}	System and core clock when Full Speed USB in operation	20	—	MHz	
f_{ENET}	System and core clock when ethernet in operation	5	—	MHz	
		50	—		
f_{BUS}	Bus clock	—	60	MHz	
FB_CLK	FlexBus clock	—	50	MHz	
f_{FLASH}	Flash clock	—	25	MHz	
f_{LPTMR}	LPTMR clock	—	25	MHz	
VLPR mode ¹					
f_{SYS}	System and core clock	—	4	MHz	
f_{BUS}	Bus clock	—	4	MHz	
FB_CLK	FlexBus clock	—	4	MHz	

Table continues on the next page...

Table 9. Device clock specifications (continued)

Symbol	Description	Min.	Max.	Unit	Notes
f _{FLASH}	Flash clock	—	0.5	MHz	
f _{LPTMR}	LPTMR clock	—	4	MHz	

1. The frequency limitations in VLPR mode here override any frequency specification listed in the timing specification for any other module.

5.3.2 General switching specifications

These general purpose specifications apply to all pins configured for:

- GPIO signaling
- Other peripheral module signaling not explicitly stated elsewhere

Table 10. General switching specifications

Symbol	Description	Min.	Max.	Unit	Notes
	GPIO pin interrupt pulse width (digital glitch filter disabled) — Synchronous path	1.5	—	Bus clock cycles	1, 2
	GPIO pin interrupt pulse width (digital glitch filter disabled, analog filter enabled) — Asynchronous path	100	—	ns	3
	GPIO pin interrupt pulse width (digital glitch filter disabled, analog filter disabled) — Asynchronous path	16	—	ns	3
	External reset pulse width (digital glitch filter disabled)	100	—	ns	3
	Mode select (EZP_CS) hold time after reset deassertion	2	—	Bus clock cycles	
	Port rise and fall time (high drive strength) <ul style="list-style-type: none"> • Slew disabled <ul style="list-style-type: none"> • $1.71 \leq V_{DD} \leq 2.7V$ • $2.7 \leq V_{DD} \leq 3.6V$ • Slew enabled <ul style="list-style-type: none"> • $1.71 \leq V_{DD} \leq 2.7V$ • $2.7 \leq V_{DD} \leq 3.6V$ 	—	14	ns	4
		—	8	ns	
		—	36	ns	
		—	24	ns	
	Port rise and fall time (low drive strength) <ul style="list-style-type: none"> • Slew disabled <ul style="list-style-type: none"> • $1.71 \leq V_{DD} \leq 2.7V$ • $2.7 \leq V_{DD} \leq 3.6V$ • Slew enabled <ul style="list-style-type: none"> • $1.71 \leq V_{DD} \leq 2.7V$ • $2.7 \leq V_{DD} \leq 3.6V$ 	—	14	ns	5
		—	8	ns	
		—	36	ns	
		—	24	ns	
t _{io50}	Port rise and fall time (high drive strength) <ul style="list-style-type: none"> • Slew disabled 				6

Table continues on the next page...

Table 10. General switching specifications (continued)

Symbol	Description	Min.	Max.	Unit	Notes
	<ul style="list-style-type: none"> • $1.71 \leq V_{DD} \leq 2.7V$ • $2.7 \leq V_{DD} \leq 3.6V$ • Slew enabled • $1.71 \leq V_{DD} \leq 2.7V$ • $2.7 \leq V_{DD} \leq 3.6V$ 	—	7	ns	—
		—	3	ns	—
		—	28	ns	—
		—	14	ns	—
t_{i050}	Port rise and fall time (low drive strength)				-1
	<ul style="list-style-type: none"> • Slew disabled • $1.71 \leq V_{DD} \leq 2.7V$ • $2.7 \leq V_{DD} \leq 3.6V$ • Slew enabled • $1.71 \leq V_{DD} \leq 2.7V$ • $2.7 \leq V_{DD} \leq 3.6V$ 	—	18	ns	—
		—	9	ns	—
		—	48	ns	—
		—	24	ns	—
t_{i060}	Port rise and fall time (high drive strength)				6
	<ul style="list-style-type: none"> • Slew disabled • $1.71 \leq V_{DD} \leq 2.7V$ • $2.7 \leq V_{DD} \leq 3.6V$ • Slew enabled • $1.71 \leq V_{DD} \leq 2.7V$ • $2.7 \leq V_{DD} \leq 3.6V$ 	—	6	ns	—
		—	3	ns	—
		—	28	ns	—
		—	14	ns	—
t_{i060}	Port rise and fall time (low drive strength)				-1
	<ul style="list-style-type: none"> • Slew disabled • $1.71 \leq V_{DD} \leq 2.7V$ • $2.7 \leq V_{DD} \leq 3.6V$ • Slew enabled • $1.71 \leq V_{DD} \leq 2.7V$ • $2.7 \leq V_{DD} \leq 3.6V$ 	—	18	ns	—
		—	6	ns	—
		—	48	ns	—
		—	24	ns	—

1. This is the minimum pulse width that is guaranteed to pass through the pin synchronization circuitry. Shorter pulses may or may not be recognized. In Stop, VLPS, LLS, and VLLSx modes, the synchronizer is bypassed so shorter pulses can be recognized in that case.
2. The greater synchronous and asynchronous timing must be met.
3. This is the minimum pulse width that is guaranteed to be recognized as a pin interrupt request in Stop, VLPS, LLS, and VLLSx modes.
4. 75 pF load
5. 15 pF load
6. 25 pF load

5.4 Thermal specifications

5.4.1 Thermal operating requirements

Table 11. Thermal operating requirements

Symbol	Description	Min.	Max.	Unit
T _J	Die junction temperature	-40	95	°C
T _A	Ambient temperature ¹	-40	85	°C

- Maximum T_A can be exceeded only if the user ensures that T_J does not exceed maximum T_J. The simplest method to determine T_J is:

$$T_J = T_A + R_{\theta JA} \times \text{chip power dissipation}$$

5.4.2 Thermal attributes

Board type	Symbol	Description	143 WLCSP	Unit	Notes
Single-layer (1s)	R _{θJA}	Thermal resistance, junction to ambient (natural convection)	77	°C/W	1, 2
Four-layer (2s2p)	R _{θJA}	Thermal resistance, junction to ambient (natural convection)	35	°C/W	1, 2, 3
—	R _{θJB}	Thermal resistance, junction to board	10	°C/W	4
—	R _{θJC}	Thermal resistance, junction to case	1.9	°C/W	5
—	Ψ _{JT}	Thermal characterization parameter, junction to package top outside center (natural convection)	2	°C/W	6

- Junction temperature is a function of die size, on-chip power dissipation, package thermal resistance, mounting site (board) temperature, ambient temperature, air flow, power dissipation of other components on the board, and board thermal resistance.
- Determined according to JEDEC Standard JESD51-2, *Integrated Circuits Thermal Test Method Environmental Conditions – Natural Convection (Still Air)* with the single layer board horizontal. Board meets JESD51-9 specification.
- Determined according to JEDEC Standard JESD51-6, *Integrated Circuits Thermal Test Method Environmental Conditions – Forced Convection (Moving Air)* with the board horizontal.
- Determined according to JEDEC Standard JESD51-8, *Integrated Circuit Thermal Test Method Environmental Conditions – Junction-to-Board*. Board temperature is measured on the top surface of the board near the package.
- Determined according to Method 1012.1 of MIL-STD 883, *Test Method Standard, Microcircuits*, with the cold plate temperature used for the case temperature. The value includes the thermal resistance of the interface material between the top of the package and the cold plate.

- 6. Determined according to JEDEC Standard JESD51-2, *Integrated Circuits Thermal Test Method Environmental Conditions – Natural Convection (Still Air)*.

6 Peripheral operating requirements and behaviors

6.1 Core modules

6.1.1 Debug trace timing specifications

Table 12. Debug trace operating behaviors

Symbol	Description	Min.	Max.	Unit
T_{cyc}	Clock period	Frequency dependent		MHz
T_{wl}	Low pulse width	2	—	ns
T_{wh}	High pulse width	2	—	ns
T_r	Clock and data rise time	—	3	ns
T_f	Clock and data fall time	—	3	ns
T_s	Data setup	3	—	ns
T_h	Data hold	2	—	ns

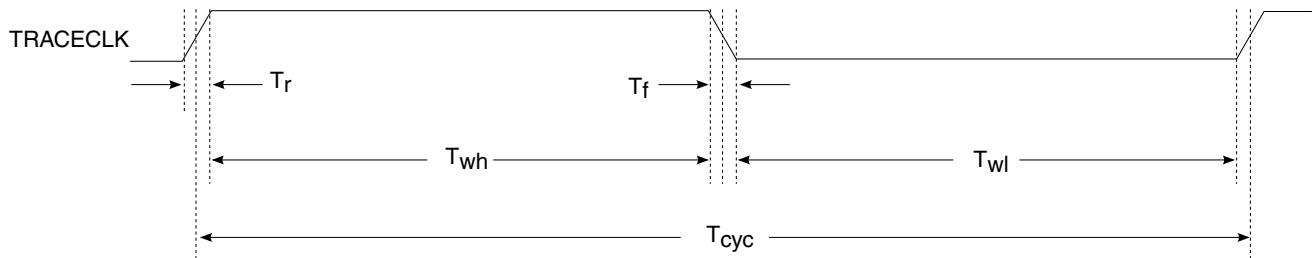


Figure 5. TRACE_CLKOUT specifications

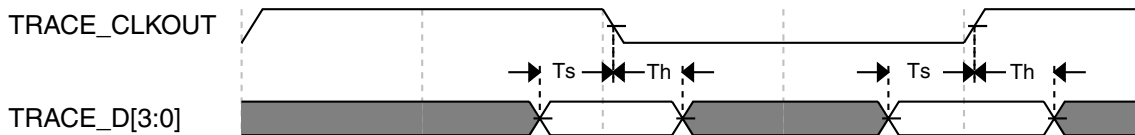


Figure 6. Trace data specifications

6.1.2 JTAG electricals

Table 13. JTAG limited voltage range electricals

Symbol	Description	Min.	Max.	Unit
	Operating voltage	2.7	3.6	V
J1	TCLK frequency of operation <ul style="list-style-type: none"> • Boundary Scan • JTAG and CJTAG • Serial Wire Debug 	0 0 0	10 25 50	MHz
J2	TCLK cycle period	1/J1	—	ns
J3	TCLK clock pulse width <ul style="list-style-type: none"> • Boundary Scan • JTAG and CJTAG • Serial Wire Debug 	50 20 10	— — —	ns ns ns
J4	TCLK rise and fall times	—	3	ns
J5	Boundary scan input data setup time to TCLK rise	20	—	ns
J6	Boundary scan input data hold time after TCLK rise	2.4	—	ns
J7	TCLK low to boundary scan output data valid	—	25	ns
J8	TCLK low to boundary scan output high-Z	—	25	ns
J9	TMS, TDI input data setup time to TCLK rise	8	—	ns
J10	TMS, TDI input data hold time after TCLK rise	1	—	ns
J11	TCLK low to TDO data valid	—	17	ns
J12	TCLK low to TDO high-Z	—	17	ns
J13	$\overline{\text{TRST}}$ assert time	100	—	ns
J14	$\overline{\text{TRST}}$ setup time (negation) to TCLK high	8	—	ns

Table 14. JTAG full voltage range electricals

Symbol	Description	Min.	Max.	Unit
	Operating voltage	1.71	3.6	V
J1	TCLK frequency of operation <ul style="list-style-type: none"> • Boundary Scan • JTAG and CJTAG • Serial Wire Debug 	0 0 0	10 20 40	MHz
J2	TCLK cycle period	1/J1	—	ns
J3	TCLK clock pulse width <ul style="list-style-type: none"> • Boundary Scan • JTAG and CJTAG • Serial Wire Debug 	50 25 12.5	— — —	ns ns ns
J4	TCLK rise and fall times	—	3	ns

Table continues on the next page...

Table 14. JTAG full voltage range electricals (continued)

Symbol	Description	Min.	Max.	Unit
J5	Boundary scan input data setup time to TCLK rise	20	—	ns
J6	Boundary scan input data hold time after TCLK rise	2.4	—	ns
J7	TCLK low to boundary scan output data valid	—	25	ns
J8	TCLK low to boundary scan output high-Z	—	25	ns
J9	TMS, TDI input data setup time to TCLK rise	8	—	ns
J10	TMS, TDI input data hold time after TCLK rise	1.4	—	ns
J11	TCLK low to TDO data valid	—	22.1	ns
J12	TCLK low to TDO high-Z	—	22.1	ns
J13	TRST assert time	100	—	ns
J14	TRST setup time (negation) to TCLK high	8	—	ns

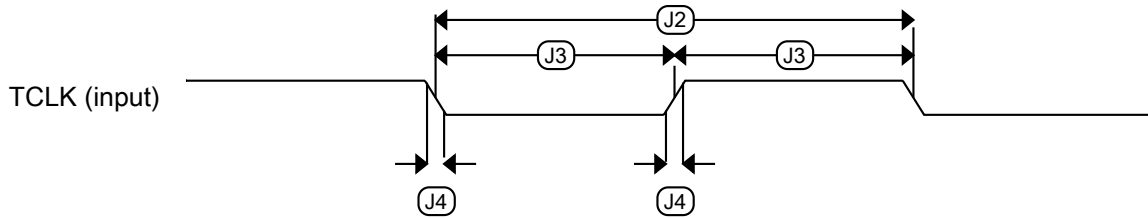


Figure 7. Test clock input timing

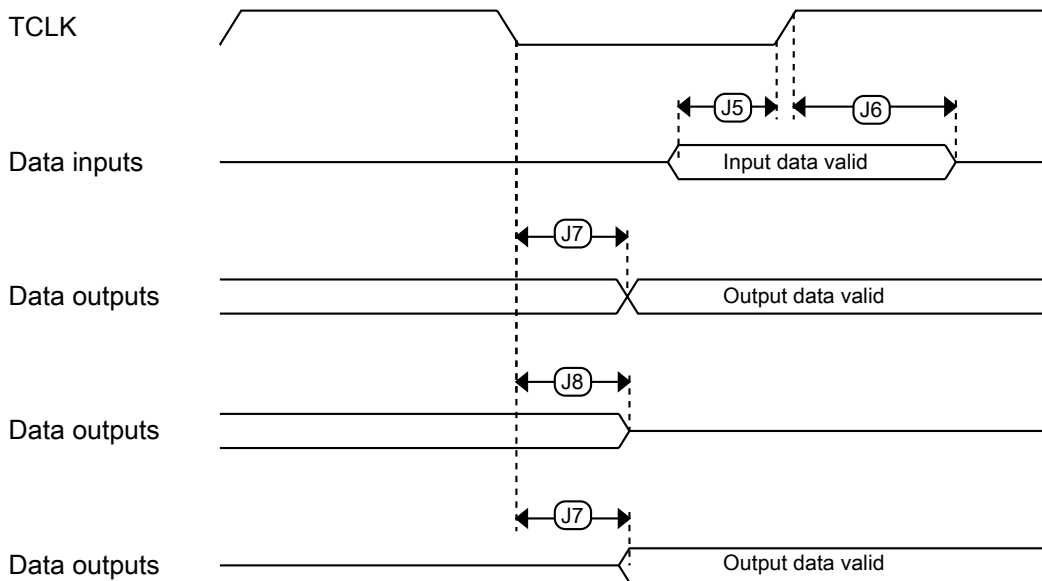


Figure 8. Boundary scan (JTAG) timing

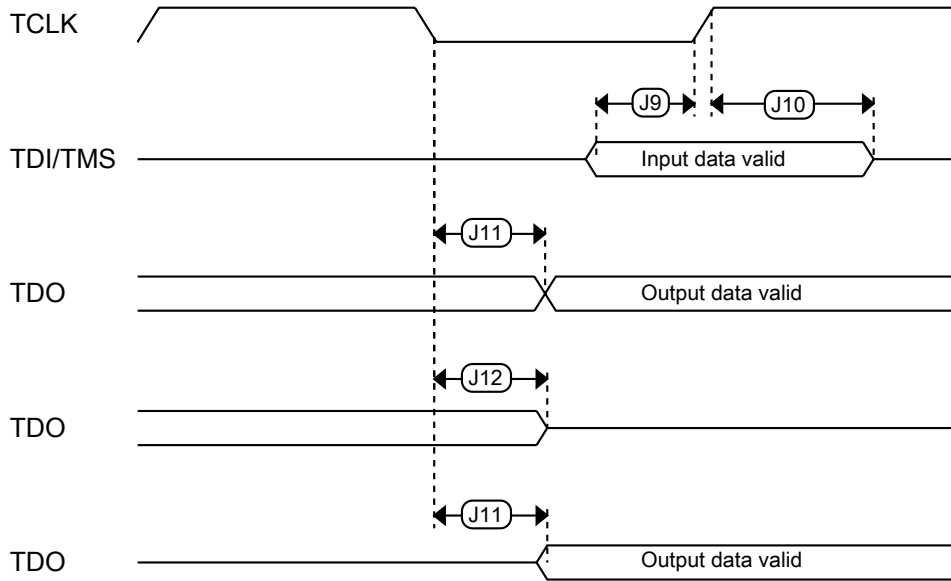


Figure 9. Test Access Port timing

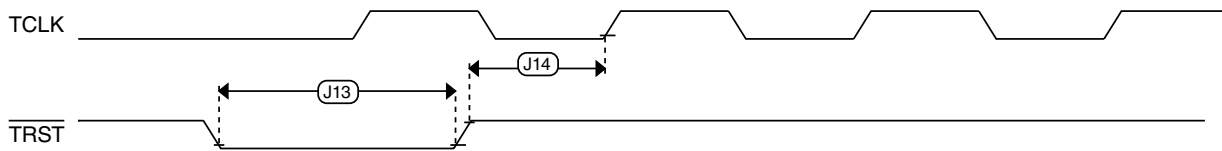


Figure 10. $\overline{\text{TRST}}$ timing

6.2 System modules

There are no specifications necessary for the device's system modules.

6.3 Clock modules

6.3.1 MCG specifications

Table 15. MCG specifications

Symbol	Description	Min.	Typ.	Max.	Unit	Notes	
f_{ints_ft}	Internal reference frequency (slow clock) — factory trimmed at nominal VDD and 25 °C	—	32.768	—	kHz		
f_{ints_t}	Internal reference frequency (slow clock) — user trimmed	31.25	—	38.2	kHz		
$\Delta f_{dco_res_t}$	Resolution of trimmed average DCO output frequency at fixed voltage and temperature — using SCTRIM and SCFTRIM	—	± 0.3	± 0.6	% f_{dco}	1	
$\Delta f_{dco_res_t}$	Resolution of trimmed average DCO output frequency at fixed voltage and temperature — using SCTRIM only	—	± 0.2	± 0.5	% f_{dco}	1	
Δf_{dco_t}	Total deviation of trimmed average DCO output frequency over fixed voltage and temperature range of 0–70°C	—	± 4.5	—	% f_{dco}	1	
f_{intf_ft}	Internal reference frequency (fast clock) — factory trimmed at nominal VDD and 25°C	—	4	—	MHz		
f_{intf_t}	Internal reference frequency (fast clock) — user trimmed at nominal VDD and 25 °C	3	—	5	MHz		
f_{loc_low}	Loss of external clock minimum frequency — RANGE = 00	$(3/5) \times f_{ints_t}$	—	—	kHz		
f_{loc_high}	Loss of external clock minimum frequency — RANGE = 01, 10, or 11	$(16/5) \times f_{ints_t}$	—	—	kHz		
FLL							
f_{fill_ref}	FLL reference frequency range	31.25	—	39.0625	kHz		
f_{dco}	DCO output frequency range	Low range (DRS=00) $640 \times f_{fill_ref}$	20	20.97	25	MHz	2, 3
		Mid range (DRS=01) $1280 \times f_{fill_ref}$	40	41.94	50	MHz	
		Mid-high range (DRS=10) $1920 \times f_{fill_ref}$	60	62.91	75	MHz	
		High range (DRS=11) $2560 \times f_{fill_ref}$	80	83.89	100	MHz	
$f_{dco_t_DMX32}$	DCO output frequency	Low range (DRS=00) $732 \times f_{fill_ref}$	—	23.99	—	MHz	4, 5
		Mid range (DRS=01) $1464 \times f_{fill_ref}$	—	47.97	—	MHz	
		Mid-high range (DRS=10) $2197 \times f_{fill_ref}$	—	71.99	—	MHz	
		High range (DRS=11) $2929 \times f_{fill_ref}$	—	95.98	—	MHz	
J_{cyc_fll}	FLL period jitter	—	180	—	ps		

Table continues on the next page...

Table 15. MCG specifications (continued)

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
	<ul style="list-style-type: none"> $f_{VCO} = 48 \text{ MHz}$ $f_{VCO} = 98 \text{ MHz}$ 	—	150	—		
$t_{fill_acquire}$	FLL target frequency acquisition time	—	—	1	ms	6
PLL0,1						
f_{pll_ref}	PLL reference frequency range	8	—	16	MHz	
f_{vcoclk_2x}	VCO output frequency	180	—	360	MHz	
f_{vcoclk}	PLL output frequency	90	—	180	MHz	
f_{vcoclk_90}	PLL quadrature output frequency	90	—	180	MHz	
I_{pll}	PLL0 operating current <ul style="list-style-type: none"> VCO @ 184 MHz ($f_{osc_hi_1} = 32 \text{ MHz}$, $f_{pll_ref} = 8 \text{ MHz}$, VDIV multiplier = 23) 	—	2.8	—	mA	
I_{pll}	PLL0 operating current <ul style="list-style-type: none"> VCO @ 360 MHz ($f_{osc_hi_1} = 32 \text{ MHz}$, $f_{pll_ref} = 8 \text{ MHz}$, VDIV multiplier = 45) 	—	4.7	—	mA	7
I_{pll}	PLL1 operating current <ul style="list-style-type: none"> VCO @ 184 MHz ($f_{osc_hi_1} = 32 \text{ MHz}$, $f_{pll_ref} = 8 \text{ MHz}$, VDIV multiplier = 23) 	—	2.3	—	mA	7
I_{pll}	PLL1 operating current <ul style="list-style-type: none"> VCO @ 360 MHz ($f_{osc_hi_1} = 32 \text{ MHz}$, $f_{pll_ref} = 8 \text{ MHz}$, VDIV multiplier = 45) 	—	3.6	—	mA	7
t_{pll_lock}	Lock detector detection time	—	—	$100 \times 10^{-6} + 1075(1/f_{pll_ref})$	s	8
J_{cyc_pll}	PLL period jitter (RMS) <ul style="list-style-type: none"> $f_{vco} = 180 \text{ MHz}$ $f_{vco} = 360 \text{ MHz}$ 	—	100	—	ps	9
J_{acc_pll}	PLL accumulated jitter over 1 μ s (RMS) <ul style="list-style-type: none"> $f_{vco} = 180 \text{ MHz}$ $f_{vco} = 360 \text{ MHz}$ 	—	600	—	ps	10
		—	300	—	ps	

- This parameter is measured with the internal reference (slow clock) being used as a reference to the FLL (FEI clock mode).
- These typical values listed are with the slow internal reference clock (FEI) using factory trim and DMX32=0.
- The resulting system clock frequencies should not exceed their maximum specified values. The DCO frequency deviation (Δf_{dco_t}) over voltage and temperature should be considered.
- These typical values listed are with the slow internal reference clock (FEI) using factory trim and DMX32=1.
- The resulting clock frequency must not exceed the maximum specified clock frequency of the device.
- This specification applies to any time the FLL reference source or reference divider is changed, trim value is changed, DMX32 bit is changed, DRS bits are changed, or changing from FLL disabled (BLPE, BLPI) to FLL enabled (FEI, FEE, FBE, FBI). If a crystal/resonator is being used as the reference, this specification assumes it is already running.
- Excludes any oscillator currents that are also consuming power while PLL is in operation.
- This specification applies to any time the PLL VCO divider or reference divider is changed, or changing from PLL disabled (BLPE, BLPI) to PLL enabled (PBE, PEE). If a crystal/resonator is being used as the reference, this specification assumes it is already running.
- This specification was obtained using a Freescale developed PCB. PLL jitter is dependent on the noise characteristics of each PCB and results will vary.
- Accumulated jitter depends on VCO frequency and VDIV.

6.3.2 Oscillator electrical specifications

6.3.2.1 Oscillator DC electrical specifications

Table 16. Oscillator DC electrical specifications

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
V _{DD}	Supply voltage	1.71	—	3.6	V	
I _{DDOSC}	Supply current — low-power mode (HGO=0) <ul style="list-style-type: none"> • 32 kHz • 4 MHz • 8 MHz (RANGE=01) • 16 MHz • 24 MHz • 32 MHz 	—	500	—	nA	1
		—	200	—	μA	
		—	300	—	μA	
		—	950	—	μA	
		—	1.2	—	mA	
		—	1.5	—	mA	
I _{DDOSC}	Supply current — high-gain mode (HGO=1) <ul style="list-style-type: none"> • 32 kHz • 4 MHz • 8 MHz (RANGE=01) • 16 MHz • 24 MHz • 32 MHz 	—	25	—	μA	1
		—	400	—	μA	
		—	500	—	μA	
		—	2.5	—	mA	
		—	3	—	mA	
		—	4	—	mA	
C _x	EXTAL load capacitance	—	—	—		2, 3
C _y	XTAL load capacitance	—	—	—		2, 3
R _F	Feedback resistor — low-frequency, low-power mode (HGO=0)	—	—	—	MΩ	2, 4
	Feedback resistor — low-frequency, high-gain mode (HGO=1)	—	10	—	MΩ	
	Feedback resistor — high-frequency, low-power mode (HGO=0)	—	—	—	MΩ	
	Feedback resistor — high-frequency, high-gain mode (HGO=1)	—	1	—	MΩ	
R _S	Series resistor — low-frequency, low-power mode (HGO=0)	—	—	—	kΩ	
	Series resistor — low-frequency, high-gain mode (HGO=1)	—	200	—	kΩ	
	Series resistor — high-frequency, low-power mode (HGO=0)	—	—	—	kΩ	
	Series resistor — high-frequency, high-gain mode (HGO=1)	—	0	—	kΩ	

Table continues on the next page...

Table 16. Oscillator DC electrical specifications (continued)

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
V_{pp}^5	Peak-to-peak amplitude of oscillation (oscillator mode) — low-frequency, low-power mode (HGO=0)	—	0.6	—	V	
	Peak-to-peak amplitude of oscillation (oscillator mode) — low-frequency, high-gain mode (HGO=1)	—	V_{DD}	—	V	
	Peak-to-peak amplitude of oscillation (oscillator mode) — high-frequency, low-power mode (HGO=0)	—	0.6	—	V	
	Peak-to-peak amplitude of oscillation (oscillator mode) — high-frequency, high-gain mode (HGO=1)	—	V_{DD}	—	V	

1. $V_{DD}=3.3$ V, Temperature =25 °C
2. See crystal or resonator manufacturer's recommendation
3. C_x and C_y can be provided by using either integrated capacitors or external components.
4. When low-power mode is selected, R_F is integrated and must not be attached externally.
5. The EXTAL and XTAL pins should only be connected to required oscillator components and must not be connected to any other device.

6.3.2.2 Oscillator frequency specifications

Table 17. Oscillator frequency specifications

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
f_{osc_lo}	Oscillator crystal or resonator frequency — low-frequency mode (MCG_C2[RANGE]=00)	32	—	40	kHz	
$f_{osc_hi_1}$	Oscillator crystal or resonator frequency — high-frequency mode (low range) (MCG_C2[RANGE]=01)	3	—	8	MHz	1
$f_{osc_hi_2}$	Oscillator crystal or resonator frequency — high frequency mode (high range) (MCG_C2[RANGE]=1x)	8	—	32	MHz	
f_{ec_extal}	Input clock frequency (external clock mode)	—	—	60	MHz	2, 3
t_{dc_extal}	Input clock duty cycle (external clock mode)	40	50	60	%	
t_{cst}	Crystal startup time — 32 kHz low-frequency, low-power mode (HGO=0)	—	1000	—	ms	4, 5
	Crystal startup time — 32 kHz low-frequency, high-gain mode (HGO=1)	—	500	—	ms	
	Crystal startup time — 8 MHz high-frequency (MCG_C2[RANGE]=01), low-power mode (HGO=0)	—	0.6	—	ms	
	Crystal startup time — 8 MHz high-frequency (MCG_C2[RANGE]=01), high-gain mode (HGO=1)	—	1	—	ms	

1. Frequencies less than 8 MHz are not in the PLL range.
2. Other frequency limits may apply when external clock is being used as a reference for the FLL or PLL.
3. When transitioning from FEI or FBI to FBE mode, restrict the frequency of the input clock so that, when it is divided by FRDIV, it remains within the limits of the DCO input clock frequency.

Peripheral operating requirements and behaviors

- Proper PC board layout procedures must be followed to achieve specifications.
- Crystal startup time is defined as the time between the oscillator being enabled and the OSCINIT bit in the MCG_S register being set.

NOTE

The 32 kHz oscillator works in low power mode by default and cannot be moved into high power/gain mode.

6.3.3 32 kHz oscillator electrical characteristics

6.3.3.1 32 kHz oscillator DC electrical specifications

Table 18. 32kHz oscillator DC electrical specifications

Symbol	Description	Min.	Typ.	Max.	Unit
V_{BAT}	Supply voltage	1.71	—	3.6	V
R_F	Internal feedback resistor	—	100	—	M Ω
C_{para}	Parasitical capacitance of EXTAL32 and XTAL32	—	5	7	pF
V_{pp} ¹	Peak-to-peak amplitude of oscillation	—	0.6	—	V

- When a crystal is being used with the 32 kHz oscillator, the EXTAL32 and XTAL32 pins should only be connected to required oscillator components and must not be connected to any other devices.

6.3.3.2 32 kHz oscillator frequency specifications

Table 19. 32 kHz oscillator frequency specifications

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
f_{osc_lo}	Oscillator crystal	—	32.768	—	kHz	
t_{start}	Crystal start-up time	—	1000	—	ms	1
$V_{ec_extal32}$	Externally provided input clock amplitude	700	—	V_{BAT}	mV	2, 3

- Proper PC board layout procedures must be followed to achieve specifications.
- This specification is for an externally supplied clock driven to EXTAL32 and does not apply to any other clock input. The oscillator remains enabled and XTAL32 must be left unconnected.
- The parameter specified is a peak-to-peak value and V_{IH} and V_{IL} specifications do not apply. The voltage of the applied clock must be within the range of V_{SS} to V_{BAT} .

6.4 Memories and memory interfaces

6.4.1 Flash (FTFE) electrical specifications

This section describes the electrical characteristics of the FTFE module.

6.4.1.1 Flash timing specifications — program and erase

The following specifications represent the amount of time the internal charge pumps are active and do not include command overhead.

Table 20. NVM program/erase timing specifications

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
$t_{hvp\text{gm}8}$	Program Phrase high-voltage time	—	7.5	18	μs	
$t_{h\text{versscr}}$	Erase Flash Sector high-voltage time	—	13	113	ms	1
$t_{h\text{versblk}128\text{k}}$	Erase Flash Block high-voltage time for 128 KB	—	104	1808	ms	1
$t_{h\text{versblk}256\text{k}}$	Erase Flash Block high-voltage time for 256 KB	—	208	3616	ms	1

1. Maximum time based on expectations at cycling end-of-life.

6.4.1.2 Flash timing specifications — commands

Table 21. Flash command timing specifications

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
$t_{rd1\text{blk}128\text{k}}$	Read 1s Block execution time					
$t_{rd1\text{blk}256\text{k}}$	<ul style="list-style-type: none"> 128 KB data flash 256 KB program flash 256 KB data flash 	—	—	0.5	ms	
		—	—	1.0	ms	
$t_{rd1\text{sec}4\text{k}}$	Read 1s Section execution time (4 KB flash)	—	—	100	μs	1
$t_{pgm\text{chk}}$	Program Check execution time	—	—	80	μs	1
$t_{rd\text{rsrc}}$	Read Resource execution time	—	—	40	μs	1
t_{pgm8}	Program Phrase execution time	—	70	150	μs	
$t_{ers\text{blk}128\text{k}}$	Erase Flash Block execution time					2
$t_{ers\text{blk}256\text{k}}$	<ul style="list-style-type: none"> 128 KB data flash 256 KB program flash 256 KB data flash 	—	110	925	ms	
		—	220	1850	ms	
$t_{ers\text{scr}}$	Erase Flash Sector execution time	—	15	115	ms	2
$t_{pgm\text{sec}4\text{k}}$	Program Section execution time (4KB flash)	—	20	—	ms	
$t_{rd1\text{alln}}$	Read 1s All Blocks execution time					
	<ul style="list-style-type: none"> Program flash only devices 	—	—	3.4	ms	
$t_{rd\text{once}}$	Read Once execution time	—	—	30	μs	1
$t_{pgm\text{once}}$	Program Once execution time	—	70	—	μs	
$t_{ers\text{all}}$	Erase All Blocks execution time	—	650	5600	ms	2
t_{vfykey}	Verify Backdoor Access Key execution time	—	—	30	μs	1
$t_{\text{swap}x01}$	Swap Control execution time					
	<ul style="list-style-type: none"> control code 0x01 	—	200	—	μs	

Table 21. Flash command timing specifications

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
$t_{\text{swap}02}$	• control code 0x02	—	70	150	μs	
$t_{\text{swap}04}$	• control code 0x04	—	70	150	μs	
$t_{\text{swap}08}$	• control code 0x08	—	—	30	μs	

1. Assumes 25MHz or greater flash clock frequency.
2. Maximum times for erase parameters based on expectations at cycling end-of-life.

6.4.1.3 Flash high voltage current behaviors

Table 22. Flash high voltage current behaviors

Symbol	Description	Min.	Typ.	Max.	Unit
$I_{\text{DD_PGM}}$	Average current adder during high voltage flash programming operation	—	3.5	7.5	mA
$I_{\text{DD_ERS}}$	Average current adder during high voltage flash erase operation	—	1.5	4.0	mA

6.4.1.4 Reliability specifications

Table 23. NVM reliability specifications

Symbol	Description	Min.	Typ. ¹	Max.	Unit	Notes
Program Flash						
$t_{\text{nv}m\text{re}t\text{p}10\text{k}}$	Data retention after up to 10 K cycles	5	50	—	years	
$t_{\text{nv}m\text{re}t\text{p}1\text{k}}$	Data retention after up to 1 K cycles	20	100	—	years	
$\eta_{\text{nv}m\text{cyc}p}$	Cycling endurance	10 K	50 K	—	cycles	2

1. Typical data retention values are based on measured response accelerated at high temperature and derated to a constant 25°C use profile. Engineering Bulletin EB618 does not apply to this technology. Typical endurance defined in Engineering Bulletin EB619.
2. Cycling endurance represents number of program/erase cycles at $-40^{\circ}\text{C} \leq T_j \leq 125^{\circ}\text{C}$.

6.4.2 EzPort switching specifications

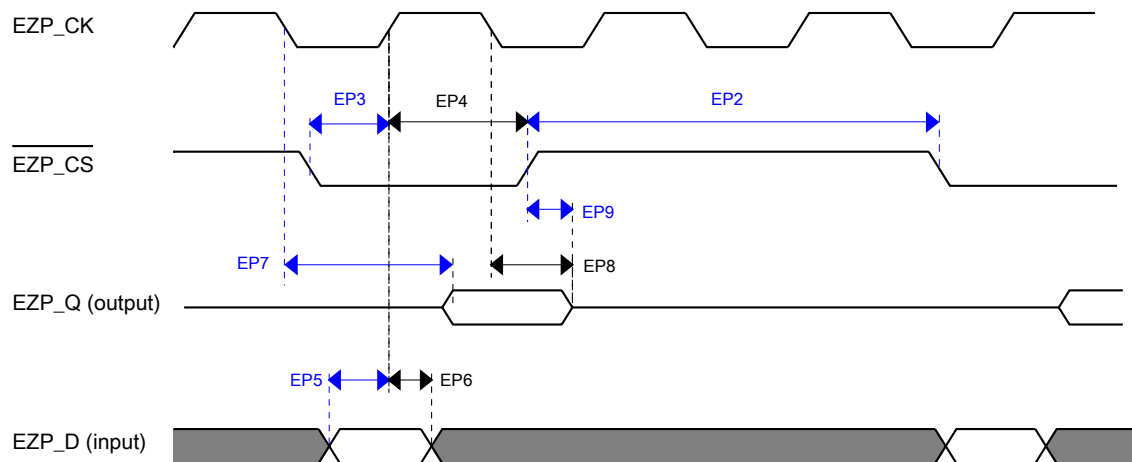
Table 24. EzPort switching specifications

Num	Description	Min.	Max.	Unit
	Operating voltage	1.71	3.6	V
EP1	EZP_CK frequency of operation (all commands except READ)	—	$f_{\text{SYS}}/2$	MHz
EP1a	EZP_CK frequency of operation (READ command)	—	$f_{\text{SYS}}/8$	MHz
EP2	EZP_CS negation to next EZP_CS assertion	$2 \times t_{\text{EZP_CK}}$	—	ns
EP3	EZP_CS input valid to EZP_CK high (setup)	5	—	ns

Table continues on the next page...

Table 24. EzPort switching specifications (continued)

Num	Description	Min.	Max.	Unit
EP4	EZP_CK high to EZP_CS input invalid (hold)	5	—	ns
EP5	EZP_D input valid to EZP_CK high (setup)	2	—	ns
EP6	EZP_CK high to EZP_D input invalid (hold)	5	—	ns
EP7	EZP_CK low to EZP_Q output valid	—	16	ns
EP8	EZP_CK low to EZP_Q output invalid (hold)	0	—	ns
EP9	EZP_CS negation to EZP_Q tri-state	—	12	ns

**Figure 11. EzPort Timing Diagram**

6.4.3 NAND flash controller specifications

The NAND flash controller (NFC) implements the interface to standard NAND flash memory devices. This section describes the timing parameters of the NFC.

In the following table:

- T_H is the flash clock high time and
- T_L is flash clock low time,

which are defined as:

$$T_{NFC} = T_L + T_H = \frac{T_{\text{input clock}}}{\text{SCALER}}$$

The SCALER value is derived from the fractional divider specified in the SIM's CLKDIV4 register:

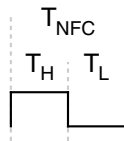
$$\text{SCALER} = \frac{\text{SIM_CLKDIV4[NFCFRAC]} + 1}{\text{SIM_CLKDIV4[NFCDIV]} + 1}$$

In case the reciprocal of SCALER is an integer, the duty cycle of NFC clock is 50%, means $T_H = T_L$. In case the reciprocal of SCALER is not an integer:

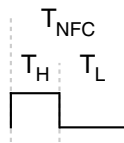
$$T_L = (1 + \text{SCALER} / 2) \times \frac{T_{\text{NFC}}}{2}$$

$$T_H = (1 - \text{SCALER} / 2) \times \frac{T_{\text{NFC}}}{2}$$

For example, if SCALER is 0.2, then $T_H = T_L = T_{\text{NFC}}/2$.



However, if SCALER is 0.667, then $T_L = 2/3 \times T_{\text{NFC}}$ and $T_H = 1/3 \times T_{\text{NFC}}$.



NOTE

The reciprocal of SCALER must be a multiple of 0.5. For example, 1, 1.5, 2, 2.5, etc.

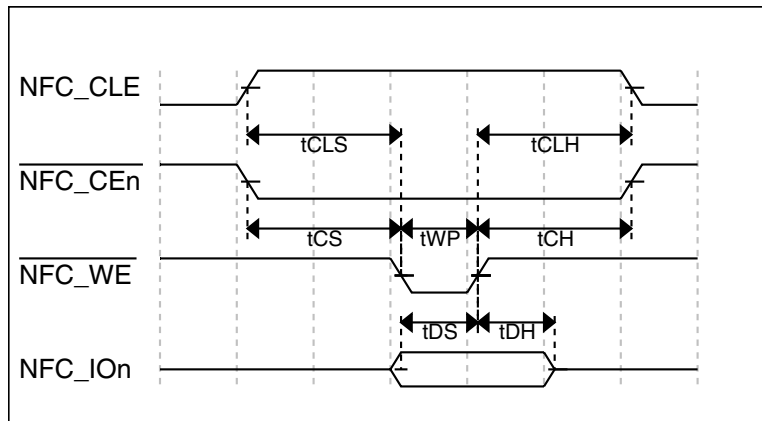
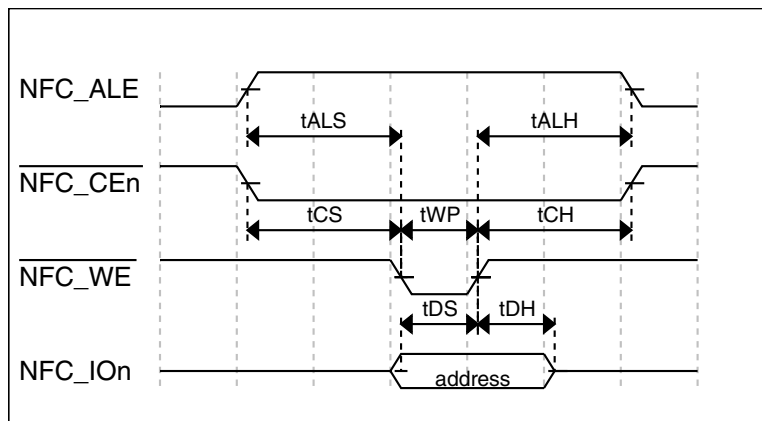
Table 25. NFC specifications

Num	Description	Min.	Max.	Unit
t _{CLS}	NFC_CLE setup time	2T _H + T _L - 1	—	ns
t _{CLH}	NFC_CLE hold time	T _H + T _L - 1	—	ns
t _{CS}	NFC_CEn setup time	2T _H + T _L - 1	—	ns
t _{CH}	NFC_CEn hold time	T _H + T _L	—	ns
t _{WP}	NFC_WP pulse width	T _L - 1	—	ns
t _{ALS}	NFC_ALE setup time	2T _H + T _L	—	ns
t _{ALH}	NFC_ALE hold time	T _H + T _L	—	ns
t _{DS}	Data setup time	T _L - 1	—	ns
t _{DH}	Data hold time	T _H - 1	—	ns
t _{WC}	Write cycle time	T _H + T _L - 1	—	ns
t _{WH}	NFC_WEn hold time	T _H - 1	—	ns

Table continues on the next page...

Table 25. NFC specifications (continued)

Num	Description	Min.	Max.	Unit
t_{RR}	Ready to $\overline{\text{NFC_RE}}$ low	$4T_H + 3T_L + 90$	—	ns
t_{RP}	$\overline{\text{NFC_RE}}$ pulse width	$T_L + 1$	—	ns
t_{RC}	Read cycle time	$T_L + T_H - 1$	—	ns
t_{REH}	$\overline{\text{NFC_RE}}$ high hold time	$T_H - 1$	—	ns
t_{IS}	Data input setup time	11	—	ns

**Figure 12. Command latch cycle timing****Figure 13. Address latch cycle timing**

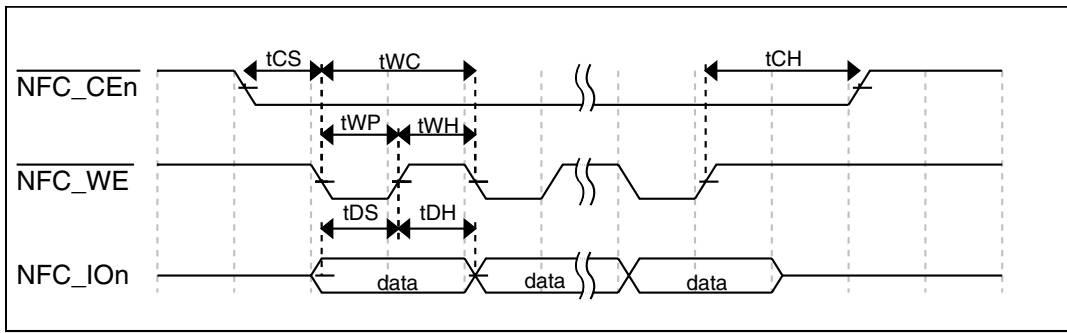


Figure 14. Write data latch cycle timing

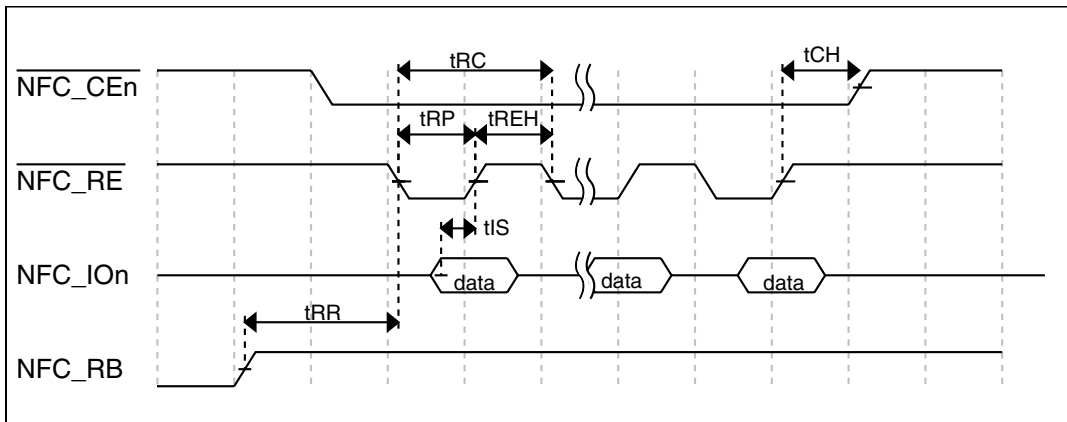


Figure 15. Read data latch cycle timing in Slow mode

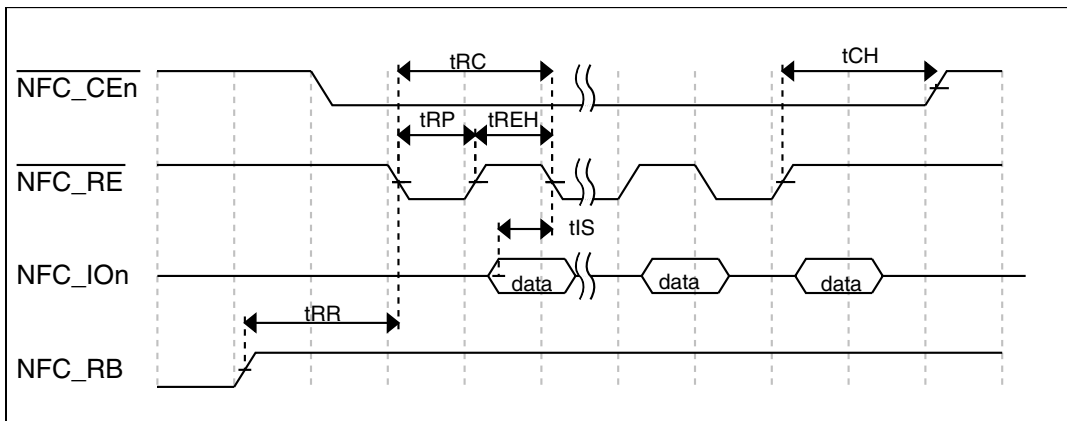


Figure 16. Read data latch cycle timing in Fast mode and EDO mode

6.4.4 Flexbus switching specifications

All processor bus timings are synchronous; input setup/hold and output delay are given in respect to the rising edge of a reference clock, FB_CLK. The FB_CLK frequency may be the same as the internal system bus frequency or an integer divider of that frequency.

The following timing numbers indicate when data is latched or driven onto the external bus, relative to the Flexbus output clock (FB_CLK). All other timing relationships can be derived from these values.

Table 26. Flexbus limited voltage range switching specifications

Num	Description	Min.	Max.	Unit	Notes
	Operating voltage	2.7	3.6	V	
	Frequency of operation	—	FB_CLK	MHz	
FB1	Clock period	20	—	ns	
FB2	Address, data, and control output valid	—	11.5	ns	1
FB3	Address, data, and control output hold	0.5	—	ns	1
FB4	Data and $\overline{\text{FB_TA}}$ input setup	8.5	—	ns	2
FB5	Data and $\overline{\text{FB_TA}}$ input hold	0.5	—	ns	2

1. Specification is valid for all FB_AD[31:0], FB_BE/BWE \overline{n} , FB_CS \overline{n} , FB_OE, FB_R/W, FB_TBST, FB_TSI[1:0], FB_ALE, and $\overline{\text{FB_TS}}$.
2. Specification is valid for all FB_AD[31:0] and $\overline{\text{FB_TA}}$.

Table 27. Flexbus full voltage range switching specifications

Num	Description	Min.	Max.	Unit	Notes
	Operating voltage	1.71	3.6	V	
	Frequency of operation	—	FB_CLK	MHz	
FB1	Clock period	1/FB_CLK	—	ns	
FB2	Address, data, and control output valid	—	13.5	ns	1
FB3	Address, data, and control output hold	0	—	ns	1
FB4	Data and $\overline{\text{FB_TA}}$ input setup	13.7	—	ns	2
FB5	Data and $\overline{\text{FB_TA}}$ input hold	0.5	—	ns	2

1. Specification is valid for all FB_AD[31:0], FB_BE/BWE \overline{n} , FB_CS \overline{n} , FB_OE, FB_R/W, FB_TBST, FB_TSI[1:0], FB_ALE, and $\overline{\text{FB_TS}}$.
2. Specification is valid for all FB_AD[31:0] and $\overline{\text{FB_TA}}$.

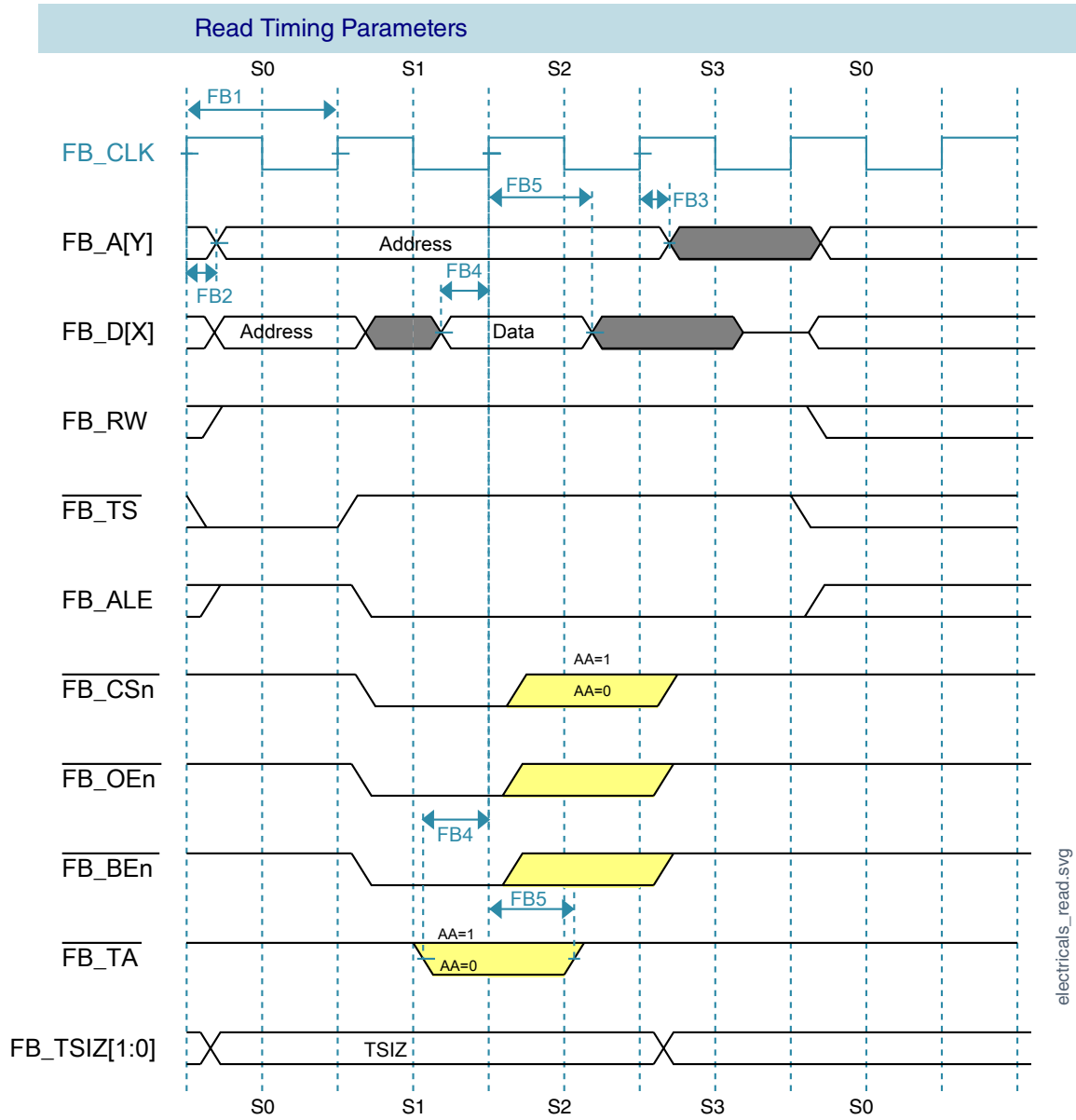


Figure 17. FlexBus read timing diagram

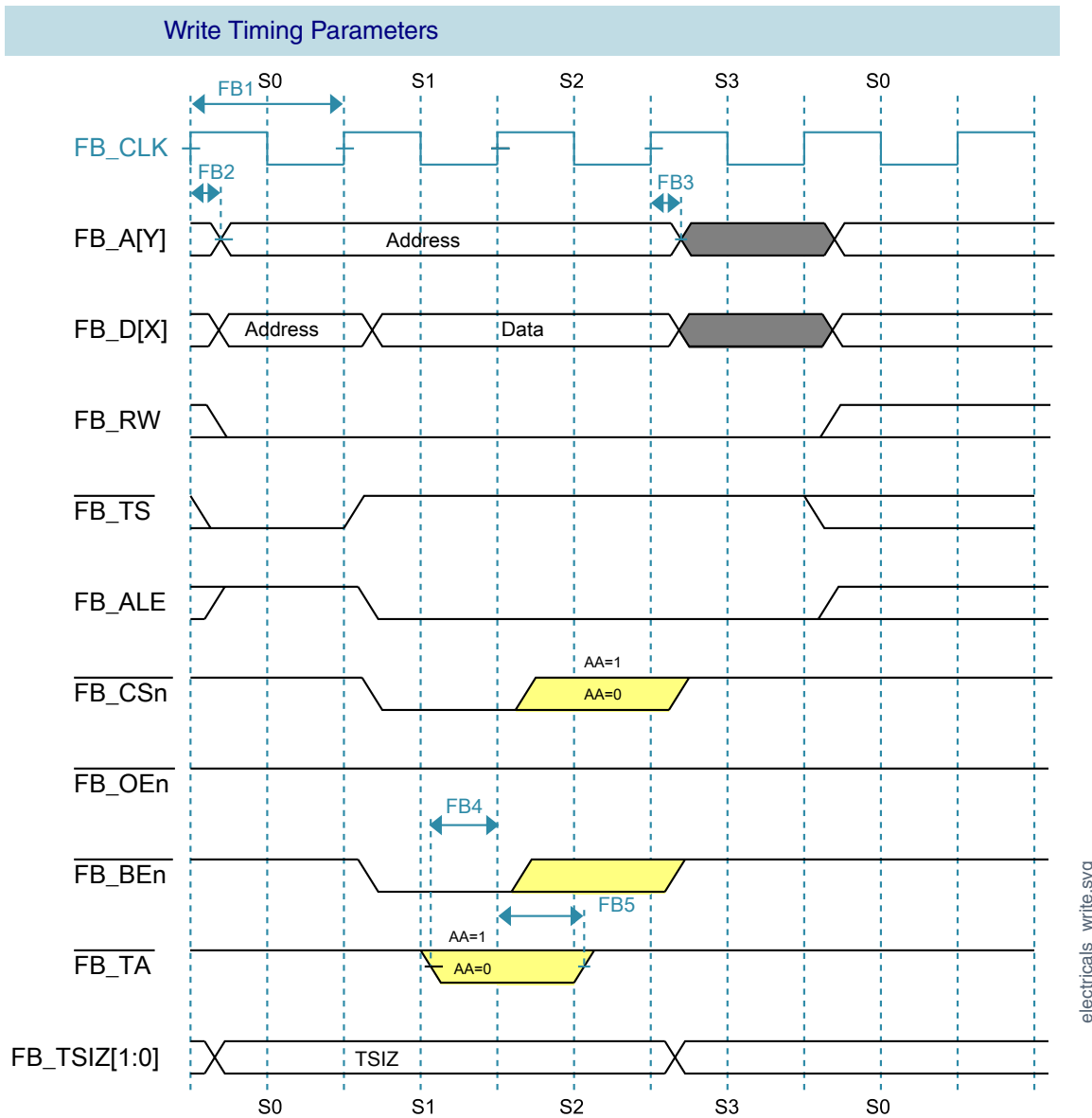


Figure 18. FlexBus write timing diagram

6.5 Security and integrity modules

6.5.1 DryIce Tamper Electrical Specifications

Information about security-related modules is not included in this document and is available only after a nondisclosure agreement (NDA) has been signed. To request an NDA, please contact your local NXP sales representative.

6.6 Analog

6.6.1 ADC electrical specifications

The 16-bit accuracy specifications listed in [Table 28](#) and [Table 29](#) are achievable on the differential pins ADCx_DP0, ADCx_DM0.

The ADCx_DP2 and ADCx_DM2 ADC inputs are connected to the PGA outputs and are not direct device pins. Accuracy specifications for these pins are defined in [Table 30](#) and [Table 31](#).

All other ADC channels meet the 13-bit differential/12-bit single-ended accuracy specifications.

6.6.1.1 16-bit ADC operating conditions

Table 28. 16-bit ADC operating conditions

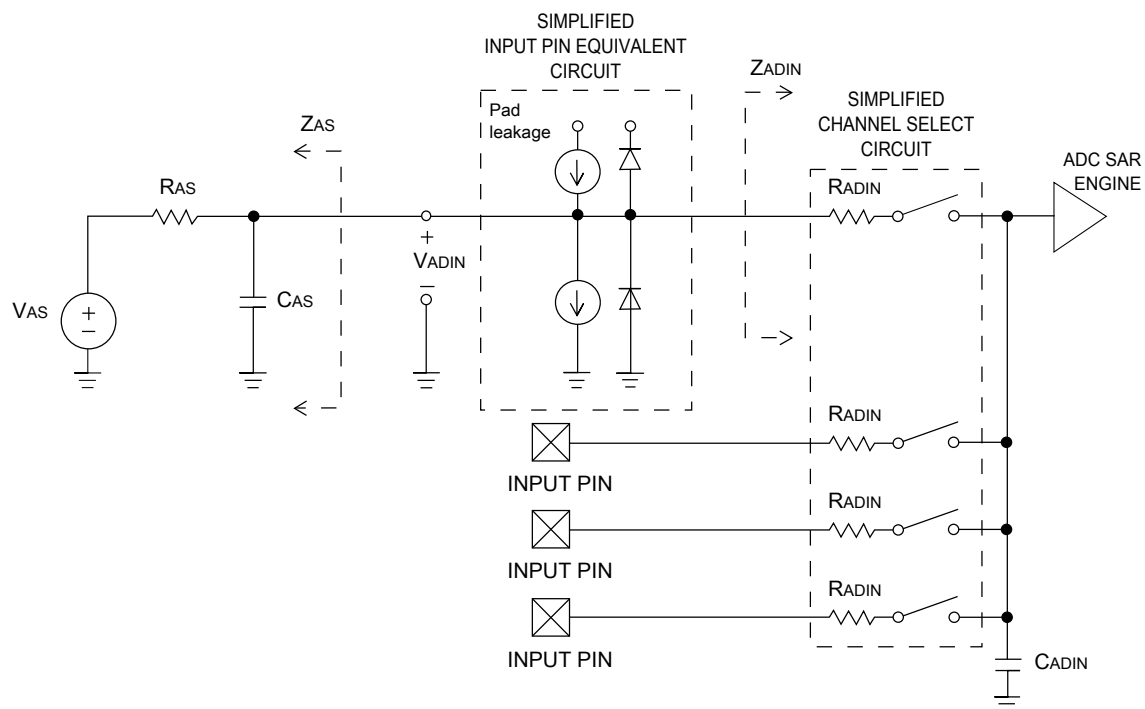
Symbol	Description	Conditions	Min.	Typ. ¹	Max.	Unit	Notes
V _{DDA}	Supply voltage	Absolute	1.71	—	3.6	V	
ΔV _{DDA}	Supply voltage	Delta to V _{DD} (V _{DD} – V _{DDA})	-100	0	+100	mV	2
ΔV _{SSA}	Ground voltage	Delta to V _{SS} (V _{SS} – V _{SSA})	-100	0	+100	mV	2
V _{REFH}	ADC reference voltage high		1.13	V _{DDA}	V _{DDA}	V	
V _{REFL}	ADC reference voltage low		V _{SSA}	V _{SSA}	V _{SSA}	V	
V _{ADIN}	Input voltage	<ul style="list-style-type: none"> 16-bit differential mode All other modes 	V _{REFL} V _{REFL}	— —	31/32 × V _{REFH} V _{REFH}	V	
C _{ADIN}	Input capacitance	<ul style="list-style-type: none"> 16-bit mode 8-bit / 10-bit / 12-bit modes 	— —	8 4	10 5	pF	
R _{ADIN}	Input series resistance		—	2	5	kΩ	
R _{AS}	Analog source resistance (external)	13-bit / 12-bit modes f _{ADCK} < 4 MHz	—	—	5	kΩ	3
f _{ADCK}	ADC conversion clock frequency	≤ 13-bit mode	1.0	—	18.0	MHz	4
f _{ADCK}	ADC conversion clock frequency	16-bit mode	2.0	—	12.0	MHz	4
C _{rate}	ADC conversion rate	≤ 13-bit modes					5

Table continues on the next page...

Table 28. 16-bit ADC operating conditions (continued)

Symbol	Description	Conditions	Min.	Typ. ¹	Max.	Unit	Notes
		No ADC hardware averaging Continuous conversions enabled, subsequent conversion time	20.000	—	818.330	kS/s	
C_{rate}	ADC conversion rate	16-bit mode No ADC hardware averaging Continuous conversions enabled, subsequent conversion time	37.037	—	461.467	kS/s	5

1. Typical values assume $V_{DDA} = 3.0\text{ V}$, $Temp = 25\text{ }^{\circ}\text{C}$, $f_{ADCK} = 1.0\text{ MHz}$, unless otherwise stated. Typical values are for reference only, and are not tested in production.
2. DC potential difference.
3. This resistance is external to MCU. To achieve the best results, the analog source resistance must be kept as low as possible. The results in this data sheet were derived from a system that had $< 8\ \Omega$ analog source resistance. The R_{AS}/C_{AS} time constant should be kept to $< 1\text{ ns}$.
4. To use the maximum ADC conversion clock frequency, $CFG2[ADHSC]$ must be set and $CFG1[ADLPC]$ must be clear.
5. For guidelines and examples of conversion rate calculation, download the [ADC calculator tool](#).

**Figure 19. ADC input impedance equivalency diagram**

6.6.1.2 16-bit ADC electrical characteristics

Table 29. 16-bit ADC characteristics ($V_{REFH} = V_{DDA}$, $V_{REFL} = V_{SSA}$)

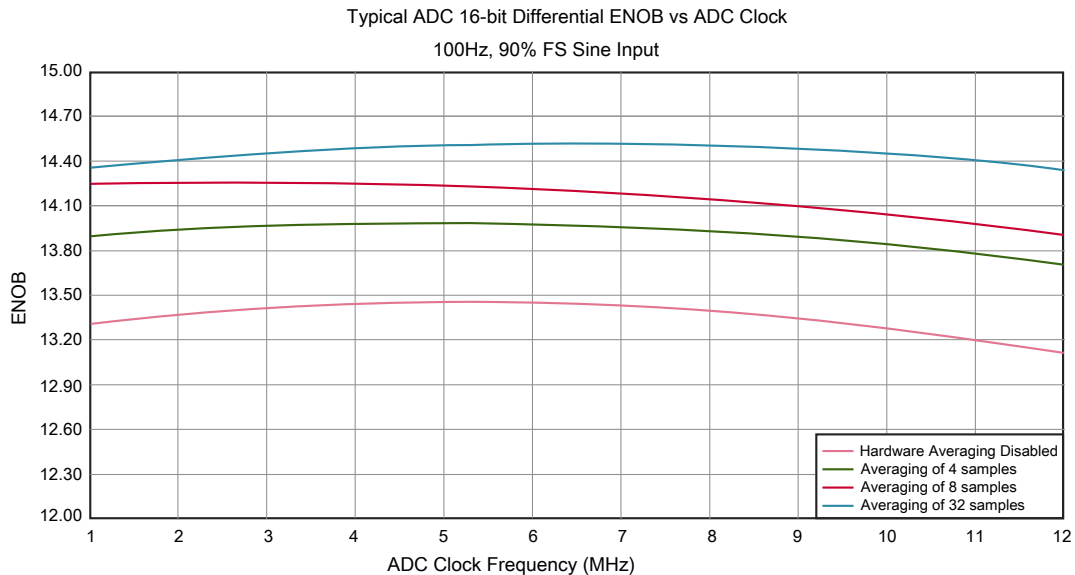
Symbol	Description	Conditions ¹	Min.	Typ. ²	Max.	Unit	Notes
I_{DDA_ADC}	Supply current		0.215	—	1.7	mA	3
f_{ADACK}	ADC asynchronous clock source	• ADLPC = 1, ADHSC = 0	1.2	2.4	3.9	MHz	$t_{ADACK} = 1/f_{ADACK}$
		• ADLPC = 1, ADHSC = 1	2.4	4.0	6.1	MHz	
		• ADLPC = 0, ADHSC = 0	3.0	5.2	7.3	MHz	
		• ADLPC = 0, ADHSC = 1	4.4	6.2	9.5	MHz	
	Sample Time	See Reference Manual chapter for sample times					
TUE	Total unadjusted error	• 12-bit modes • <12-bit modes	— —	± 4 ± 1.4	± 6.8 ± 2.1	LSB ⁴	5
DNL	Differential non-linearity	• 12-bit modes • <12-bit modes	— —	± 0.7 ± 0.2	-1.1 to +1.9 -0.3 to 0.5	LSB ⁴	5
INL	Integral non-linearity	• 12-bit modes • <12-bit modes	— —	± 1.0 ± 0.5	-2.7 to +1.9 -0.7 to +0.5	LSB ⁴	5
E_{FS}	Full-scale error	• 12-bit modes • <12-bit modes	— —	-4 -1.4	-5.4 -1.8	LSB ⁴	$V_{ADIN} = V_{DDA}$ ⁵
E_Q	Quantization error	• 16-bit modes • ≤ 13 -bit modes	— —	-1 to 0 —	— ± 0.5	LSB ⁴	
ENOB	Effective number of bits	16-bit differential mode					6
		• Avg = 32	12.8	14.5	—	bits	
		• Avg = 4	11.9	13.8	—	bits	
		16-bit single-ended mode					
• Avg = 32	12.2	13.9	—	bits			
• Avg = 4	11.4	13.1	—	bits			
SINAD	Signal-to-noise plus distortion	See ENOB	6.02 × ENOB + 1.76			dB	
THD	Total harmonic distortion	16-bit differential mode				dB	7
		• Avg = 32	—	-94	—	dB	
		16-bit single-ended mode					
		• Avg = 32	—	-85	—		
SFDR	Spurious free dynamic range	16-bit differential mode				dB	7
		• Avg = 32	82	95	—	dB	
		16-bit single-ended mode	78	90	—		

Table continues on the next page...

Table 29. 16-bit ADC characteristics ($V_{REFH} = V_{DDA}$, $V_{REFL} = V_{SSA}$) (continued)

Symbol	Description	Conditions ¹	Min.	Typ. ²	Max.	Unit	Notes
		• Avg = 32					
E_{IL}	Input leakage error		$I_{in} \times R_{AS}$			mV	I_{in} = leakage current (refer to the MCU's voltage and current operating ratings)
	Temp sensor slope	Across the full temperature range of the device	1.55	1.62	1.69	mV/°C	8
V_{TEMP25}	Temp sensor voltage	25 °C	706	716	726	mV	8

- All accuracy numbers assume the ADC is calibrated with $V_{REFH} = V_{DDA}$
- Typical values assume $V_{DDA} = 3.0$ V, Temp = 25 °C, $f_{ADCK} = 2.0$ MHz unless otherwise stated. Typical values are for reference only and are not tested in production.
- The ADC supply current depends on the ADC conversion clock speed, conversion rate and ADC_CFG1[ADLPC] (low power). For lowest power operation, ADC_CFG1[ADLPC] must be set, the ADC_CFG2[ADHSC] bit must be clear with 1 MHz ADC conversion clock speed.
- 1 LSB = $(V_{REFH} - V_{REFL})/2^N$
- ADC conversion clock < 16 MHz, Max hardware averaging (AVGE = %1, AVGS = %11)
- Input data is 100 Hz sine wave. ADC conversion clock < 12 MHz.
- Input data is 1 kHz sine wave. ADC conversion clock < 12 MHz.
- ADC conversion clock < 3 MHz

**Figure 20. Typical ENOB vs. ADC_CLK for 16-bit differential mode**

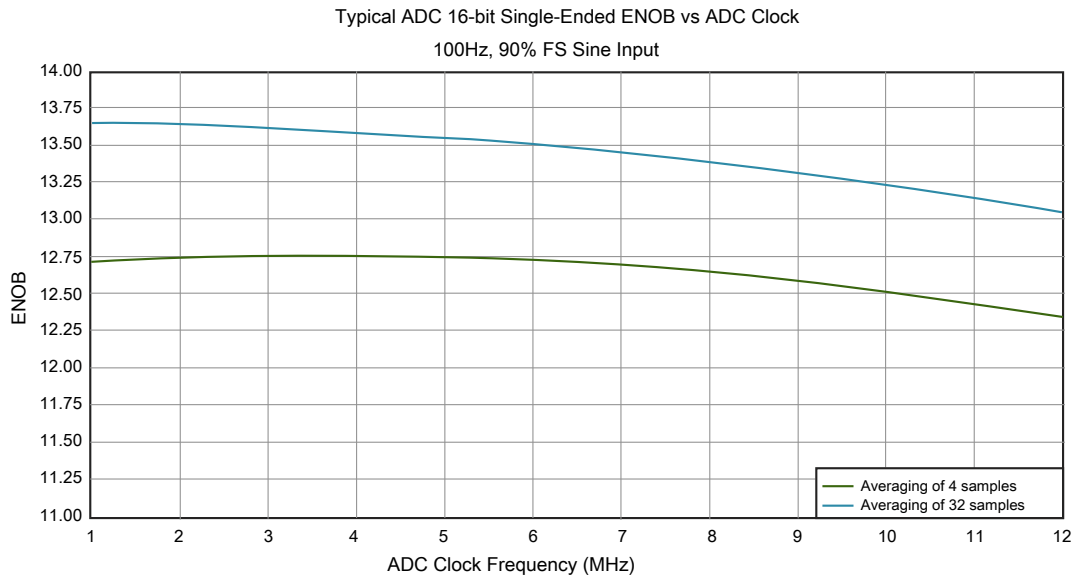


Figure 21. Typical ENOB vs. ADC_CLK for 16-bit single-ended mode

6.6.1.3 16-bit ADC with PGA operating conditions

Table 30. 16-bit ADC with PGA operating conditions

Symbol	Description	Conditions	Min.	Typ. ¹	Max.	Unit	Notes
V _{DDA}	Supply voltage	Absolute	1.71	—	3.6	V	
V _{REFPGA}	PGA ref voltage		VREF_OU T	VREF_OU T	VREF_OU T	V	2, 3
V _{ADIN}	Input voltage		V _{SSA}	—	V _{DDA}	V	
V _{CM}	Input Common Mode range		V _{SSA}	—	V _{DDA}	V	
R _{PGAD}	Differential input impedance	Gain = 1, 2, 4, 8 Gain = 16, 32 Gain = 64	—	128 64 32	—	kΩ	IN+ to IN- ⁴
R _{AS}	Analog source resistance		—	100	—	Ω	5
T _S	ADC sampling time		1.25	—	—	μs	6
C _{rate}	ADC conversion rate	≤ 13 bit modes No ADC hardware averaging Continuous conversions enabled Peripheral clock = 50 MHz	18.484	—	450	Ksps	7
		16 bit modes	37.037	—	250	Ksps	8

Table 30. 16-bit ADC with PGA operating conditions

Symbol	Description	Conditions	Min.	Typ. ¹	Max.	Unit	Notes
		No ADC hardware averaging Continuous conversions enabled Peripheral clock = 50 MHz					

1. Typical values assume $V_{DDA} = 3.0\text{ V}$, $\text{Temp} = 25^\circ\text{C}$, $f_{\text{ADCK}} = 6\text{ MHz}$ unless otherwise stated. Typical values are for reference only and are not tested in production.
2. ADC must be configured to use the internal voltage reference (VREF_OUT)
3. PGA reference is internally connected to the VREF_OUT pin. If the user wishes to drive VREF_OUT with a voltage other than the output of the VREF module, the VREF module must be disabled.
4. For single ended configurations the input impedance of the driven input is $R_{\text{PGAD}}/2$
5. The analog source resistance (R_{AS}), external to MCU, should be kept as minimum as possible. Increased R_{AS} causes drop in PGA gain without affecting other performances. This is not dependent on ADC clock frequency.
6. The minimum sampling time is dependent on input signal frequency and ADC mode of operation. A minimum of $1.25\mu\text{s}$ time should be allowed for $F_{\text{in}}=4\text{ kHz}$ at 16-bit differential mode. Recommended ADC setting is: ADLSMP=1, ADLSTS=2 at 8 MHz ADC clock.
7. ADC clock = 18 MHz, ADLSMP = 1, ADLST = 00, ADHSC = 1
8. ADC clock = 12 MHz, ADLSMP = 1, ADLST = 01, ADHSC = 1

6.6.1.4 16-bit ADC with PGA characteristics

Table 31. 16-bit ADC with PGA characteristics

Symbol	Description	Conditions	Min.	Typ. ¹	Max.	Unit	Notes
$I_{\text{DDA_PGA}}$	Supply current	Low power (ADC_PGA[PGALPb]=0)	—	420	644	μA	2
$I_{\text{DC_PGA}}$	Input DC current		$\frac{2}{R_{\text{PGAD}}} \left(\frac{V_{\text{REFPGA}} \times 0.583 - V_{\text{CM}}}{\text{Gain} + 1} \right)$			A	3
		Gain =1, $V_{\text{REFPGA}}=1.2\text{V}$, $V_{\text{CM}}=0.5\text{V}$	—	1.54	—	μA	
		Gain =64, $V_{\text{REFPGA}}=1.2\text{V}$, $V_{\text{CM}}=0.1\text{V}$	—	0.57	—	μA	
G	Gain ⁴	<ul style="list-style-type: none"> • PGAG=0 • PGAG=1 • PGAG=2 • PGAG=3 • PGAG=4 • PGAG=5 • PGAG=6 	0.95 1.9 3.8 7.6 15.2 30.0 58.8	1 2 4 8 16 31.6 63.3	1.05 2.1 4.2 8.4 16.6 33.2 67.8		$R_{\text{AS}} < 100\Omega$
BW	Input signal bandwidth	• 16-bit modes	—	—	4	kHz	
		• < 16-bit modes	—	—	40	kHz	
PSRR	Power supply rejection ratio	Gain=1	—	-84	—	dB	$V_{\text{DDA}} = 3\text{V}$ $\pm 100\text{mV}$,

Table continues on the next page...

Table 31. 16-bit ADC with PGA characteristics (continued)

Symbol	Description	Conditions	Min.	Typ. ¹	Max.	Unit	Notes
							f_{VDDA} = 50Hz, 60Hz
CMRR	Common mode rejection ratio	<ul style="list-style-type: none"> Gain=1 Gain=64 	—	-84	—	dB	V_{CM} = 500mVpp, f_{VCM} = 50Hz, 100Hz
			—	-85	—	dB	
V_{OFS}	Input offset voltage	<ul style="list-style-type: none"> Chopping disabled (ADC_PGA[PGACHPb] =1) Chopping enabled (ADC_PGA[PGACHPb] =0) 	—	2.4	—	mV	Output offset = $V_{OFS} * (Gain+1)$
			—	0.2	—	mV	
T_{GSW}	Gain switching settling time		—	—	10	μ s	5
dG/dT	Gain drift over full temperature range	<ul style="list-style-type: none"> Gain=1 Gain=64 	—	6	10	ppm/°C	
			—	31	42	ppm/°C	
dG/dV _{DDA}	Gain drift over supply voltage	<ul style="list-style-type: none"> Gain=1 Gain=64 	—	0.07	0.21	%/V	V_{DDA} from 1.71 to 3.6V
			—	0.14	0.31	%/V	
E_{IL}	Input leakage error	All modes	$I_{in} \times R_{AS}$			mV	I_{in} = leakage current (refer to the MCU's voltage and current operating ratings)
$V_{PP,DIFF}$	Maximum differential input signal swing		$\left(\frac{(\min(V_x, V_{DDA} - V_x) - 0.2) \times 4}{Gain} \right)$			V	6
			where $V_x = V_{REFPGA} \times 0.583$				
SNR	Signal-to-noise ratio	<ul style="list-style-type: none"> Gain=1 Gain=64 	80	90	—	dB	16-bit differential mode, Average=32
			52	66	—	dB	
THD	Total harmonic distortion	<ul style="list-style-type: none"> Gain=1 Gain=64 	85	100	—	dB	16-bit differential mode, Average=32, f_{in} =100Hz
			49	95	—	dB	
SFDR	Spurious free dynamic range	<ul style="list-style-type: none"> Gain=1 Gain=64 	85	105	—	dB	16-bit differential mode, Average=32, f_{in} =100Hz
			53	88	—	dB	
ENOB	Effective number of bits	<ul style="list-style-type: none"> Gain=1, Average=4 Gain=1, Average=8 Gain=64, Average=4 Gain=64, Average=8 	11.6	13.4	—	bits	16-bit differential mode, f_{in} =100Hz
			8.0	13.6	—	bits	
			7.2	9.6	—	bits	
			6.3	9.6	—	bits	
			12.8	14.5	—	bits	

Table continues on the next page...

Table 31. 16-bit ADC with PGA characteristics (continued)

Symbol	Description	Conditions	Min.	Typ. ¹	Max.	Unit	Notes
		<ul style="list-style-type: none"> Gain=1, Average=32 Gain=2, Average=32 Gain=4, Average=32 Gain=8, Average=32 Gain=16, Average=32 Gain=32, Average=32 Gain=64, Average=32 	11.0	14.3	—	bits	
			7.9	13.8	—	bits	
			7.3	13.1	—	bits	
			6.8	12.5	—	bits	
			6.8	11.5	—	bits	
			7.5	10.6	—	bits	
SINAD	Signal-to-noise plus distortion ratio	See ENOB	6.02 × ENOB + 1.76			dB	

1. Typical values assume $V_{DDA} = 3.0V$, $Temp = 25^{\circ}C$, $f_{ADCK} = 6MHz$ unless otherwise stated.
2. This current is a PGA module adder, in addition to ADC conversion currents.
3. Between $IN+$ and $IN-$. The PGA draws a DC current from the input terminals. The magnitude of the DC current is a strong function of input common mode voltage (V_{CM}) and the PGA gain.
4. $Gain = 2^{PGAG}$
5. After changing the PGA gain setting, a minimum of 2 ADC+PGA conversions should be ignored.
6. Limit the input signal swing so that the PGA does not saturate during operation. Input signal swing is dependent on the PGA reference voltage and gain setting.

6.6.2 CMP and 6-bit DAC electrical specifications

Table 32. Comparator and 6-bit DAC electrical specifications

Symbol	Description	Min.	Typ.	Max.	Unit
V_{DD}	Supply voltage	1.71	—	3.6	V
I_{DDHS}	Supply current, High-speed mode (EN=1, PMODE=1)	—	—	200	μA
$I_{DDL S}$	Supply current, low-speed mode (EN=1, PMODE=0)	—	—	20	μA
V_{AIN}	Analog input voltage	$V_{SS} - 0.3$	—	V_{DD}	V
V_{AIO}	Analog input offset voltage	—	—	20	mV
V_H	Analog comparator hysteresis ¹ <ul style="list-style-type: none"> CR0[HYSTCTR] = 00 CR0[HYSTCTR] = 01 CR0[HYSTCTR] = 10 CR0[HYSTCTR] = 11 	—	5	—	mV
		—	10	—	mV
		—	20	—	mV
		—	30	—	mV
V_{CMPOH}	Output high	$V_{DD} - 0.5$	—	—	V
V_{CMPOI}	Output low	—	—	0.5	V
t_{DHS}	Propagation delay, high-speed mode (EN=1, PMODE=1)	20	50	200	ns
t_{DLS}	Propagation delay, low-speed mode (EN=1, PMODE=0)	80	250	600	ns
	Analog comparator initialization delay ²	—	—	40	μs
I_{DAC6b}	6-bit DAC current adder (enabled)	—	7	—	μA

Table continues on the next page...

Table 32. Comparator and 6-bit DAC electrical specifications (continued)

Symbol	Description	Min.	Typ.	Max.	Unit
INL	6-bit DAC integral non-linearity	-0.5	—	0.5	LSB ³
DNL	6-bit DAC differential non-linearity	-0.3	—	0.3	LSB

1. Typical hysteresis is measured with input voltage range limited to 0.6 to $V_{DD}-0.6$ V.
2. Comparator initialization delay is defined as the time between software writes to change control inputs (Writes to CMP_DACCR[DACEN], CMP_DACCR[VRSEL], CMP_DACCR[VOSEL], CMP_MUXCR[PSEL], and CMP_MUXCR[MSEL]) and the comparator output settling to a stable level.
3. $1 \text{ LSB} = V_{\text{reference}}/64$

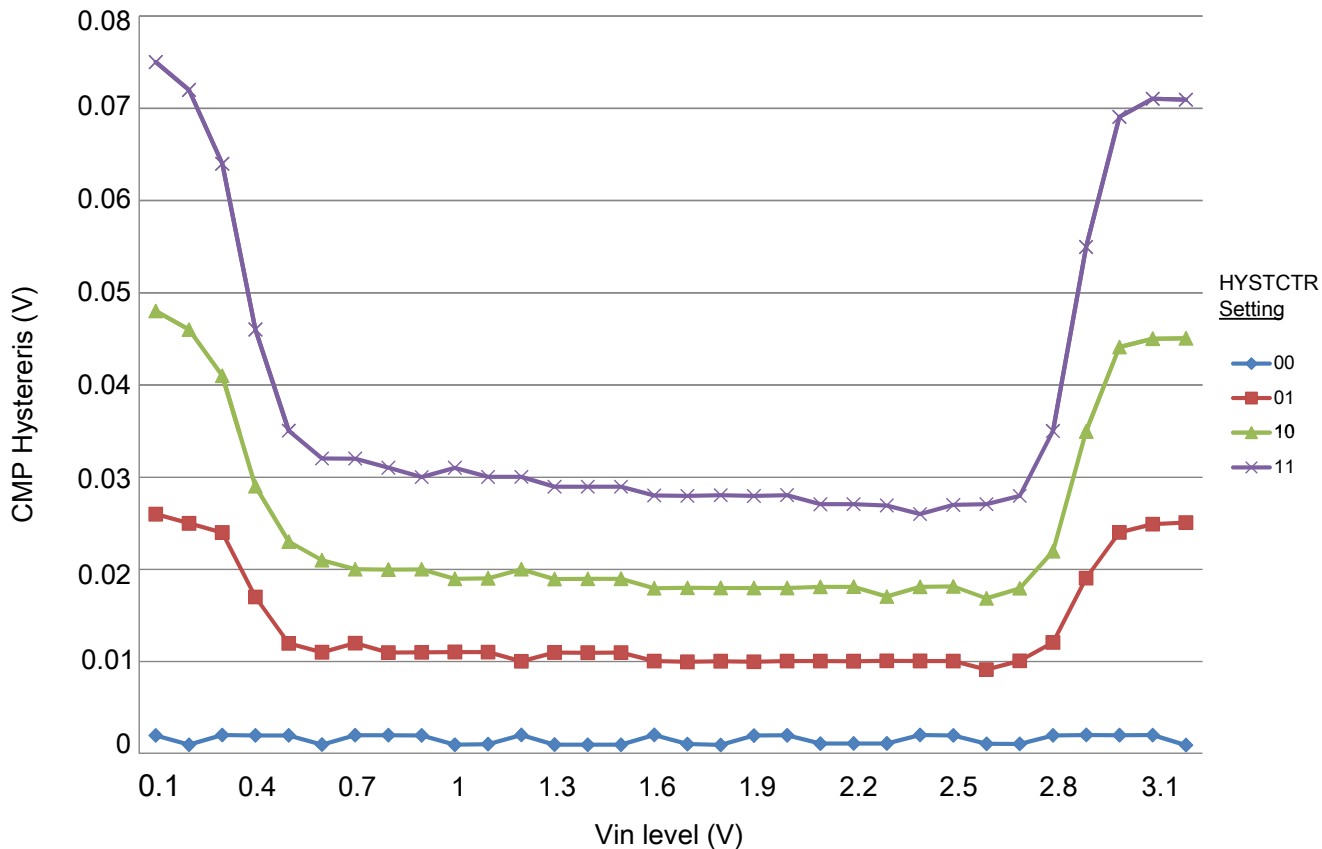


Figure 22. Typical hysteresis vs. Vin level (VDD = 3.3 V, PMODE = 0)

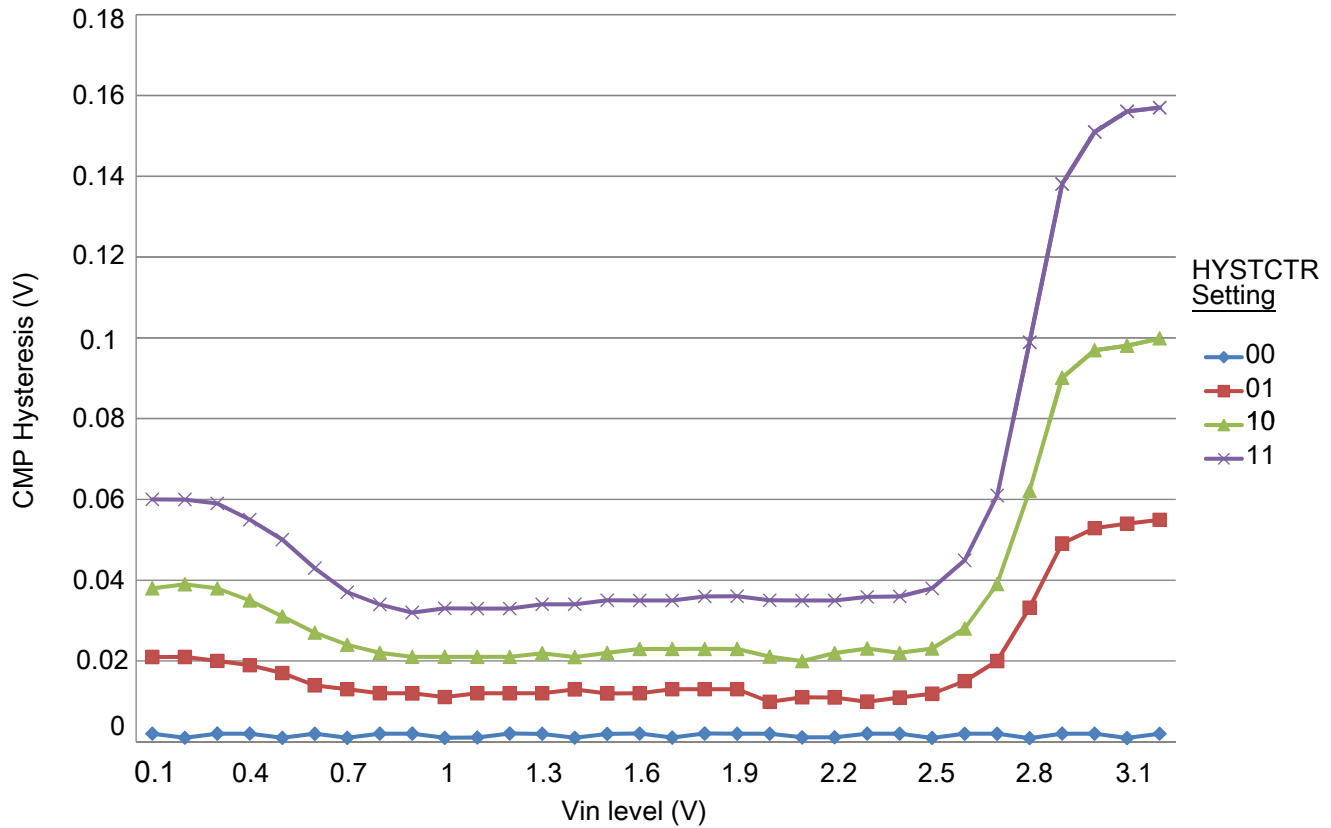


Figure 23. Typical hysteresis vs. Vin level (VDD = 3.3 V, PMODE = 1)

6.6.3 12-bit DAC electrical characteristics

6.6.3.1 12-bit DAC operating requirements

Table 33. 12-bit DAC operating requirements

Symbol	Description	Min.	Max.	Unit	Notes
V_{DDA}	Supply voltage	1.71	3.6	V	
V_{DACR}	Reference voltage	1.13	3.6	V	1
C_L	Output load capacitance	—	100	pF	2
I_L	Output load current	—	1	mA	

1. The DAC reference can be selected to be V_{DDA} or V_{REF_OUT} .
2. A small load capacitance (47 pF) can improve the bandwidth performance of the DAC.

6.6.3.2 12-bit DAC operating behaviors

Table 34. 12-bit DAC operating behaviors

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
$I_{DDA_DACL_P}$	Supply current — low-power mode	—	—	150	μA	
$I_{DDA_DACH_P}$	Supply current — high-speed mode	—	—	700	μA	
t_{DACL_P}	Full-scale settling time (0x080 to 0xF7F) — low-power mode	—	100	200	μs	1
t_{DACH_P}	Full-scale settling time (0x080 to 0xF7F) — high-power mode	—	15	30	μs	1
t_{CCDACL_P}	Code-to-code settling time (0xBF8 to 0xC08) — low-power mode and high-speed mode	—	0.7	1	μs	1
$V_{dacoutl}$	DAC output voltage range low — high-speed mode, no load, DAC set to 0x000	—	—	100	mV	
$V_{dacouth}$	DAC output voltage range high — high-speed mode, no load, DAC set to 0xFFF	$V_{DACR} - 100$	—	V_{DACR}	mV	
INL	Integral non-linearity error — high speed mode	—	—	± 8	LSB	2
DNL	Differential non-linearity error — $V_{DACR} > 2\text{ V}$	—	—	± 1	LSB	3
DNL	Differential non-linearity error — $V_{DACR} = V_{REF_OUT}$	—	—	± 1	LSB	4
V_{OFFSET}	Offset error	—	± 0.4	± 0.8	%FSR	5
E_G	Gain error	—	± 0.1	± 0.6	%FSR	5
PSRR	Power supply rejection ratio, $V_{DDA} \geq 2.4\text{ V}$	60	—	90	dB	
T_{CO}	Temperature coefficient offset voltage	—	3.7	—	$\mu\text{V}/\text{C}$	6
T_{GE}	Temperature coefficient gain error	—	0.000421	—	%FSR/C	
R_{op}	Output resistance (load = 3 k Ω)	—	—	250	Ω	
SR	Slew rate -80h → F7Fh → 80h <ul style="list-style-type: none"> High power (SP_{HP}) Low power (SP_{LP}) 	1.2 0.05	1.7 0.12	— —	V/ μs	
CT	Channel to channel cross talk	—	—	-80	dB	
BW	3dB bandwidth <ul style="list-style-type: none"> High power (SP_{HP}) Low power (SP_{LP}) 	550 40	— —	— —	kHz	

- Settling within ± 1 LSB
- The INL is measured for 0 + 100 mV to $V_{DACR} - 100$ mV
- The DNL is measured for 0 + 100 mV to $V_{DACR} - 100$ mV
- The DNL is measured for 0 + 100 mV to $V_{DACR} - 100$ mV with $V_{DDA} > 2.4\text{ V}$
- Calculated by a best fit curve from $V_{SS} + 100$ mV to $V_{DACR} - 100$ mV
- $V_{DDA} = 3.0\text{ V}$, reference select set for V_{DDA} ($DACx_CO:DACRFS = 1$), high power mode ($DACx_CO:LPEN = 0$), DAC set to 0x800, temperature range is across the full range of the device

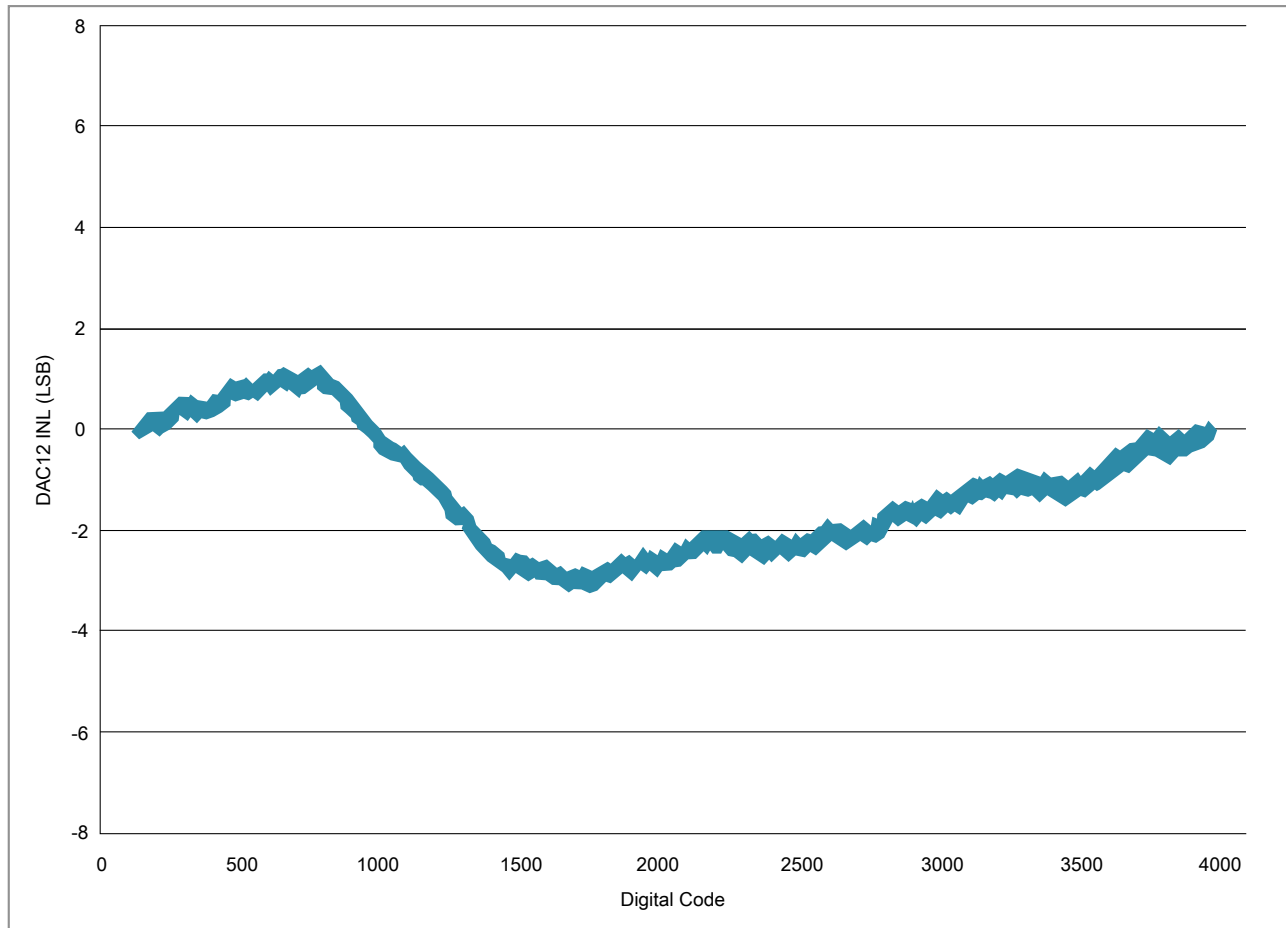


Figure 24. Typical INL error vs. digital code

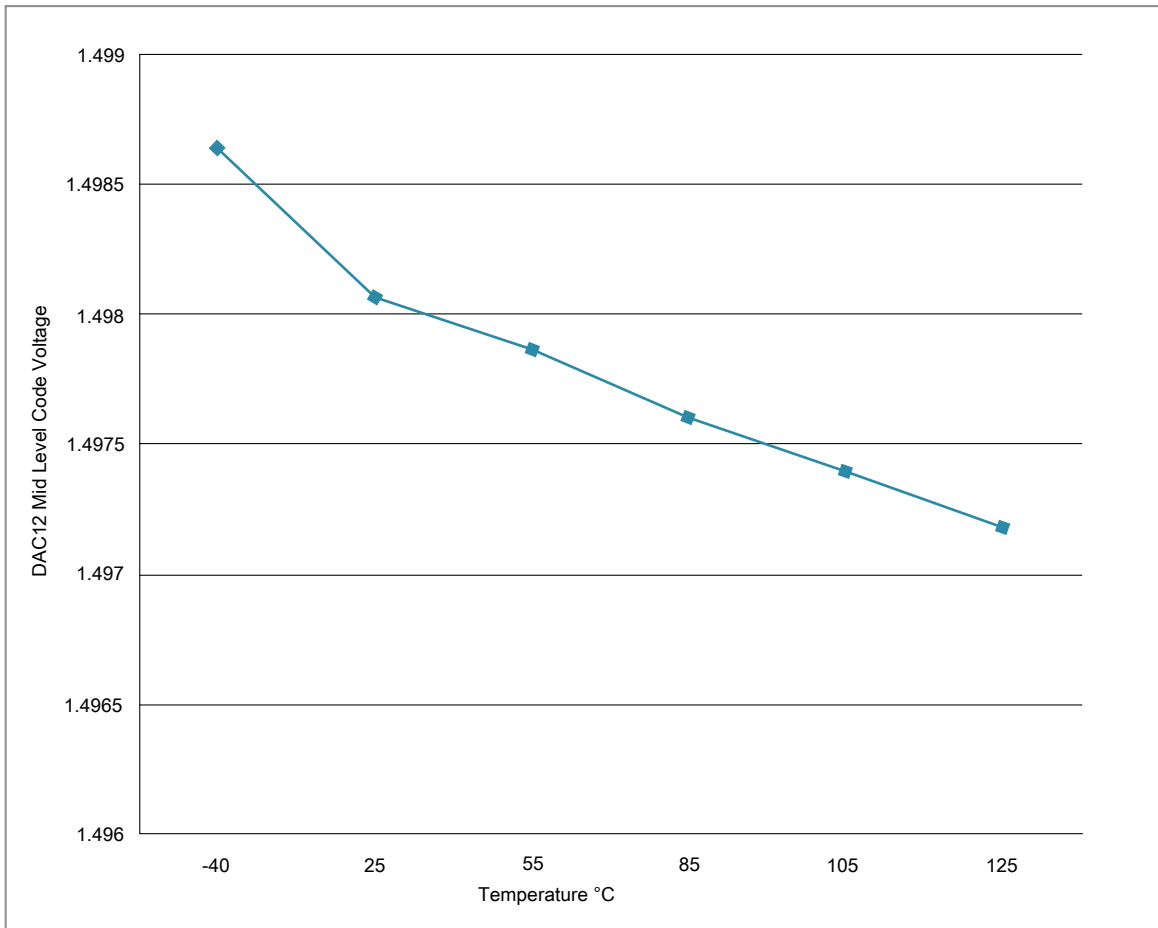


Figure 25. Offset at half scale vs. temperature

6.6.4 Voltage reference electrical specifications

Table 35. VREF full-range operating requirements

Symbol	Description	Min.	Max.	Unit	Notes
V_{DDA}	Supply voltage	1.71	3.6	V	
T_A	Temperature	Operating temperature range of the device		°C	
C_L	Output load capacitance	100		nF	1, 2

1. C_L must be connected to VREF_OUT if the VREF_OUT functionality is being used for either an internal or external reference.
2. The load capacitance should not exceed +/-25% of the nominal specified C_L value over the operating temperature range of the device.

Table 36. VREF full-range operating behaviors

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
V_{out}	Voltage reference output with factory trim at nominal V_{DDA} and temperature=25C	1.1915	1.195	1.1977	V	1
V_{out}	Voltage reference output — factory trim	1.1584	—	1.2376	V	1
V_{out}	Voltage reference output — user trim	1.193	—	1.197	V	1
V_{step}	Voltage reference trim step	—	0.5	—	mV	1
V_{tdrift}	Temperature drift ($V_{max} - V_{min}$ across the full temperature range: -40 to 85°C)	—	—	70	mV	1
I_{bg}	Bandgap only current	—	—	80	μ A	1
I_{hp}	High-power buffer current	—	—	1	mA	1
ΔV_{LOAD}	Load regulation <ul style="list-style-type: none"> • current = + 1.0 mA • current = - 1.0 mA 	—	2	—	mV	1, 2
T_{stup}	Buffer startup time	—	—	100	μ s	
V_{vdrift}	Voltage drift ($V_{max} - V_{min}$ across the full voltage range)	—	2	—	mV	1

1. See the chip's Reference Manual for the appropriate settings of the VREF Status and Control register.
2. Load regulation voltage is the difference between the VREF_OUT voltage with no load vs. voltage with defined load

Table 37. VREF limited-range operating requirements

Symbol	Description	Min.	Max.	Unit	Notes
T_A	Temperature	0	50	°C	

Table 38. VREF limited-range operating behaviors

Symbol	Description	Min.	Max.	Unit	Notes
V_{out}	Voltage reference output with factory trim	1.173	1.225	V	

6.7 Timers

See [General switching specifications](#).

6.8 Communication interfaces

6.8.1 Ethernet switching specifications

The following timing specs are defined at the chip I/O pin and must be translated appropriately to arrive at timing specs/constraints for the physical interface.

6.8.1.1 MII signal switching specifications

The following timing specs meet the requirements for MII style interfaces for a range of transceiver devices.

Table 39. MII signal switching specifications

Symbol	Description	Min.	Max.	Unit
—	RXCLK frequency	—	25	MHz
MII1	RXCLK pulse width high	35%	65%	RXCLK period
MII2	RXCLK pulse width low	35%	65%	RXCLK period
MII3	RXD[3:0], RXDV, RXER to RXCLK setup	5	—	ns
MII4	RXCLK to RXD[3:0], RXDV, RXER hold	5	—	ns
—	TXCLK frequency	—	25	MHz
MII5	TXCLK pulse width high	35%	65%	TXCLK period
MII6	TXCLK pulse width low	35%	65%	TXCLK period
MII7	TXCLK to TXD[3:0], TXEN, TXER invalid	2	—	ns
MII8	TXCLK to TXD[3:0], TXEN, TXER valid	—	25	ns

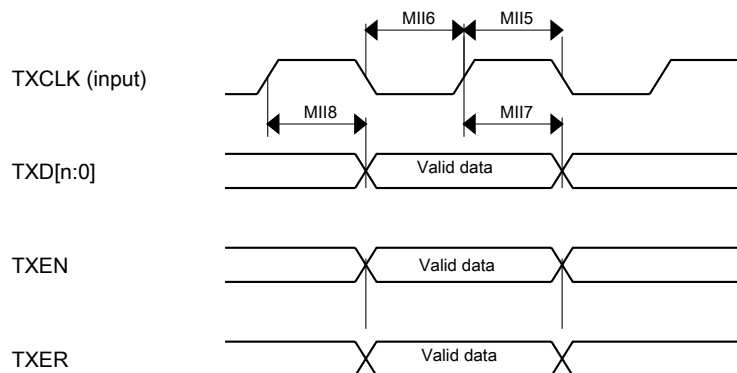


Figure 26. RMI/MII transmit signal timing diagram



Figure 27. RMII/MII receive signal timing diagram

6.8.1.2 RMII signal switching specifications

The following timing specs meet the requirements for RMII style interfaces for a range of transceiver devices.

Table 40. RMII signal switching specifications

Num	Description	Min.	Max.	Unit
—	EXTAL frequency (RMII input clock RMII_CLK)	—	50	MHz
RMII1	RMII_CLK pulse width high	35%	65%	RMII_CLK period
RMII2	RMII_CLK pulse width low	35%	65%	RMII_CLK period
RMII3	RXD[1:0], CRS_DV, RXER to RMII_CLK setup	4	—	ns
RMII4	RMII_CLK to RXD[1:0], CRS_DV, RXER hold	2	—	ns
RMII7	RMII_CLK to TXD[1:0], TXEN invalid	4	—	ns
RMII8	RMII_CLK to TXD[1:0], TXEN valid	—	15	ns

6.8.1.3 MDIO serial management timing specifications

Table 41. MDIO serial management channel signal timing

Num	Characteristic	Min	Max	Unit
E10	MDC cycle time	400	—	ns
E11	MDC pulse width	40	60	% t_{MDC}
E12	MDC to MDIO output valid	F_{sys} period ₁	—	ns
E13	MDC to MDIO output invalid	F_{sys} period ¹	—	ns
E14	MDIO input to MDC setup	10	—	ns
E15	MDIO input to MDC hold	0	—	ns

Peripheral operating requirements and behaviors

- MDIO output valid and hold time can be adjusted using the ENET_MSCR[HOLDTIME] field. The minimum specification shown here is for the default ENET_MSCR value, where HOLDTIME = 0. The minimum output valid and output hold times can be increased by changing the HOLDTIME register field

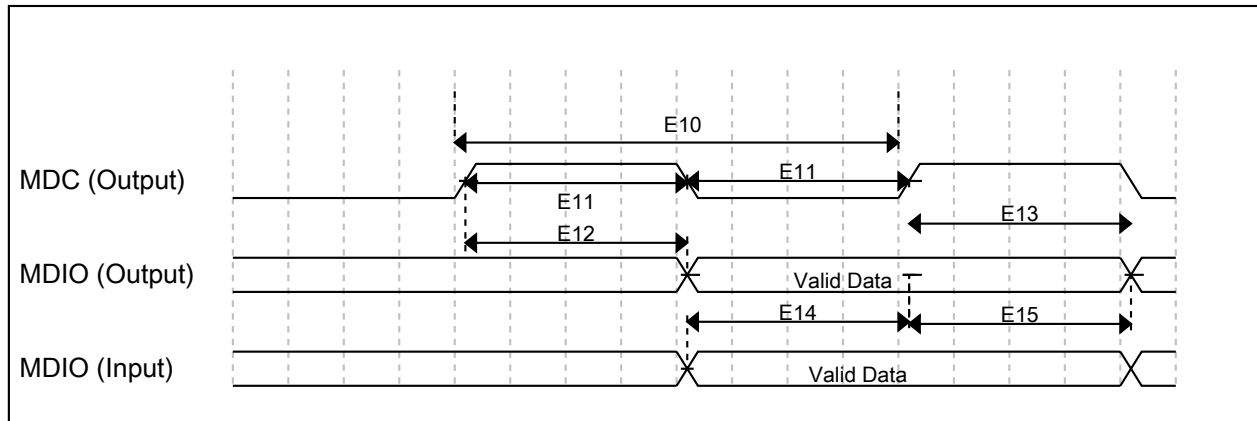


Figure 28. MDIO serial management channel timing diagram

6.8.2 USB electrical specifications

The USB electricals for the USB On-the-Go module conform to the standards documented by the Universal Serial Bus Implementers Forum. For the most up-to-date standards, visit usb.org.

NOTE

The MCGPLLCLK meets the USB jitter and signaling rate specifications for certification with the use of an external clock/crystal for both Device and Host modes.

The MCGFLLCLK does not meet the USB jitter or signaling rate specifications for certification.

6.8.3 USB DCD electrical specifications

Table 42. USB0 DCD electrical specifications

Symbol	Description	Min.	Typ.	Max.	Unit
V _{DP_SRC}	USB_DP source voltage (up to 250 μ A)	0.5	—	0.7	V
V _{LGC}	Threshold voltage for logic high	0.8	—	2.0	V
I _{DP_SRC}	USB_DP source current	7	10	13	μ A
I _{DM_SINK}	USB_DM sink current	50	100	150	μ A
R _{DM_DWN}	D- pulldown resistance for data pin contact detect	14.25	—	24.8	k Ω
V _{DAT_REF}	Data detect voltage	0.25	0.325	0.4	V

6.8.4 USB VREG electrical specifications

Table 43. USB VREG electrical specifications

Symbol	Description	Min.	Typ. ¹	Max.	Unit	Notes
VREGIN	Input supply voltage	2.7	—	5.5	V	
I _{DDon}	Quiescent current — Run mode, load current equal zero, input supply (VREGIN) > 3.6 V	—	125	186	μA	
I _{DDstby}	Quiescent current — Standby mode, load current equal zero	—	1.1	10	μA	
I _{DDoff}	Quiescent current — Shutdown mode <ul style="list-style-type: none"> • VREGIN = 5.0 V and temperature=25 °C • Across operating voltage and temperature 	—	650	—	nA	
		—	—	4	μA	
I _{LOADrun}	Maximum load current — Run mode	—	—	120	mA	
I _{LOADstby}	Maximum load current — Standby mode	—	—	1	mA	
V _{Reg33out}	Regulator output voltage — Input supply (VREGIN) > 3.6 V <ul style="list-style-type: none"> • Run mode • Standby mode 	3	3.3	3.6	V	
		2.1	2.8	3.6	V	
V _{Reg33out}	Regulator output voltage — Input supply (VREGIN) < 3.6 V, pass-through mode	2.1	—	3.6	V	2
C _{OUT}	External output capacitor	1.76	2.2	8.16	μF	
ESR	External output capacitor equivalent series resistance	1	—	100	mΩ	
I _{LIM}	Short circuit current	—	290	—	mA	

1. Typical values assume VREGIN = 5.0 V, Temp = 25 °C unless otherwise stated.
2. Operating in pass-through mode: regulator output voltage equal to the input voltage minus a drop proportional to I_{Load}.

6.8.5 CAN switching specifications

See [General switching specifications](#).

6.8.6 DSPI switching specifications (limited voltage range)

The DMA Serial Peripheral Interface DSPI provides a synchronous serial bus with master and slave operations. Many of the transfer attributes are programmable. The tables below provide DSPI timing characteristics for classic DSPI timing modes. Refer to the DSPI chapter of the Reference Manual for information on the modified transfer formats used for communicating with slower peripheral devices.

Table 44. Master mode DSPI timing (limited voltage range)

Num	Description	Min.	Max.	Unit	Notes
	Operating voltage	2.7	3.6	V	
	Frequency of operation	—	30	MHz	
DS1	DSPI_SCK output cycle time	$2 \times t_{BUS}$	—	ns	
DS2	DSPI_SCK output high/low time	$(t_{SCK}/2) - 2$	$(t_{SCK}/2) + 2$	ns	
DS3	DSPI_PCSn valid to DSPI_SCK delay	$(t_{BUS} \times 2) - 2$	—	ns	1
DS4	DSPI_SCK to DSPI_PCSn invalid delay	$(t_{BUS} \times 2) - 2$	—	ns	2
DS5	DSPI_SCK to DSPI_SOUT valid	—	8.5	ns	
DS6	DSPI_SCK to DSPI_SOUT invalid	-2	—	ns	
DS7	DSPI_SIN to DSPI_SCK input setup	15	—	ns	
DS8	DSPI_SCK to DSPI_SIN input hold	0	—	ns	

1. The delay is programmable in DSPIx_CTARn[PSSCK] and DSPIx_CTARn[CSSCK].
2. The delay is programmable in DSPIx_CTARn[PASC] and DSPIx_CTARn[ASC].

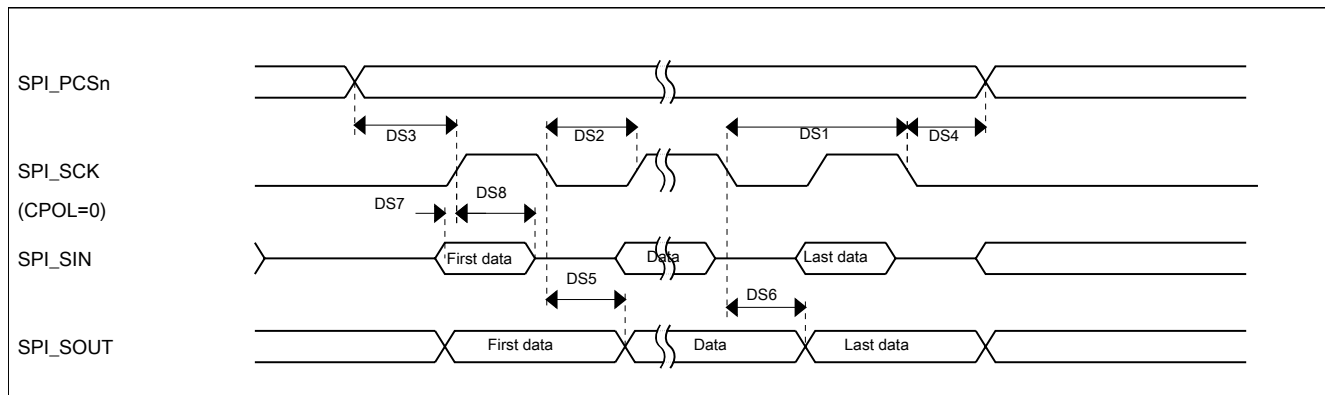


Figure 29. DSPI classic DSPI timing — master mode

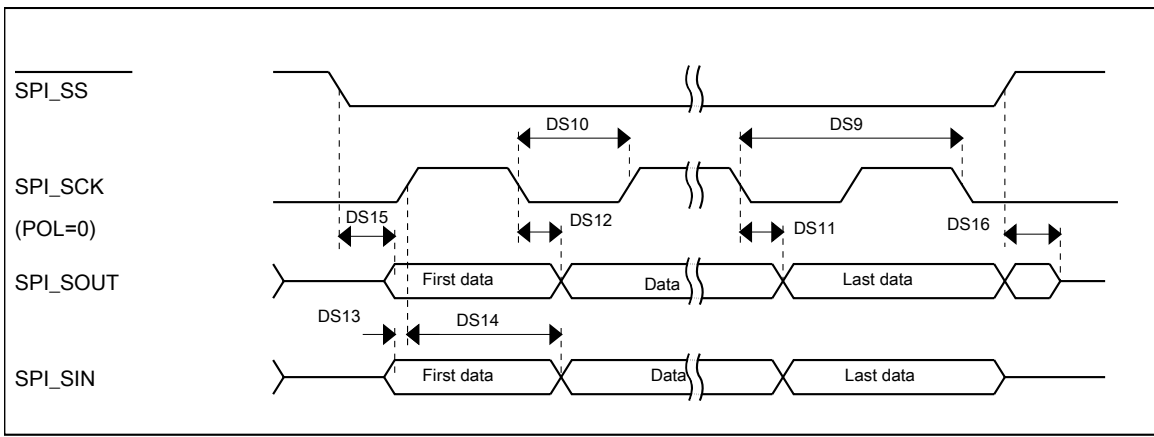
Table 45. Slave mode DSPI timing (limited voltage range)

Num	Description	Min.	Max.	Unit
	Operating voltage	2.7	3.6	V
	Frequency of operation		15	MHz
DS9	DSPI_SCK input cycle time	$4 \times t_{BUS}$	—	ns

Table continues on the next page...

Table 45. Slave mode DSPI timing (limited voltage range) (continued)

Num	Description	Min.	Max.	Unit
DS10	DSPI_SCK input high/low time	$(t_{SCK/2}) - 2$	$(t_{SCK/2}) + 2$	ns
DS11	DSPI_SCK to DSPI_SOUT valid	—	10	ns
DS12	DSPI_SCK to DSPI_SOUT invalid	0	—	ns
DS13	DSPI_SIN to DSPI_SCK input setup	2	—	ns
DS14	DSPI_SCK to DSPI_SIN input hold	7	—	ns
DS15	DSPI_SS active to DSPI_SOUT driven	—	14	ns
DS16	DSPI_SS inactive to DSPI_SOUT not driven	—	14	ns

**Figure 30. DSPI classic DSPI timing — slave mode**

6.8.7 DSPI switching specifications (full voltage range)

The DMA Serial Peripheral Interface DSPI provides a synchronous serial bus with master and slave operations. Many of the transfer attributes are programmable. The tables below provides DSPI timing characteristics for classic SPI timing modes. Refer to the DSPI chapter of the Reference Manual for information on the modified transfer formats used for communicating with slower peripheral devices.

Table 46. Master mode DSPI timing (full voltage range)

Num	Description	Min.	Max.	Unit	Notes
	Operating voltage	1.71	3.6	V	1
	Frequency of operation	—	15	MHz	
DS1	DSPI_SCK output cycle time	$4 \times t_{BUS}$	—	ns	
DS2	DSPI_SCK output high/low time	$(t_{SCK/2}) - 4$	$(t_{SCK/2}) + 4$	ns	
DS3	DSPI_PCS _n valid to DSPI_SCK delay	$(t_{BUS} \times 2) - 4$	—	ns	2

Table continues on the next page...

Table 46. Master mode DSPI timing (full voltage range) (continued)

Num	Description	Min.	Max.	Unit	Notes
DS4	DSPI_SCK to DSPI_PCSn invalid delay	$(t_{BUS} \times 2) - 4$	—	ns	3
DS5	DSPI_SCK to DSPI_SOUT valid	—	10	ns	
DS6	DSPI_SCK to DSPI_SOUT invalid	-4.5	—	ns	
DS7	DSPI_SIN to DSPI_SCK input setup	20.5	—	ns	
DS8	DSPI_SCK to DSPI_SIN input hold	0	—	ns	

1. The DSPI module can operate across the entire operating voltage for the processor, but to run across the full voltage range the maximum frequency of operation is reduced.
2. The delay is programmable in SPIx_CTARn[PSSCK] and SPIx_CTARn[CSSCK].
3. The delay is programmable in SPIx_CTARn[PASC] and SPIx_CTARn[ASC].

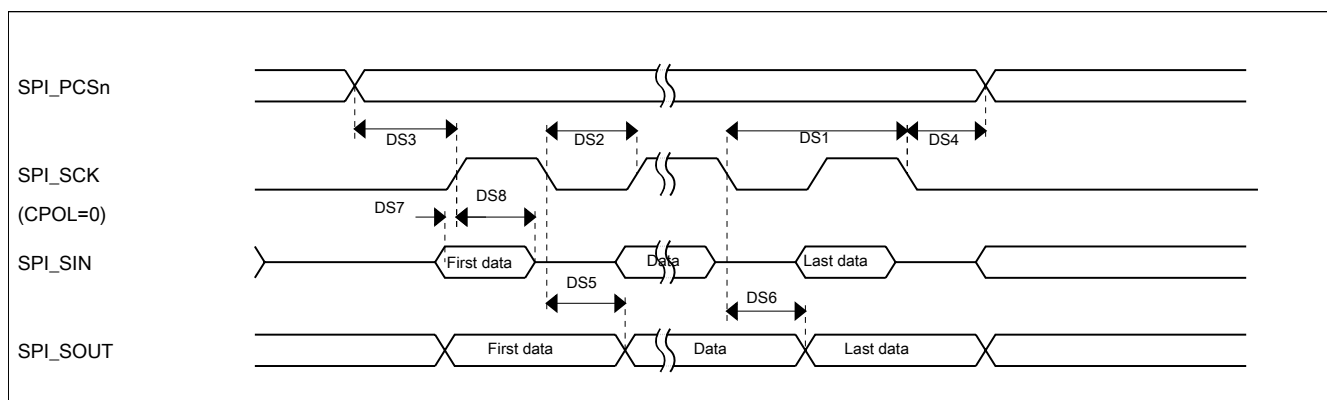


Figure 31. DSPI classic SPI timing — master mode

Table 47. Slave mode DSPI timing (full voltage range)

Num	Description	Min.	Max.	Unit
	Operating voltage	1.71	3.6	V
	Frequency of operation	—	7.5	MHz
DS9	DSPI_SCK input cycle time	$8 \times t_{BUS}$	—	ns
DS10	DSPI_SCK input high/low time	$(t_{SCK}/2) - 4$	$(t_{SCK}/2) + 4$	ns
DS11	DSPI_SCK to DSPI_SOUT valid	—	20	ns
DS12	DSPI_SCK to DSPI_SOUT invalid	0	—	ns
DS13	DSPI_SIN to DSPI_SCK input setup	2	—	ns
DS14	DSPI_SCK to DSPI_SIN input hold	7	—	ns
DS15	DSPI_SS active to DSPI_SOUT driven	—	19	ns
DS16	DSPI_SS inactive to DSPI_SOUT not driven	—	19	ns

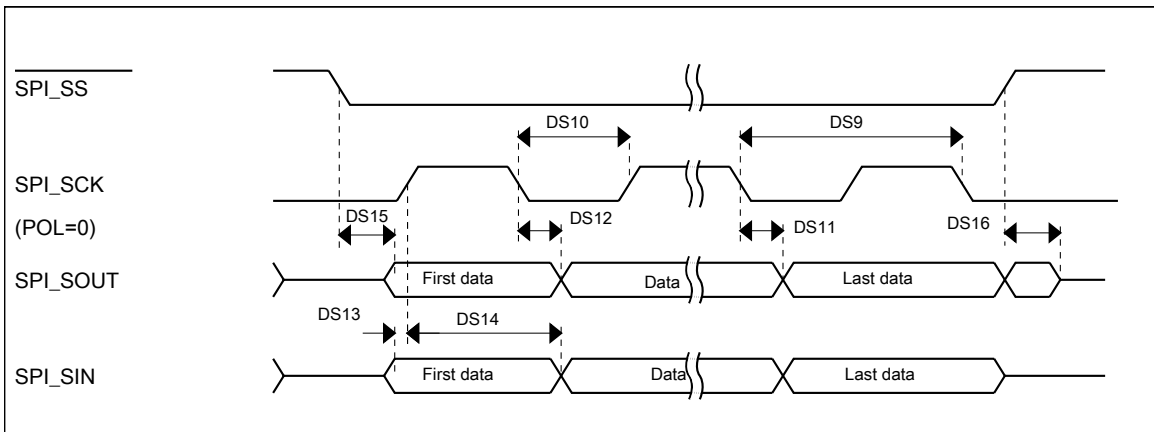


Figure 32. DSPI classic SPI timing — slave mode

6.8.8 Inter-Integrated Circuit Interface (I²C) timing

Table 48. I²C timing

Characteristic	Symbol	Standard Mode		Fast Mode		Unit
		Minimum	Maximum	Minimum	Maximum	
SCL Clock Frequency	f_{SCL}	0	100	0	400 ¹	kHz
Hold time (repeated) START condition. After this period, the first clock pulse is generated.	$t_{HD}; STA$	4	—	0.6	—	μs
LOW period of the SCL clock	t_{LOW}	4.7	—	1.25	—	μs
HIGH period of the SCL clock	t_{HIGH}	4	—	0.6	—	μs
Set-up time for a repeated START condition	$t_{SU}; STA$	4.7	—	0.6	—	μs
Data hold time for I ² C bus devices	$t_{HD}; DAT$	0 ²	3.45 ³	0 ⁴	0.9 ²	μs
Data set-up time	$t_{SU}; DAT$	250 ⁵	—	100 ^{3,6}	—	ns
Rise time of SDA and SCL signals	t_r	—	1000	$20 + 0.1C_b$ ⁷	300	ns
Fall time of SDA and SCL signals	t_f	—	300	$20 + 0.1C_b$ ⁶	300	ns
Set-up time for STOP condition	$t_{SU}; STO$	4	—	0.6	—	μs
Bus free time between STOP and START condition	t_{BUF}	4.7	—	1.3	—	μs
Pulse width of spikes that must be suppressed by the input filter	t_{SP}	N/A	N/A	0	50	ns

1. The maximum SCL Clock Frequency in Fast mode with maximum bus loading can only be achieved when using a pin configured for high drive across the full voltage range and when using the a pin configured for low drive with $V_{DD} \geq 2.7 V$.
2. The master mode I²C deasserts ACK of an address byte simultaneously with the falling edge of SCL. If no slaves acknowledge this address byte, then a negative hold time can result, depending on the edge rates of the SDA and SCL lines.
3. The maximum $t_{HD}; DAT$ must be met only if the device does not stretch the LOW period (t_{LOW}) of the SCL signal.
4. Input signal Slew = 10 ns and Output Load = 50 pF
5. Set-up time in slave-transmitter mode is 1 IPBus clock period, if the TX FIFO is empty.
6. A Fast mode I²C bus device can be used in a Standard mode I²C bus system, but the requirement $t_{SU}; DAT \geq 250 ns$ must then be met. This is automatically the case if the device does not stretch the LOW period of the SCL signal. If such a

Peripheral operating requirements and behaviors

device does stretch the LOW period of the SCL signal, then it must output the next data bit to the SDA line $t_{rmax} + t_{SU; DAT} = 1000 + 250 = 1250$ ns (according to the Standard mode I²C bus specification) before the SCL line is released.

7. C_b = total capacitance of the one bus line in pF.

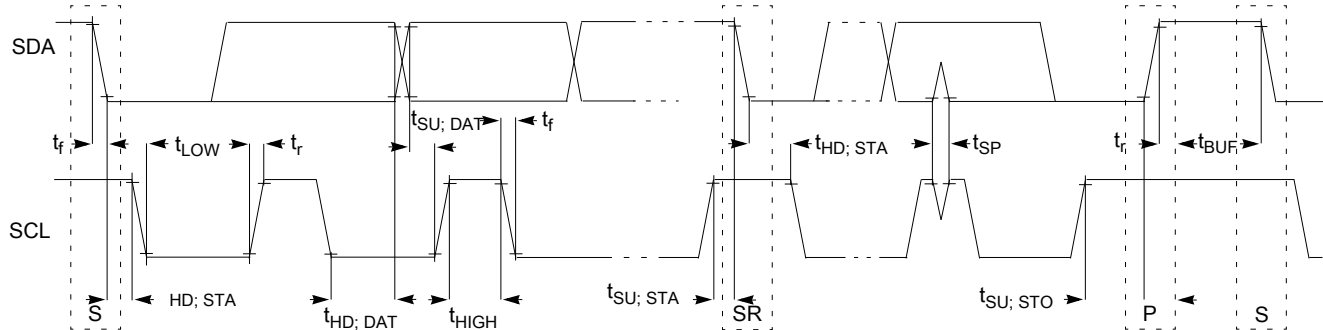


Figure 33. Timing definition for fast and standard mode devices on the I²C bus

6.8.9 UART switching specifications

See [General switching specifications](#).

6.8.10 SDHC specifications

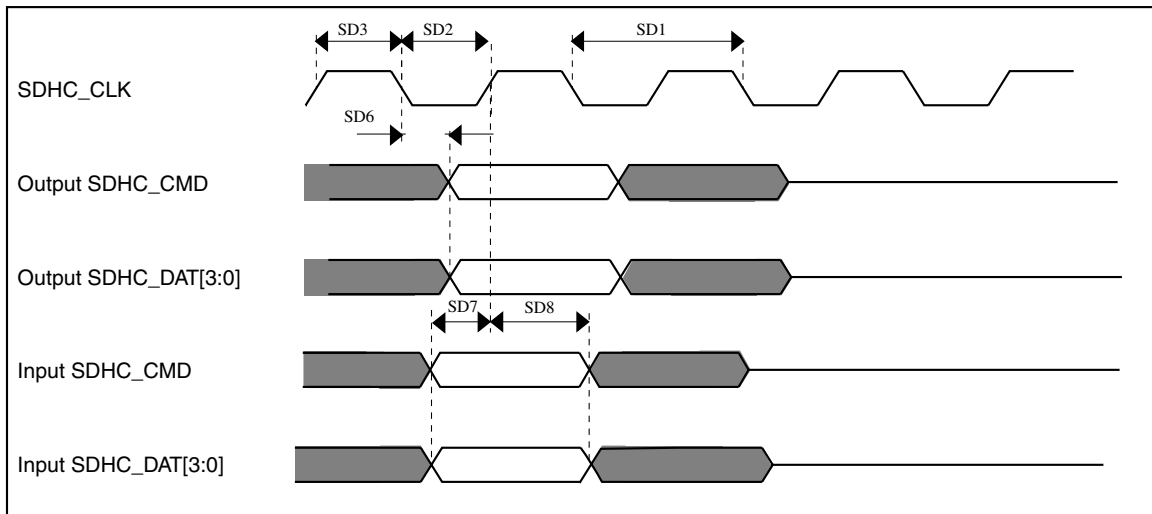
The following timing specs are defined at the chip I/O pin and must be translated appropriately to arrive at timing specs/constraints for the physical interface.

Table 49. SDHC switching specifications over a limited operating voltage range

Num	Symbol	Description	Min.	Max.	Unit
		Operating voltage	2.7	3.6	V
Card input clock					
SD1	f _{pp}	Clock frequency (low speed)	0	400	kHz
	f _{pp}	Clock frequency (SD\SDIO full speed\high speed)	0	25\40	MHz
	f _{pp}	Clock frequency (MMC full speed\high speed)	0	25\50	MHz
	f _{OD}	Clock frequency (identification mode)	0	400	kHz
SD2	t _{WL}	Clock low time	7	—	ns
SD3	t _{WH}	Clock high time	7	—	ns
SD4	t _{TLH}	Clock rise time	—	3	ns
SD5	t _{THL}	Clock fall time	—	3	ns
SDHC output / card inputs SDHC_CMD, SDHC_DAT (reference to SDHC_CLK)					
SD6	t _{OD}	SDHC output delay (output valid)	-5	6.5	ns
SDHC input / card inputs SDHC_CMD, SDHC_DAT (reference to SDHC_CLK)					
SD7	t _{ISU}	SDHC input setup time	5	—	ns
SD8	t _{IH}	SDHC input hold time	0	—	ns

Table 50. SDHC switching specifications over the full operating voltage range

Num	Symbol	Description	Min.	Max.	Unit
		Operating voltage	1.71	3.6	V
Card input clock					
SD1	f _{pp}	Clock frequency (low speed)	0	400	kHz
	f _{pp}	Clock frequency (SD\SDIO full speed\high speed)	0	25\40	MHz
	f _{pp}	Clock frequency (MMC full speed\high speed)	0	25\50	MHz
	f _{OD}	Clock frequency (identification mode)	0	400	kHz
SD2	t _{WL}	Clock low time	7	—	ns
SD3	t _{WH}	Clock high time	7	—	ns
SD4	t _{TLH}	Clock rise time	—	3	ns
SD5	t _{THL}	Clock fall time	—	3	ns
SDHC output / card inputs SDHC_CMD, SDHC_DAT (reference to SDHC_CLK)					
SD6	t _{OD}	SDHC output delay (output valid)	-5	6.5	ns
SDHC input / card inputs SDHC_CMD, SDHC_DAT (reference to SDHC_CLK)					
SD7	t _{ISU}	SDHC input setup time	5	—	ns
SD8	t _{IH}	SDHC input hold time	1.3	—	ns

**Figure 34. SDHC timing**

6.8.11 I2S/SAI switching specifications

This section provides the AC timing for the I2S/SAI module in master mode (clocks are driven) and slave mode (clocks are input). All timing is given for noninverted serial clock polarity (TCR2[BCP] is 0, RCR2[BCP] is 0) and a noninverted frame sync (TCR4[FSP]

is 0, RCR4[FSP] is 0). If the polarity of the clock and/or the frame sync have been inverted, all the timing remains valid by inverting the bit clock signal (BCLK) and/or the frame sync (FS) signal shown in the following figures.

6.8.11.1 Normal Run, Wait and Stop mode performance over a limited operating voltage range

This section provides the operating performance over a limited operating voltage for the device in Normal Run, Wait and Stop modes.

Table 51. I2S/SAI master mode timing in Normal Run, Wait and Stop modes (limited voltage range)

Num.	Characteristic	Min.	Max.	Unit
	Operating voltage	2.7	3.6	V
S1	I2S_MCLK cycle time	40	—	ns
S2	I2S_MCLK pulse width high/low	45%	55%	MCLK period
S3	I2S_TX_BCLK/I2S_RX_BCLK cycle time (output)	80	—	ns
S4	I2S_TX_BCLK/I2S_RX_BCLK pulse width high/low	45%	55%	BCLK period
S5	I2S_TX_BCLK/I2S_RX_BCLK to I2S_TX_FS/ I2S_RX_FS output valid	—	15	ns
S6	I2S_TX_BCLK/I2S_RX_BCLK to I2S_TX_FS/ I2S_RX_FS output invalid	0	—	ns
S7	I2S_TX_BCLK to I2S_TXD valid	—	15	ns
S8	I2S_TX_BCLK to I2S_TXD invalid	0	—	ns
S9	I2S_RXD/I2S_RX_FS input setup before I2S_RX_BCLK	15	—	ns
S10	I2S_RXD/I2S_RX_FS input hold after I2S_RX_BCLK	0	—	ns

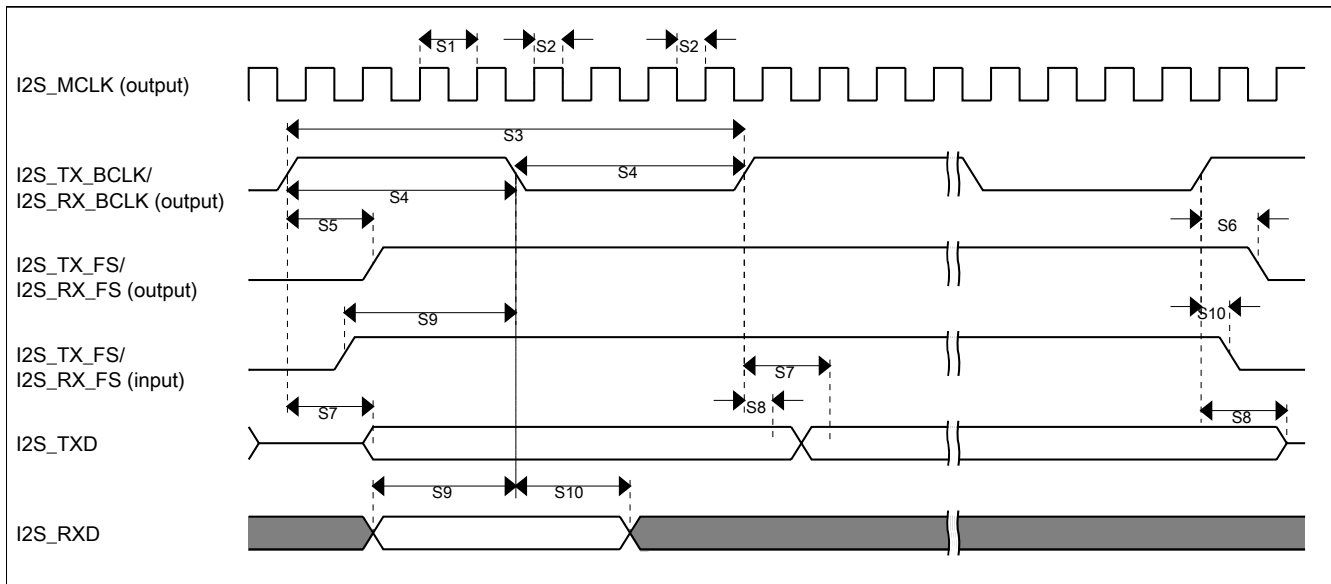


Figure 35. I2S/SAI timing — master modes

Table 52. I2S/SAI slave mode timing in Normal Run, Wait and Stop modes (limited voltage range)

Num.	Characteristic	Min.	Max.	Unit
	Operating voltage	2.7	3.6	V
S11	I2S_TX_BCLK/I2S_RX_BCLK cycle time (input)	80	—	ns
S12	I2S_TX_BCLK/I2S_RX_BCLK pulse width high/low (input)	45%	55%	MCLK period
S13	I2S_TX_FS/I2S_RX_FS input setup before I2S_TX_BCLK/I2S_RX_BCLK	4.5	—	ns
S14	I2S_TX_FS/I2S_RX_FS input hold after I2S_TX_BCLK/I2S_RX_BCLK	2	—	ns
S15	I2S_TX_BCLK to I2S_TXD/I2S_TX_FS output valid <ul style="list-style-type: none"> Multiple SAI Synchronous mode All other modes 	—	21 15	ns
S16	I2S_TX_BCLK to I2S_TXD/I2S_TX_FS output invalid	0	—	ns
S17	I2S_RXD setup before I2S_RX_BCLK	4.5	—	ns
S18	I2S_RXD hold after I2S_RX_BCLK	2	—	ns
S19	I2S_TX_FS input assertion to I2S_TXD output valid ¹	—	25	ns

1. Applies to first bit in each frame and only if the TCR4[FSE] bit is clear

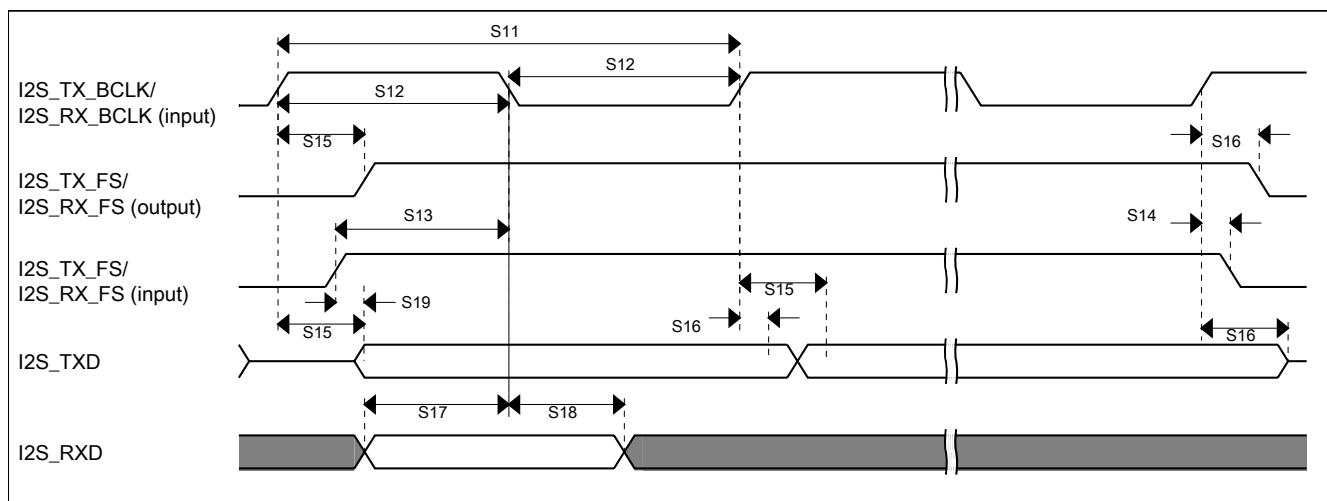


Figure 36. I2S/SAI timing — slave modes

6.8.11.2 Normal Run, Wait and Stop mode performance over the full operating voltage range

This section provides the operating performance over the full operating voltage for the device in Normal Run, Wait and Stop modes.

Table 53. I2S/SAI master mode timing in Normal Run, Wait and Stop modes (full voltage range)

Num.	Characteristic	Min.	Max.	Unit
	Operating voltage	1.71	3.6	V
S1	I2S_MCLK cycle time	40	—	ns
S2	I2S_MCLK pulse width high/low	45%	55%	MCLK period
S3	I2S_TX_BCLK/I2S_RX_BCLK cycle time (output)	80	—	ns
S4	I2S_TX_BCLK/I2S_RX_BCLK pulse width high/low	45%	55%	BCLK period
S5	I2S_TX_BCLK/I2S_RX_BCLK to I2S_TX_FS/ I2S_RX_FS output valid	—	15	ns
S6	I2S_TX_BCLK/I2S_RX_BCLK to I2S_TX_FS/ I2S_RX_FS output invalid	-1.0	—	ns
S7	I2S_TX_BCLK to I2S_TXD valid	—	15	ns
S8	I2S_TX_BCLK to I2S_TXD invalid	0	—	ns
S9	I2S_RXD/I2S_RX_FS input setup before I2S_RX_BCLK	20.5	—	ns
S10	I2S_RXD/I2S_RX_FS input hold after I2S_RX_BCLK	0	—	ns

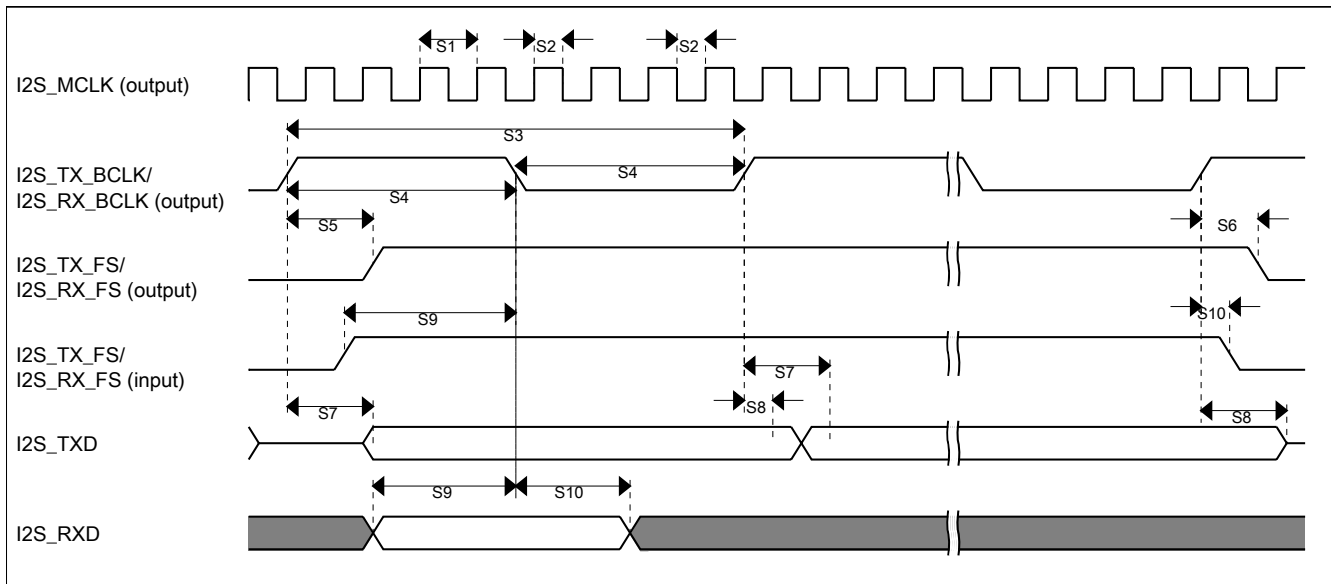


Figure 37. I2S/SAI timing — master modes

Table 54. I2S/SAI slave mode timing in Normal Run, Wait and Stop modes (full voltage range)

Num.	Characteristic	Min.	Max.	Unit
	Operating voltage	1.71	3.6	V
S11	I2S_TX_BCLK/I2S_RX_BCLK cycle time (input)	80	—	ns
S12	I2S_TX_BCLK/I2S_RX_BCLK pulse width high/low (input)	45%	55%	MCLK period
S13	I2S_TX_FS/I2S_RX_FS input setup before I2S_TX_BCLK/I2S_RX_BCLK	5.8	—	ns
S14	I2S_TX_FS/I2S_RX_FS input hold after I2S_TX_BCLK/I2S_RX_BCLK	2	—	ns
S15	I2S_TX_BCLK to I2S_TXD/I2S_TX_FS output valid <ul style="list-style-type: none"> Multiple SAI Synchronous mode All other modes 	—	24 20.6	ns
S16	I2S_TX_BCLK to I2S_TXD/I2S_TX_FS output invalid	0	—	ns
S17	I2S_RXD setup before I2S_RX_BCLK	5.8	—	ns
S18	I2S_RXD hold after I2S_RX_BCLK	2	—	ns
S19	I2S_TX_FS input assertion to I2S_TXD output valid ¹	—	25	ns

1. Applies to first bit in each frame and only if the TCR4[FSE] bit is clear

Peripheral operating requirements and behaviors

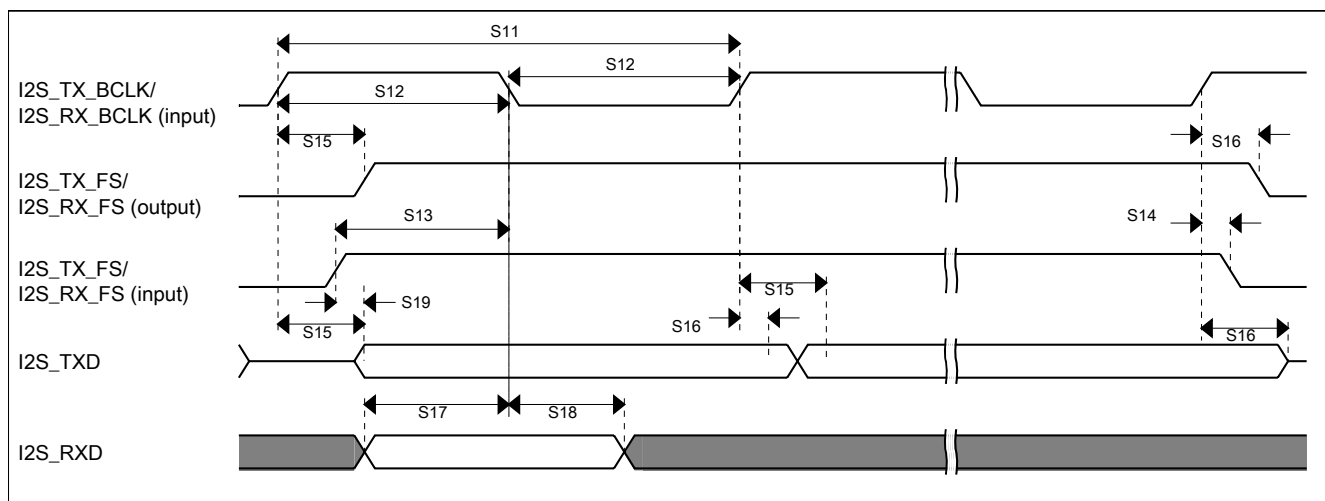


Figure 38. I2S/SAI timing — slave modes

6.8.11.3 VLPR, VLPW, and VLPS mode performance over the full operating voltage range

This section provides the operating performance over the full operating voltage for the device in VLPR, VLPW, and VLPS modes.

Table 55. I2S/SAI master mode timing in VLPR, VLPW, and VLPS modes (full voltage range)

Num.	Characteristic	Min.	Max.	Unit
	Operating voltage	1.71	3.6	V
S1	I2S_MCLK cycle time	62.5	—	ns
S2	I2S_MCLK pulse width high/low	45%	55%	MCLK period
S3	I2S_TX_BCLK/I2S_RX_BCLK cycle time (output)	250	—	ns
S4	I2S_TX_BCLK/I2S_RX_BCLK pulse width high/low	45%	55%	BCLK period
S5	I2S_TX_BCLK/I2S_RX_BCLK to I2S_TX_FS/ I2S_RX_FS output valid	—	45	ns
S6	I2S_TX_BCLK/I2S_RX_BCLK to I2S_TX_FS/ I2S_RX_FS output invalid	0	—	ns
S7	I2S_TX_BCLK to I2S_TXD valid	—	45	ns
S8	I2S_TX_BCLK to I2S_TXD invalid	-1.6	—	ns
S9	I2S_RXD/I2S_RX_FS input setup before I2S_RX_BCLK	45	—	ns
S10	I2S_RXD/I2S_RX_FS input hold after I2S_RX_BCLK	0	—	ns

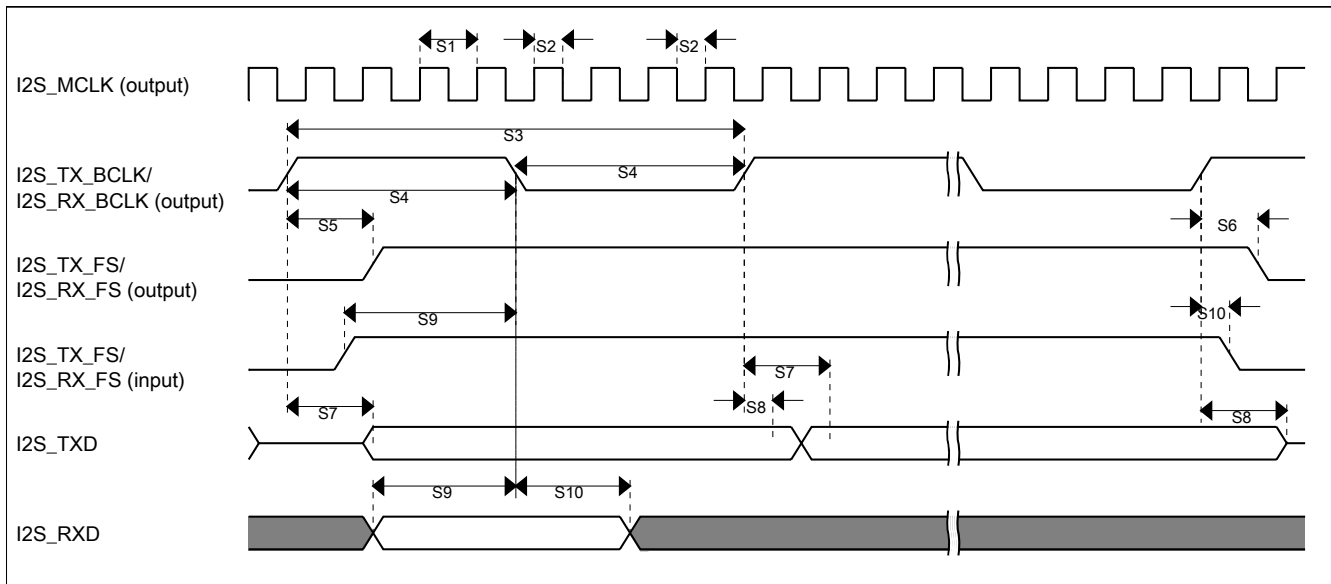


Figure 39. I2S/SAI timing — master modes

Table 56. I2S/SAI slave mode timing in VLPR, VLPW, and VLPS modes (full voltage range)

Num.	Characteristic	Min.	Max.	Unit
	Operating voltage	1.71	3.6	V
S11	I2S_TX_BCLK/I2S_RX_BCLK cycle time (input)	250	—	ns
S12	I2S_TX_BCLK/I2S_RX_BCLK pulse width high/low (input)	45%	55%	MCLK period
S13	I2S_TX_FS/I2S_RX_FS input setup before I2S_TX_BCLK/I2S_RX_BCLK	30	—	ns
S14	I2S_TX_FS/I2S_RX_FS input hold after I2S_TX_BCLK/I2S_RX_BCLK	3	—	ns
S15	I2S_TX_BCLK to I2S_TXD/I2S_TX_FS output valid	—	63	ns
S16	I2S_TX_BCLK to I2S_TXD/I2S_TX_FS output invalid	0	—	ns
S17	I2S_RXD setup before I2S_RX_BCLK	30	—	ns
S18	I2S_RXD hold after I2S_RX_BCLK	2	—	ns
S19	I2S_TX_FS input assertion to I2S_TXD output valid ¹	—	72	ns

1. Applies to first bit in each frame and only if the TCR4[FSE] bit is clear

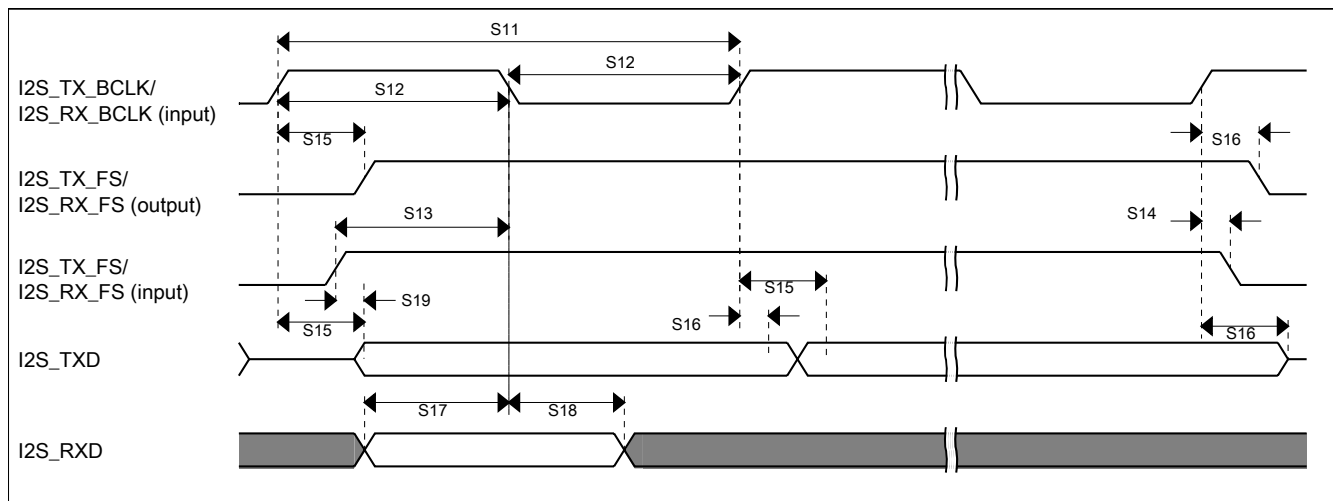


Figure 40. I2S/SAI timing — slave modes

6.9 Human-machine interfaces (HMI)

6.9.1 TSI electrical specifications

Table 57. TSI electrical specifications

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
V _{DDTSI}	Operating voltage	1.71	—	3.6	V	
C _{ELE}	Target electrode capacitance range	1	20	500	pF	1
f _{REFmax}	Reference oscillator frequency	—	8	15	MHz	2, 3
f _{ELEmax}	Electrode oscillator frequency	—	1	1.8	MHz	2, 4
C _{REF}	Internal reference capacitor	—	1	—	pF	
V _{DELTA}	Oscillator delta voltage	—	600	—	mV	2, 5
I _{REF}	Reference oscillator current source base current <ul style="list-style-type: none"> • 2 μA setting (REFCHRG = 0) • 32 μA setting (REFCHRG = 15) 	—	2 36	3 50	μ A	2, 6
I _{ELE}	Electrode oscillator current source base current <ul style="list-style-type: none"> • 2 μA setting (EXTCHRG = 0) • 32 μA setting (EXTCHRG = 15) 	—	2 36	3 50	μ A	2, 7
Pres5	Electrode capacitance measurement precision	—	8.3333	38400	fF/count	8
Pres20	Electrode capacitance measurement precision	—	8.3333	38400	fF/count	9
Pres100	Electrode capacitance measurement precision	—	8.3333	38400	fF/count	10
MaxSens	Maximum sensitivity	0.008	1.46	—	fF/count	11
Res	Resolution	—	—	16	bits	
T _{Con20}	Response time @ 20 pF	8	15	25	μ s	12
I _{TSI_RUN}	Current added in run mode	—	55	—	μ A	
I _{TSI_LP}	Low power mode current adder	—	1.3	2.5	μ A	13

1. The TSI module is functional with capacitance values outside this range. However, optimal performance is not guaranteed.
2. Fixed external capacitance of 20 pF.
3. REFCHRG = 2, EXTCHRG=0.
4. REFCHRG = 0, EXTCHRG = 10.
5. $V_{DD} = 3.0\text{ V}$.
6. The programmable current source value is generated by multiplying the SCANC[REFCHRG] value and the base current.
7. The programmable current source value is generated by multiplying the SCANC[EXTCHRG] value and the base current.
8. Measured with a 5 pF electrode, reference oscillator frequency of 10 MHz, PS = 128, NSCN = 8; I_{ext} = 16.
9. Measured with a 20 pF electrode, reference oscillator frequency of 10 MHz, PS = 128, NSCN = 2; I_{ext} = 16.
10. Measured with a 20 pF electrode, reference oscillator frequency of 10 MHz, PS = 16, NSCN = 3; I_{ext} = 16.
11. Sensitivity defines the minimum capacitance change when a single count from the TSI module changes. Sensitivity depends on the configuration used. The documented values are provided as examples calculated for a specific configuration of operating conditions using the following equation: $(C_{ref} * I_{ext}) / (I_{ref} * PS * NSCN)$

The typical value is calculated with the following configuration:

$I_{ext} = 6\ \mu\text{A}$ (EXTCHRG = 2), PS = 128, NSCN = 2, $I_{ref} = 16\ \mu\text{A}$ (REFCHRG = 7), $C_{ref} = 1.0\ \text{pF}$

The minimum value is calculated with the following configuration:

$I_{ext} = 2\ \mu\text{A}$ (EXTCHRG = 0), PS = 128, NSCN = 32, $I_{ref} = 32\ \mu\text{A}$ (REFCHRG = 15), $C_{ref} = 0.5\ \text{pF}$

The highest possible sensitivity is the minimum value because it represents the smallest possible capacitance that can be measured by a single count.

12. Time to do one complete measurement of the electrode. Sensitivity resolution of 0.0133 pF, PS = 0, NSCN = 0, 1 electrode, EXTCHRG = 7.
13. REFCHRG=0, EXTCHRG=4, PS=7, NSCN=0F, LPSCNITV=F, LPO is selected (1 kHz), and fixed external capacitance of 20 pF. Data is captured with an average of 7 periods window.

7 Dimensions

7.1 Obtaining package dimensions

Package dimensions are provided in package drawings.

To find a package drawing, go to nxp.com and perform a keyword search for the drawing's document number:

If you want the drawing for this package	Then use this document number
143-pin WLCSP	98ASA00402D

8 Pinout

8.1 Pins with active pull control after reset

The following pins are actively pulled up or down after reset:

Table 58. Pins with active pull control after reset

Pin	Active pull direction after reset
PTA0	pulldown
PTA1	pullup
PTA3	pullup
PTA4	pullup
RESET_b	pullup

8.2 K61 Signal Multiplexing and Pin Assignments

The following table shows the signals available on each pin and the locations of these pins on the devices supported by this document. The Port Control Module is responsible for selecting which ALT functionality is available on each pin.

143 WLC SP	Pin Name	Default	ALT0	ALT1	ALT2	ALT3	ALT4	ALT5	ALT6	ALT7	EzPort
A11	PTE0	ADC1_SE4a	ADC1_SE4a	PTE0	SPI1_PCS1	UART1_TX	SDHC0_D1		I2C1_SDA	RTC_CLKOUT	
C10	PTE1/ LLWU_P0	ADC1_SE5a	ADC1_SE5a	PTE1/ LLWU_P0	SPI1_SOUT	UART1_RX	SDHC0_D0		I2C1_SCL	SPI1_SIN	
B11	PTE2/ LLWU_P1	ADC1_SE6a	ADC1_SE6a	PTE2/ LLWU_P1	SPI1_SCK	UART1_CTS_b	SDHC0_DCLK				
D10	PTE3	ADC1_SE7a	ADC1_SE7a	PTE3	SPI1_SIN	UART1_RTS_b	SDHC0_CMD			SPI1_SOUT	
E7	VDD	VDD	VDD								
E8	VSS	VSS	VSS								
C11	PTE4/ LLWU_P2	DISABLED		PTE4/ LLWU_P2	SPI1_PCS0	UART3_TX	SDHC0_D3				
D11	PTE5	DISABLED		PTE5	SPI1_PCS2	UART3_RX	SDHC0_D2		FTM3_CH0		
E9	PTE6	DISABLED		PTE6	SPI1_PCS3	UART3_CTS_b	I2S0_MCLK		FTM3_CH1	USB_SOF_OUT	
E10	PTE7	DISABLED		PTE7		UART3_RTS_b	I2S0_RXD0		FTM3_CH2		
E11	PTE8	ADC2_SE16	ADC2_SE16	PTE8	I2S0_RXD1	UART5_TX	I2S0_RX_FS		FTM3_CH3		
F8	PTE9	ADC2_SE17	ADC2_SE17	PTE9	I2S0_TXD1	UART5_RX	I2S0_RX_BCLK		FTM3_CH4		
F9	PTE10	DISABLED		PTE10		UART5_CTS_b	I2S0_TXD0		FTM3_CH5		
F10	PTE11	ADC3_SE16	ADC3_SE16	PTE11		UART5_RTS_b	I2S0_TX_FS		FTM3_CH6		
F11	PTE12	ADC3_SE17	ADC3_SE17	PTE12			I2S0_TX_BCLK		FTM3_CH7		
F7	VDD	VDD	VDD								

143 WLC SP	Pin Name	Default	ALT0	ALT1	ALT2	ALT3	ALT4	ALT5	ALT6	ALT7	EzPort
E6	VSS	VSS	VSS								
G11	USB0_DP	USB0_DP	USB0_DP								
G10	USB0_DM	USB0_DM	USB0_DM								
G9	VOUT33	VOUT33	VOUT33								
G8	VREGIN	VREGIN	VREGIN								
H11	PGA2_DP/ ADC2_DP0/ ADC3_DP3/ ADC0_DP1	PGA2_DP/ ADC2_DP0/ ADC3_DP3/ ADC0_DP1	PGA2_DP/ ADC2_DP0/ ADC3_DP3/ ADC0_DP1								
H10	PGA2_DM/ ADC2_DM0/ ADC3_DM3/ ADC0_DM1	PGA2_DM/ ADC2_DM0/ ADC3_DM3/ ADC0_DM1	PGA2_DM/ ADC2_DM0/ ADC3_DM3/ ADC0_DM1								
H9	PGA3_DP/ ADC3_DP0/ ADC2_DP3/ ADC1_DP1	PGA3_DP/ ADC3_DP0/ ADC2_DP3/ ADC1_DP1	PGA3_DP/ ADC3_DP0/ ADC2_DP3/ ADC1_DP1								
H8	PGA3_DM/ ADC3_DM0/ ADC2_DM3/ ADC1_DM1	PGA3_DM/ ADC3_DM0/ ADC2_DM3/ ADC1_DM1	PGA3_DM/ ADC3_DM0/ ADC2_DM3/ ADC1_DM1								
J11	PGA0_DP/ ADC0_DP0/ ADC1_DP3	PGA0_DP/ ADC0_DP0/ ADC1_DP3	PGA0_DP/ ADC0_DP0/ ADC1_DP3								
J10	PGA0_DM/ ADC0_DM0/ ADC1_DM3	PGA0_DM/ ADC0_DM0/ ADC1_DM3	PGA0_DM/ ADC0_DM0/ ADC1_DM3								
J9	PGA1_DP/ ADC1_DP0/ ADC0_DP3	PGA1_DP/ ADC1_DP0/ ADC0_DP3	PGA1_DP/ ADC1_DP0/ ADC0_DP3								
J8	PGA1_DM/ ADC1_DM0/ ADC0_DM3	PGA1_DM/ ADC1_DM0/ ADC0_DM3	PGA1_DM/ ADC1_DM0/ ADC0_DM3								
K11	VDDA	VDDA	VDDA								
K10	VREFH	VREFH	VREFH								
K9	VREFL	VREFL	VREFL								
K8	VSSA	VSSA	VSSA								
J7	VREF_OUT/ CMP1_IN5/ CMP0_IN5/ ADC1_SE18	VREF_OUT/ CMP1_IN5/ CMP0_IN5/ ADC1_SE18	VREF_OUT/ CMP1_IN5/ CMP0_IN5/ ADC1_SE18								
L11	DAC0_OUT/ CMP1_IN3/ ADC0_SE23	DAC0_OUT/ CMP1_IN3/ ADC0_SE23	DAC0_OUT/ CMP1_IN3/ ADC0_SE23								
K7	DAC1_OUT/ CMP0_IN4/ CMP2_IN3/ ADC1_SE23	DAC1_OUT/ CMP0_IN4/ CMP2_IN3/ ADC1_SE23	DAC1_OUT/ CMP0_IN4/ CMP2_IN3/ ADC1_SE23								

Pinout

143 WLC SP	Pin Name	Default	ALT0	ALT1	ALT2	ALT3	ALT4	ALT5	ALT6	ALT7	EzPort
M11	TAMPER0/ RTC_ WAKEUP_B	TAMPER0/ RTC_ WAKEUP_B	TAMPER0/ RTC_ WAKEUP_B								
M10	TAMPER1	TAMPER1	TAMPER1								
M9	TAMPER2	TAMPER2	TAMPER2								
M8	TAMPER3	TAMPER3	TAMPER3								
L10	XTAL32	XTAL32	XTAL32								
L9	EXTAL32	EXTAL32	EXTAL32								
L8	VBAT	VBAT	VBAT								
L7	PTE24	ADC0_SE17/ EXTAL1	ADC0_SE17/ EXTAL1	PTE24	CAN1_TX	UART4_TX	I2S1_TX_FS		EWM_OUT_b	I2S1_RXD1	
H7	PTE25	ADC0_SE18/ XTAL1	ADC0_SE18/ XTAL1	PTE25	CAN1_RX	UART4_RX	I2S1_TX_ BCLK		EWM_IN	I2S1_TXD1	
H6	PTE26	ADC3_SE5b	ADC3_SE5b	PTE26	ENET_1588_ CLKIN	UART4_CTS_ b	I2S1_TXD0		RTC_ CLKOUT	USB_CLKIN	
L6	PTE27	ADC3_SE4b	ADC3_SE4b	PTE27		UART4_RTS_ b	I2S1_MCLK				
K6	PTA0	JTAG_TCLK/ SWD_CLK/ EZP_CLK	TSIO_CH1	PTA0	UART0_CTS_ b/ UART0_COL_ b	FTM0_CH5				JTAG_TCLK/ SWD_CLK	EZP_CLK
J6	PTA1	JTAG_TDI/ EZP_DI	TSIO_CH2	PTA1	UART0_RX	FTM0_CH6				JTAG_TDI	EZP_DI
H5	PTA2	JTAG_TDO/ TRACE_SWO/ EZP_DO	TSIO_CH3	PTA2	UART0_TX	FTM0_CH7				JTAG_TDO/ TRACE_SWO	EZP_DO
J5	PTA3	JTAG_TMS/ SWD_DIO	TSIO_CH4	PTA3	UART0_RTS_ b	FTM0_CH0				JTAG_TMS/ SWD_DIO	
K5	PTA4/ LLWU_P3	NMI_b/ EZP_CS_b	TSIO_CH5	PTA4/ LLWU_P3		FTM0_CH1				NMI_b	EZP_CS_b
L5	PTA5	DISABLED		PTA5	USB_CLKIN	FTM0_CH2	RMII0_RXER/ MII0_RXER	CMP2_OUT	I2S0_TX_ BCLK	JTAG_TRST_ b	
G5	VDD	VDD	VDD								
F5	VSS	VSS	VSS								
L4	PTA12	CMP2_IN0	CMP2_IN0	PTA12	CAN0_TX	FTM1_CH0	RMII0_RXD1/ MII0_RXD1		I2S0_TXD0	FTM1_QD_ PHA	
K4	PTA13/ LLWU_P4	CMP2_IN1	CMP2_IN1	PTA13/ LLWU_P4	CAN0_RX	FTM1_CH1	RMII0_RXD0/ MII0_RXD0		I2S0_TX_FS	FTM1_QD_ PHB	
J4	PTA14	CMP3_IN0	CMP3_IN0	PTA14	SPI0_PCS0	UART0_TX	RMII0_CRS_ DV/ MII0_RXDV		I2S0_RX_ BCLK	I2S0_TXD1	
L3	PTA15	CMP3_IN1	CMP3_IN1	PTA15	SPI0_SCK	UART0_RX	RMII0_TXEN/ MII0_TXEN		I2S0_RXD0		
K3	PTA16	CMP3_IN2	CMP3_IN2	PTA16	SPI0_SOUT	UART0_CTS_ b/ UART0_COL_ b	RMII0_TXD0/ MII0_TXD0		I2S0_RX_FS	I2S0_RXD1	

143 WLC SP	Pin Name	Default	ALT0	ALT1	ALT2	ALT3	ALT4	ALT5	ALT6	ALT7	EzPort
J3	PTA17	ADC1_SE17	ADC1_SE17	PTA17	SPI0_SIN	UART0_RTS_b	RMII0_TXD1/ MII0_TXD1		I2S0_MCLK		
L2	VDD	VDD	VDD								
J2	VSS	VSS	VSS								
L1	PTA18	EXTAL0	EXTAL0	PTA18		FTM0_FLT2	FTM_CLKIN0				
K1	PTA19	XTAL0	XTAL0	PTA19		FTM1_FLT0	FTM_CLKIN1		LPTMR0_ALT1		
J1	RESET_b	RESET_b	RESET_b								
H4	PTB0/ LLWU_P5	ADC0_SE8/ ADC1_SE8/ ADC2_SE8/ ADC3_SE8/ TSI0_CH0	ADC0_SE8/ ADC1_SE8/ ADC2_SE8/ ADC3_SE8/ TSI0_CH0	PTB0/ LLWU_P5	I2C0_SCL	FTM1_CH0	RMII0_MDIO/ MII0_MDIO		FTM1_QD_PHA		
H3	PTB1	ADC0_SE9/ ADC1_SE9/ ADC2_SE9/ ADC3_SE9/ TSI0_CH6	ADC0_SE9/ ADC1_SE9/ ADC2_SE9/ ADC3_SE9/ TSI0_CH6	PTB1	I2C0_SDA	FTM1_CH1	RMII0_MDC/ MII0_MDC		FTM1_QD_PHB		
H2	PTB2	ADC0_SE12/ TSI0_CH7	ADC0_SE12/ TSI0_CH7	PTB2	I2C0_SCL	UART0_RTS_b	ENET0_1588_TMR0		FTM0_FLT3		
H1	PTB3	ADC0_SE13/ TSI0_CH8	ADC0_SE13/ TSI0_CH8	PTB3	I2C0_SDA	UART0_CTS_b/ UART0_COL_b	ENET0_1588_TMR1		FTM0_FLT0		
G4	PTB4	ADC1_SE10	ADC1_SE10	PTB4			ENET0_1588_TMR2		FTM1_FLT0		
G3	PTB5	ADC1_SE11	ADC1_SE11	PTB5			ENET0_1588_TMR3		FTM2_FLT0		
G2	PTB6	ADC1_SE12	ADC1_SE12	PTB6				FB_AD23			
G1	PTB7	ADC1_SE13	ADC1_SE13	PTB7				FB_AD22			
F4	PTB8	DISABLED		PTB8		UART3_RTS_b		FB_AD21			
F3	PTB9	DISABLED		PTB9	SPI1_PCS1	UART3_CTS_b		FB_AD20			
F2	PTB10	ADC1_SE14	ADC1_SE14	PTB10	SPI1_PCS0	UART3_RX	I2S1_TX_BCLK	FB_AD19	FTM0_FLT1		
F1	PTB11	ADC1_SE15	ADC1_SE15	PTB11	SPI1_SCK	UART3_TX	I2S1_TX_FS	FB_AD18	FTM0_FLT2		
G6	VSS	VSS	VSS								
E5	VDD	VDD	VDD								
E1	PTB16	TSI0_CH9	TSI0_CH9	PTB16	SPI1_SOUT	UART0_RX	I2S1_TXD0	FB_AD17	EWM_IN		
E2	PTB17	TSI0_CH10	TSI0_CH10	PTB17	SPI1_SIN	UART0_TX	I2S1_TXD1	FB_AD16	EWM_OUT_b		
E3	PTB18	TSI0_CH11	TSI0_CH11	PTB18	CAN0_TX	FTM2_CH0	I2S0_TX_BCLK	FB_AD15	FTM2_QD_PHA		
E4	PTB19	TSI0_CH12	TSI0_CH12	PTB19	CAN0_RX	FTM2_CH1	I2S0_TX_FS	FB_OE_b	FTM2_QD_PHB		
D1	PTB20	ADC2_SE4a	ADC2_SE4a	PTB20	SPI2_PCS0			FB_AD31/ NFC_DATA15	CMP0_OUT		

Pinout

143 WLC SP	Pin Name	Default	ALT0	ALT1	ALT2	ALT3	ALT4	ALT5	ALT6	ALT7	EzPort
D2	PTB21	ADC2_SE5a	ADC2_SE5a	PTB21	SPI2_SCK			FB_AD30/ NFC_DATA14	CMP1_OUT		
D5	PTB22	DISABLED		PTB22	SPI2_SOUT			FB_AD29/ NFC_DATA13	CMP2_OUT		
D4	PTB23	DISABLED		PTB23	SPI2_SIN	SPI0_PCS5		FB_AD28/ NFC_DATA12	CMP3_OUT		
D3	PTC0	ADC0_SE14/ TSIO_CH13	ADC0_SE14/ TSIO_CH13	PTC0	SPI0_PCS4	PDB0_EXTRG		FB_AD14/ NFC_DATA11	I2S0_TXD1		
C1	PTC1/ LLWU_P6	ADC0_SE15/ TSIO_CH14	ADC0_SE15/ TSIO_CH14	PTC1/ LLWU_P6	SPI0_PCS3	UART1_RTS_ b	FTM0_CH0	FB_AD13/ NFC_DATA10	I2S0_TXD0		
C2	PTC2	ADC0_SE4b/ CMP1_IN0/ TSIO_CH15	ADC0_SE4b/ CMP1_IN0/ TSIO_CH15	PTC2	SPI0_PCS2	UART1_CTS_ b	FTM0_CH1	FB_AD12/ NFC_DATA9	I2S0_TX_FS		
B1	PTC3/ LLWU_P7	CMP1_IN1	CMP1_IN1	PTC3/ LLWU_P7	SPI0_PCS1	UART1_RX	FTM0_CH2	CLKOUT	I2S0_TX_ BCLK		
G7	VDD	VDD	VDD								
A3	PTC4/ LLWU_P8	DISABLED		PTC4/ LLWU_P8	SPI0_PCS0	UART1_TX	FTM0_CH3	FB_AD11/ NFC_DATA8	CMP1_OUT	I2S1_TX_ BCLK	
B4	PTC5/ LLWU_P9	DISABLED		PTC5/ LLWU_P9	SPI0_SCK	LPTMR0_ ALT2	I2S0_RXD0	FB_AD10/ NFC_DATA7	CMP0_OUT	I2S1_TX_FS	
C5	PTC6/ LLWU_P10	CMP0_IN0	CMP0_IN0	PTC6/ LLWU_P10	SPI0_SOUT	PDB0_EXTRG	I2S0_RX_ BCLK	FB_AD9/ NFC_DATA6	I2S0_MCLK		
B5	PTC7	CMP0_IN1	CMP0_IN1	PTC7	SPI0_SIN	USB_SOF_ OUT	I2S0_RX_FS	FB_AD8/ NFC_DATA5			
A4	PTC8	ADC1_SE4b/ CMP0_IN2	ADC1_SE4b/ CMP0_IN2	PTC8		FTM3_CH4	I2S0_MCLK	FB_AD7/ NFC_DATA4			
C6	PTC9	ADC1_SE5b/ CMP0_IN3	ADC1_SE5b/ CMP0_IN3	PTC9		FTM3_CH5	I2S0_RX_ BCLK	FB_AD6/ NFC_DATA3	FTM2_FLT0		
D6	PTC10	ADC1_SE6b	ADC1_SE6b	PTC10	I2C1_SCL	FTM3_CH6	I2S0_RX_FS	FB_AD5/ NFC_DATA2	I2S1_MCLK		
A5	PTC11/ LLWU_P11	ADC1_SE7b	ADC1_SE7b	PTC11/ LLWU_P11	I2C1_SDA	FTM3_CH7	I2S0_RXD1	FB_RW_b/ NFC_WE			
D7	PTC12	DISABLED		PTC12		UART4_RTS_ b		FB_AD27	FTM3_FLT0		
B6	PTC13	DISABLED		PTC13		UART4_CTS_ b		FB_AD26			
C7	PTC14	DISABLED		PTC14		UART4_RX		FB_AD25			
A6	PTC15	DISABLED		PTC15		UART4_TX		FB_AD24			
C4	VDD	VDD	VDD								
A7	PTC16	DISABLED		PTC16	CAN1_RX	UART3_RX	ENET0_1588_ TMR0	FB_CS5_b/ FB_TSI21/ FB_BE23_16_ b	NFC_RB		
B7	PTC17	DISABLED		PTC17	CAN1_TX	UART3_TX	ENET0_1588_ TMR1	FB_CS4_b/ FB_TSI20/ FB_BE31_24_ b	NFC_CE0_b		

143 WLC SP	Pin Name	Default	ALT0	ALT1	ALT2	ALT3	ALT4	ALT5	ALT6	ALT7	EzPort
C8	PTC18	DISABLED		PTC18		UART3_RTS_b	ENET0_1588_TMR2	FB_TBST_b/ FB_CS2_b/ FB_BE15_8_b	NFC_CE1_b		
D8	PTC19	DISABLED		PTC19		UART3_CTS_b	ENET0_1588_TMR3	FB_CS3_b/ FB_BE7_0_b	FB_TA_b		
B8	PTD0/ LLWU_P12	DISABLED		PTD0/ LLWU_P12	SPI0_PCS0	UART2_RTS_b	FTM3_CH0	FB_ALE/ FB_CS1_b/ FB_TS_b	I2S1_RXD1		
A8	PTD1	ADC0_SE5b	ADC0_SE5b	PTD1	SPI0_SCK	UART2_CTS_b	FTM3_CH1	FB_CS0_b	I2S1_RXD0		
D9	PTD2/ LLWU_P13	DISABLED		PTD2/ LLWU_P13	SPI0_SOUT	UART2_RX	FTM3_CH2	FB_AD4	I2S1_RX_FS		
C9	PTD3	DISABLED		PTD3	SPI0_SIN	UART2_TX	FTM3_CH3	FB_AD3	I2S1_RX_BCLK		
B9	PTD4/ LLWU_P14	DISABLED		PTD4/ LLWU_P14	SPI0_PCS1	UART0_RTS_b	FTM0_CH4	FB_AD2/ NFC_DATA1	EWM_IN		
A9	PTD5	ADC0_SE6b	ADC0_SE6b	PTD5	SPI0_PCS2	UART0_CTS_b/ UART0_COL_b	FTM0_CH5	FB_AD1/ NFC_DATA0	EWM_OUT_b		
B10	PTD6/ LLWU_P15	ADC0_SE7b	ADC0_SE7b	PTD6/ LLWU_P15	SPI0_PCS3	UART0_RX	FTM0_CH6	FB_AD0	FTM0_FLT0		
K2	VDD	VDD	VDD								
A10	PTD7	DISABLED		PTD7	CMT_IRO	UART0_TX	FTM0_CH7		FTM0_FLT1		
B2	NC	NC	NC								
C3	NC	NC	NC								
A2	NC	NC	NC								
B3	NC	NC	NC								
A1	NC	NC	NC								
M1	NC	NC	NC								
M2	NC	NC	NC								
M3	NC	NC	NC								
M4	NC	NC	NC								
M5	NC	NC	NC								
M6	NC	NC	NC								
M7	NC	NC	NC								
A12	NC	NC	NC								
B12	NC	NC	NC								
C12	NC	NC	NC								
D12	NC	NC	NC								
E12	NC	NC	NC								
F12	NC	NC	NC								
G12	NC	NC	NC								
H12	NC	NC	NC								

Pinout

143 WLC SP	Pin Name	Default	ALT0	ALT1	ALT2	ALT3	ALT4	ALT5	ALT6	ALT7	EzPort
J12	NC	NC	NC								
K12	NC	NC	NC								
L12	NC	NC	NC								
M12	NC	NC	NC								

8.3 K61 Pinouts

The below figure shows the pinout diagram for the devices supported by this document. Many signals may be multiplexed onto a single pin. To determine what signals can be used on which pin, see the previous section.

	1	2	3	4	5	6	7	8	9	10	11	12	
A	NC	NC	PTC4/ LLWU_P8	PTC8	PTC11/ LLWU_P11	PTC15	PTC16	PTD1	PTD5	PTD7	PTE0	NC	A
B	PTC3/ LLWU_P7	NC	NC	PTC5/ LLWU_P9	PTC7	PTC13	PTC17	PTD0/ LLWU_P12	PTD4/ LLWU_P14	PTD6/ LLWU_P15	PTE2/ LLWU_P1	NC	B
C	PTC1/ LLWU_P6	PTC2	NC	VDD	PTC6/ LLWU_P10	PTC9	PTC14	PTC18	PTD3	PTE1/ LLWU_P0	PTE4/ LLWU_P2	NC	C
D	PTB20	PTB21	PTC0	PTB23	PTB22	PTC10	PTC12	PTC19	PTD2/ LLWU_P13	PTE3	PTE5	NC	D
E	PTB16	PTB17	PTB18	PTB19	VDD	VSS	VDD	VSS	PTE6	PTE7	PTE8	NC	E
F	PTB11	PTB10	PTB9	PTB8	VSS		VDD	PTE9	PTE10	PTE11	PTE12	NC	F
G	PTB7	PTB6	PTB5	PTB4	VDD	VSS	VDD	VREGIN	VOU33	USB0_DM	USB0_DP	NC	G
H	PTB3	PTB2	PTB1	PTB0/ LLWU_P5	PTA2	PTE26	PTE25	PGA3_DM/ ADC3_DM0/ ADC2_DM3/ ADC1_DM1	PGA3_DP/ ADC3_DP0/ ADC2_DP3/ ADC1_DP1	PGA2_DM/ ADC2_DM0/ ADC3_DM3/ ADC0_DM1	PGA2_DP/ ADC2_DP0/ ADC3_DP3/ ADC0_DP1	NC	H
J	RESET_b	VSS	PTA17	PTA14	PTA3	PTA1	VREF_OUT/ CMP1_IN5/ CMP0_IN5/ ADC1_SE18	PGA1_DM/ ADC1_DM0/ ADC0_DM3	PGA1_DP/ ADC1_DP0/ ADC0_DP3	PGA0_DM/ ADC0_DM0/ ADC1_DM3	PGA0_DP/ ADC0_DP0/ ADC1_DP3	NC	J
K	PTA19	VDD	PTA16	PTA13/ LLWU_P4	PTA4/ LLWU_P3	PTA0	DAC1_OUT/ CMP0_IN4/ CMP2_IN3/ ADC1_SE23	VSSA	VREFL	VREFH	VDDA	NC	K
L	PTA18	VDD	PTA15	PTA12	PTA5	PTE27	PTE24	VBAT	EXTAL32	XTAL32	DAC0_OUT/ CMP1_IN3/ ADC0_SE23	NC	L
M	NC	NC	NC	NC	NC	NC	NC	TAMPER3	TAMPER2	TAMPER1	TAMPER0/ RTC_ WAKEUP_B	NC	M

Figure 41. K61 143 WLCSP Pinout Diagram

9 Revision History

The following table provides a revision history for this document.

Table 59. Revision History

Rev. No.	Date	Substantial Changes
3	3/2012	Initial public release
4	10/2012	Replaced TBDs throughout.
5	10/2013	<p>Changes for 4N96B mask set:</p> <ul style="list-style-type: none"> Min VDD operating requirement specification updated to support operation down to 1.71V. <p>New specifications:</p> <ul style="list-style-type: none"> Updated Vdd_dds min specification. Added Vodpu specification. Removed loz, loz_dds, and loz_tamper Hi-Z leakage specifications. They have been replaced by new lina, lind, and Zind specifications. Fpll_ref_acc specification has been added. I²C module was previously covered by the general switching specifications. To provide more detail on I²C operation a dedicated Inter-Integrated Circuit Interface (I²C) timing section has been added. <p>Modified specifications:</p> <ul style="list-style-type: none"> Vref_dds max spec has been updated. Tpor spec has been split into two specifications based on VDD slew rate. Trd1allx and Trd1alln max have been updated. 16-bit ADC Temp sensor slope and Temp sensor voltage (Vtemp25) have been modified. The typical values that were listed previously have been updated, and min and max specifications have been added. <p>Corrections:</p> <ul style="list-style-type: none"> Some versions of the datasheets listed incorrect clock mode information in the "Diagram: Typical IDD_RUN operating behavior section." These errors have been corrected. Fintf_ft specification was previously shown as a max value. It has been corrected to be shown as a typical value as originally intended. Corrected DDR write and read timing diagrams to show the correct location of the Tcmv specification. SDHC peripheral 50MHz high speed mode options were left out of the last datasheet. These have been added to the SDHC specifications section.
6	09/2015	<ul style="list-style-type: none"> Updated the footnotes of Thermal Attributes table Removed Power Sequencing section Added footnote to ambient temperature specification of Thermal Operating requirements Removed "USB HS/LS/FS on-the-go controller with on-chip high speed transceiver" from features section Updated Terminology and guidelines section Updated the footnotes and the values of Power consumption operating behaviors table Added Notes in USB electrical specification section Updated I2C timing table

Table continues on the next page...

Table 59. Revision History (continued)

Rev. No.	Date	Substantial Changes
7	02/2018	<ul style="list-style-type: none">• Updated maximum SDHC frequency in SDHC specifications• Added MDIO serial management timing specifications section in Ethernet Switching Specifications



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